



**Augmentation of a Nano-Satellite Electronic Power System using a
Field-Programmable-Gate-Array**

by

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Abstract

The CubeSat standard has various engineering challenges due to its small size and surface area. The challenge is to incorporate a large amount of technology into a form factor no bigger than 10cm^3 . This research project investigates the space environment, solar cells, secondary sources of power, and Field-Programmable-Gate-Array (FPGA) technology in order to address the size, weight and power challenges presented by the CubeSat standard. As FPGAs have not yet been utilised in this particular sub-system as the main controller, this research investigates whether or not the implementation of an FPGA-based electronic power supply sub-system will optimise its functionality by overcoming these size weight and power challenges.

The SmartFusion FPGA was chosen due to its analogue front end which can reduce the number of peripheral components required by such complex systems. Various maximum power point tracking algorithms were studied and it was determined that the perturb-and-observe maximum power point tracking algorithm best suits the design constraints, as it only requires the measurement of either solar cell voltage or solar cell current, thus further decreasing the component count. The SmartFusion FPGA analogue compute engine allows for increased performance of the perturb-and-observe algorithm implemented on the microcontroller sub-system as it allows for the offloading of many repetitive calculations. A VHDL implementation of the pulse-width-modulator was developed in order to produce the various changes in duty cycle produced by the perturb-and-observe algorithm.

The aim of this research project was achieved through the development and testing of a nano-satellite power system prototype using the SmartFusion FPGA from Microsemi with a decreased number of peripheral circuits. Maximum power point was achieved in 347ms at worst case with a 55% decrease in power consumption from the estimated 330mW as indicated in the power budget. The SmartFusion FPGA consumes only a worst case of 148.93mW. It was found that the unique features of the SmartFusion FPGA do in fact address the size weight and power constraints of the CubeSat standard within this sub-system.

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List of Abbreviations and Definitions

1-U	1 Unit CubeSat 10cmx10cmx10cm
2-U	2 Unit CubeSat 20cmX10cmX10cm
3-U	3 Unit CubeSat 30cmx10cmx10cm
ABPS	Active bi-polar pre-scalar
ACE	Analogue Compute Engine
ADC	Analogue to Digital Converter
AFE	Analogue Front End
AHB	Advanced High-Performance Bus
Albedo	Radiation reflected by a surface, typically that of a planet or moon.
AM0	Air Mass zero-solar irradiation in space 1400W/m ²
AMBA	Advanced Microcontroller Bus Architecture
Battery Charging scheme	Arrangement and inclusion of components in the proposed charging system
Boost converter	Step up /dc-dc converter topology
Buck converter	Step down dc-dc converter
Buck-Boost converter	Step up / step down dc-dc converter topology
CCCs	Clock Conditioning Circuits
CC-CV	Constant Current – Constant Voltage
Charging Time Out	Precautionary method implemented to protect and prevent damage to the energy storage device due to prolonged periods of charging
Controller	The component that will provide the gating signals
Depth-of-Discharge	Amount of Energy removed from a battery as a Percentage
DET	Direct Energy Transfer
EFROM	Electrically Flash ROM or Electrically Erasable ROM
EPS	Electronic Power System
ENVM	External Non-Volatile Memory

FPGA	Field-Programmable-Gate-Array
Geostationary Earth Orbit	35786 km above the earth's surface
GPIO's	General Purpose User Inputs and Outputs
Ground-Station	Designated area used to monitor and acquire data from a satellite
High Charging Temperature	Precautionary method implemented to protect and prevent damage to the energy storage device due to elevated temperatures during charging
I ² C	Inter Integrated Circuit
Krad	Absorbed radiation dose in silicone (1 rad = 100 Grey)
Lithium-ion battery	Energy storage device considered in this battery charging scheme
Low Earth Orbit	200 km to 2000 km above the earth's surface
Medium Earth Orbit	2000 km to 20 000 km above the earth's surface
MPU	Micro Processor Unit
MPPT	Maximum Power Point Tracking
Nano-satellite	Artificial Satellite with a mass between 1 to 10 kg
On-orbit	Operational area of a satellite
Over charging protection	Precautionary method implemented to protect and prevent damage to the energy storage device due to over-charging conditions
PDMA	Peripheral Direct Memory Access
PPE	Post Processing Engine
P-POD	Poly-PicoSatellite Orbital Deployer
SAR	Successive approximation register
Solar Array	A collection of solar cells (also known as solar panel)
Space Heritage	Component proven to operate efficiently in space
SPI	Serial Peripheral Interface
SSE	Sample Sequencing Engine
VHDL	VHSIC Hardware Description Language
VHSIC	Very High Speed Integrated Circuit

Nomenclature

A	Area of cells in cm^2
a	arbitrary constant
C	capacity in amp-hours
E	Energy stored in Watt-Hours
I_{pv}	output current
I_{ph}	photo current
I_{sat}	diode reverse saturation current
$I_{s_3.3}$	current during sun exposure on the 3.3V bus
I_{s_5}	current during sun exposure on the 5V bus
$I_{e_3.3}$	current required during eclipse on the 3.3V
I_{e_5}	current during eclipse on the 5V bus
I_s	diode 1 saturation current
I_{s2}	diode 2 saturation current
I_{charge}	charge current
J_{mpp}	current per cm^2 at peak power
K	Boltzmann's constant
N1	diode 1 emission coefficient
N2	diode 2 emission coefficient
N	solar cell ideality factor
n_s	number of solar cells in series
n_p	number of solar cells in parallel
$n_{(side)}$	number of solar cells on the side panels
$n_{(top)}$	number of solar cell on the top panel
Pd	power dissipated
$P_{out(side)}$	output power of the side panels

q	charge on an electron
R_s	series resistance
R_{sh}	parallel resistance
R_E	radius of the Earth
R_{PROG}	programmable resistance
T_j	junction temperature
T_a	ambient temperature
T_{orbit}	orbital period
T_{sun}	time spent exposed to the sun
$T_{eclipse}$	time spent in eclipse
T_{cell}	solar panel temperature
V_{pv}	output voltage
V_{mpp}	voltage at peak power
V_{avg}	average voltage during discharge
V_t	thermal voltage
ΔP	change in power dissipation
ΔI	change in current
ΔD	change in duty cycle
Θ_{ja}	junction to ambient temperature
Θ_{sa}	heat sink to ambient thermal resistance temperature
Θ_{cs}	insulator thermal resistance temperature
Θ_{jc}	junction to case thermal resistance temperature
μ	earth gravitational constant

Chapter 1

Introduction

1.1 Background

Aspiring satellite engineers in South Africa have the opportunity to enrol at the Cape Peninsula University of Technology (CPUT) in partnership with the French South African Institute of Technology (F'SATI) to complete a two year dual Master's Degree in Satellite Engineering (IAC, 2011). F'SATI was established in 1996 through collaboration between the French and South African Governments in an effort to increase human capacity in this developing field in South Africa. With the passing of the South African National Space Agency Act, a number of key role players such as the National Research Foundation (NRF), Paris Chamber of Commerce, CPUT and other well-established organisations have shown an increasing interest in the future of the South African Space Industry.

The satellites being developed are CubeSats with dimensions of 10cm-by-10cm-by-10cm typical of a 1-U. A complete 1-U CubeSat called ZACUBE-01 has already been developed and is awaiting a launch date. The 1-U mission was designed, together with the South African National Space Agency (SANSA) SPACE SCIENCE division, in order to use this particular CubeSat to calibrate an array of transmitters in Antarctica, known as SuperDarn (Super Dual Auroral Radar Network) (Greenwald, 1999). Funding has been secured for the further development of a 3-U CubeSat with anticipated completion in 2015.

The CubeSat standard started as an effort between Prof. Jordi Puig-Suari at California Polytechnic State University, San Luis Obispo, and Prof. Bob Twiggs at Stanford University's Space System Development Laboratory (SSDL) with the intention of creating a standard for nano-satellites which will decrease the development cost, decrease the development time and increase the accessibility to space through the implementation of the Poly-PicoSatellite Orbital Deployer(P-POD) (Nason, Creedon, & Johansen, 2002).

1.2 Problem Statement

FPGAs have not yet been implemented on CubeSat electronic power supply sub-systems as it is perceived that these devices consume relatively large amounts of power. This research investigates whether the implementation of an FPGA-based electronic power supply sub-system will optimise functionality by addressing the size, weight and power challenges (otherwise known as SWAP challenges) presented by the CubeSat standard.

1.3 Objectives of the Research

Augmentation of the Electronic Power System (EPS) using an FPGA as the main controller will address the SWAP constraints of the CubeSat standard. The specific objectives are listed as follows:

- Design a high-level CubeSat power budget according to specified requirements considering the environment in space, orbital parameters, critical sub-systems, payloads and duty cycle of operation of these sub-systems.
- Investigate the solar cell and battery technologies and determine the solar array (SA) size and the capacity of the secondary source of power (batteries).
- Investigate various maximum power point tracking methods and determine which method is best suited for the design and implementation in the field-programmable-gate-array.
- Develop a flow chart of the algorithm chosen and write a suitable application code to be implemented using the field-programmable-gate-array.
- Utilise an FPGA as the main controller of the EPS sub-system:
 - The FPGA should be chosen through comparative studies while considering the application as well as the SWAP constraints.
 - The FPGA should implement the necessary logic and algorithms while considering the SWAP constraints.
 - The FPGA feasibility in a nano-satellite EPS sub-system must be determined.
- Choose an appropriate architecture while considering the SWAP constraints.
- Illustrate the various design steps followed in order to implement the design.
- Design and develop an EPS prototype to be used as proof of concept of operation.
- Conduct stand-alone tests to verify the correct operation of the prototype and proof of concept.

1.4 Research Methodology

First a literature review was done to establish the effects of the environment in space on the electronics found within an Electrical Power Sub-System (EPS), also taking into consideration that the orbit greatly affects which space environmental factors to consider. Research was then directed into solar cell and battery technologies in order to establish which technologies best suit the design requirements, followed by an extensive investigation into FPGA technology and the VHDL programming language.

Different charging topologies were investigated, taking into account the different battery chemistries and the implementation of maximum power point tracking algorithms. Subsequently, power conditioning topologies were investigated and compared in order to meet the power budget requirements.

This was followed by the designing of each sub-circuit of the sub-system, simulating the different sub-circuits, procurement of components, construction and testing of individual sub-circuits and a final orbital simulation test of the integrated prototype.

1.5 Delineation of the Research

A mock mission needs to be created to establish the necessary sub-system requirements in order to fully delineate the research. These sub-system requirements, based on previous CubeSat missions, will allow for accurate power consumption estimations. The design of an EPS system usually starts with a power budget, a tool used by engineers to estimate the amount of power that will be required to drive all the subsequent sub-systems; however, in a real world situation, the power budget is subject to change.

At this stage, the power budget is an estimation of the incoming power, outgoing power, and stored power as well as the expected maximum power. The incoming power is the power that is converted from solar irradiance while the outgoing power is the power that is utilised by the sub-systems. Maximum power should be able to allow the operation of all sub-systems for a certain period of time.

The sub-systems that will be considered are the EPS, On-Board-Computer(OBC), communication system and a camera as a payload. These sub-systems' (e.g. communication, payload, OBC) power consumptions are to be simulated during testing using an active load. The

on-time of these sub-systems are directly related to the orbit of the satellite; for instance, the communication system transmits (Tx) only during the period when the satellite has a direct line of sight with respect to the ground-station, while the receiving (Rx) of instruction should always be enabled so as not to lose contact/control of the CubeSat. The payloads are only active over areas of interest while the OBC and the EPS are the only sub-systems that should remain active throughout the entirety of the mission as they are responsible for the majority of the critical functions.

1.6 Significance of the Research

The size, weight and power constraints of CubeSats are the limiting factors in the engineering design process of these satellites. So if engineers are able to overcome these constraints, larger more expensive satellites may not be necessary. By optimising this particular sub-system, the entire satellite will be allowed to operate more efficiently which in turn will allow CubeSats to increase their overall efficiencies. The engineers at ClydeSpace have shown that there is a market for small satellites in the world as their popularity is ever-increasing. Engineers have shown that the true potential of CubeSats lies within the large number of CubeSats that can be produced and used within a swarm of satellites to have multiple overpasses over a particular area, known as a high temporal resolution. With the completion of this project, the working prototype may be further developed into a flight ready model sub-system which will be an intellectual property of CPUT. CPUT will have the opportunity to exploit the growing market of CubeSats.

1.7 Structure of the Dissertation

Following this introductory chapter, Chapter 2 provides a literature overview of the nano-satellite power system including space environment, battery technologies, field-programmable-gate-arrays and various Maximum Power Point Tracking (MPPT) algorithms. Chapter 3 includes the design solution of the nano-satellite power system including development of the power budget, battery sizing, FPGA functionality, MPPT algorithm employed, development of the distribution system and design of an active load. Chapter 4 deals with the practical construction of the various sub-circuits of the EPS sub-system and FPGA implementation of the design. Chapter 5 covers the results of the nano-satellite power system, while Chapter 6 concludes the findings and provides recommendations for further research.

Chapter 2

Nano-Satellite Power Systems and the Environment in Space

2.1 Nano-Satellite Power System Overview

The $10 \times 10 \times 10 \text{cm}^3$ dimensions of the CubeSat 1-U standard place a large number of constraints on the design of such a nano-satellite. These constraints are known as the size, weight and power (SWAP) constraints. Engineers aim to place as much technology as possible in a 1-U CubeSat in order to increase its functionality. However, a key area to be addressed is the availability of power. Due to the environment in space, solar energy is the most preferred source of power available to satellites in general; thus, the efficiency of a satellite depends on how well each sub-system utilises the energy made available by the solar cells and the efficiency of the solar cell itself.

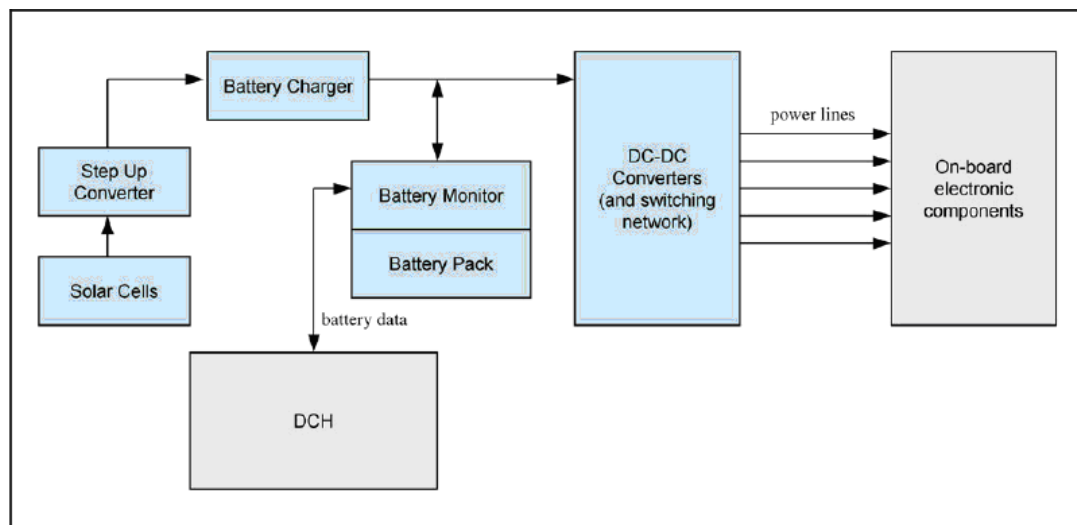


Figure 2.1: Overview of a nano-satellite Electronic Power System (EPS) (Akagi, J. n.d)

Figure 2.1 shows the main components of an EPS found within nano-satellites, as well as EPS sub-systems designed by ClydeSpace and GomSpace (GomSpace, 2012; Clyde Space, 2010). These include solar cells, a step-up converter (MPPT circuit), a battery charger, a secondary

source of power (battery), command and data handling units, and dc-dc converters (distribution system).

The design of the EPS starts with the mission requirements, taking into account the space environment, power requirements of the payload and other critical sub-systems as well as mission lifetime. From these requirements, the solar cell technology, battery technology and distribution architecture may be chosen according to beginning-of-life (BOL) and end-of-life (EOL) requirements.

2.2 Space Environment

2.2.1 Orbital Parameters

The orbital parameters are fixed values with small amounts of variance caused by orbit degradation. Orbital parameters are chosen to suite a particular mission. Hence the design process of any satellite sub-system strongly depends on these parameters. These orbital parameters have a direct implication on the satellite's operation. Factors such as the time spent in the sun and time spent in eclipse are governed by these parameters. The parameters to be dealt with include the following: the type of orbit, orbital height, inclination, time spent in the sun, time spent in eclipse, average orbits per day, and average orbits for the extent of the mission.

Satellites that are in orbit are classified according to their height above the earth. These heights are typically in one of these classifications: Geostationary Earth Orbit (GEO), Medium Earth Orbits (MEO), or Low Earth Orbit (LEO). The differences in orbital heights are tabulated in Table 2.1.

Orbital height, together with the inclination of the orbit, affect the period of the satellite's orbit as well as the time spent in the sun and eclipse. The following formula (Equation 2.1) was used to calculate the orbital period:

$$T_{orbit} = 2\pi \sqrt{\frac{a^3}{\mu}} \quad (2.1)$$

where a is $R_E(\text{km}) + \text{orbit altitude}(\text{km})$, R_E is the radius of the earth (6378 km) and μ is the Earth's gravitational constant ($3.986005 \cdot 10^4 \text{m}^3/\text{s}^2$)

Table 2.1: Space environment classification

<u>Orbit</u>	<u>Height</u>
GEO	35786 km
MEO	2000 km to 20 000 km
LEO	200 km to 2000 km

By calculating the orbital period, the time spent in the sun and eclipse may be calculated with Equations 2.2, 2.3 and 2.4 below:

$$T_{sun} = \left(\frac{180^\circ + 2\alpha}{360^\circ} \right) T_{orbit} \quad (2.2)$$

Where T_{sun} is the time spent in the sun in minutes

$$T_{eclipse} = \left(\frac{180^\circ - 2\alpha}{360^\circ} \right) T_{orbit} \quad (2.3)$$

Where $T_{eclipse}$ is the time spent in eclipse in minutes

α is calculated from

$$\alpha = \cos^{-1} \left(\frac{R_E}{R_E + H} \right) \quad (2.4)$$

Where H is the altitude of the satellite above the earth's surface.

From these calculations, the total number of charge/discharge cycles required by the battery and the average depth of discharge (DoD) are both determined. These are critical factors as they influence battery sizing.

Albedo from the earth was established as 410W/m^2 , while infrared reflection from the earth was approximated to 240W/m^2 , and direct solar input is taken as 1358W/m^2 . The effects of these parameters are illustrated in Figure 2.2.

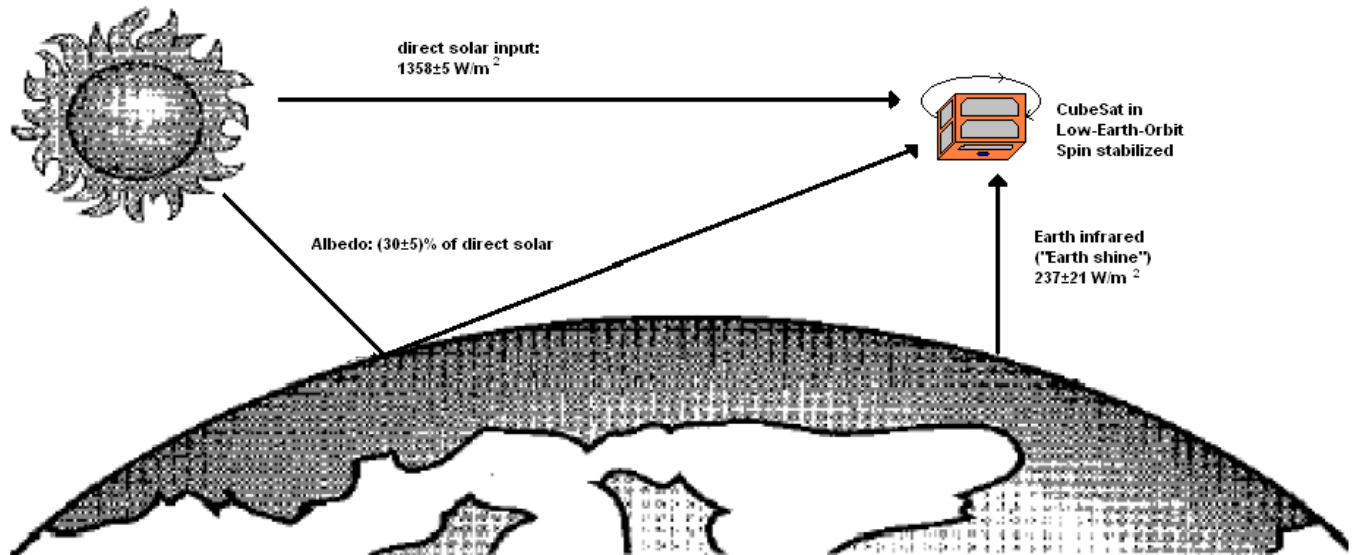


Figure 2.2: Irradiance affecting a satellite in orbit (Kjaer, 2002)

The CubeSat shown in Figure 2.2 is spin stabilised to ensure that the payload (camera) is always pointing toward the earth's surface. This method of stabilisation is normally used on 1-U mission due to the size restriction of a 1-U CubeSat.

2.3 Solar Cell Technology

Solar cells, also known as photovoltaic (PV) cells, are devices that convert electromagnetic radiation of the sun into electrical energy through what is known as the 'photoelectric effect'. These cells may be connected in series or parallel either to increase voltage or increase overall current respectively. The grouping of the solar cells is known as an array. The solar cells should be chosen in such a way as to provide enough electrical energy to charge the batteries and satisfy all sub-system power requirements during the period of sun exposure, ensuring that the satellite stays operational throughout the entire orbit and overcomes the eclipse period. Other sources of electrical energy used on satellites include nuclear power, radio-isotope technology, the fuel cell and solar thermal dynamics; however, due to the size and weight constraints in the design of a CubeSat, solar cells are the preferred choice.

2.3.1 Solar Cell Theory

Solar cells operate on the basis of the photoelectric effect (Figure 2.3), an effect which occurs when photons of the electromagnetic radiation produced by the sun strike a semiconductor material. Maini and Agrawal (2007) explain that these photons can reflect off the surface of the semiconductor material, pass through the semiconductor material without striking anything, or be absorbed by electrons in the semiconductor material's crystal lattice. Once these photons are absorbed and excite the electrons in the material's crystal lattice, the electrons which are tightly bound in covalent bonds between atoms are able to move freely throughout the material. The electrons leave behind an electron 'hole' which can then be filled by another electron of a nearby atom creating another electron 'hole'. These electron-hole pairs then move throughout the semiconductor material driven by either an electrostatic field established across the material or by gradient in the electrochemical composition. The movement of these electrons throughout the material creates current and can be used to drive external loads.

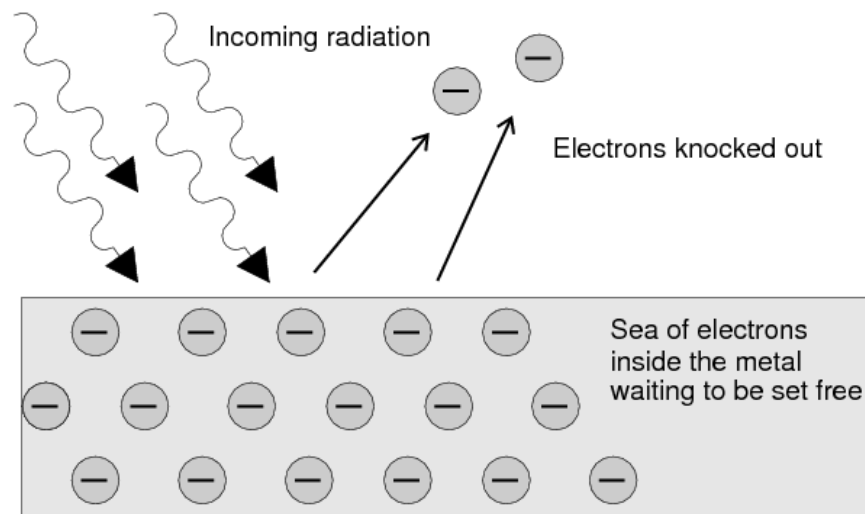


Figure 2.3: Photoelectric effect (Horner, 2011)

The movement of the photons straight through the crystal lattice and the reflection thereof decrease the efficiency of the solar cell. Table 2.2 compares various solar cell technologies considered for this design.

Table 2.2: Solar cell technology comparison

<u>Company</u>	<u>Solar cell Description</u>	<u>Mass</u>	<u>Type</u>	<u>Min Efficiency</u>	<u>Dimensions</u>
EMCORE	Triple-Junction Satellite Solar Cell	84 mg/cm ²	Germanium Triple Junction	28.5%	26.6 cm ² x 140 μm (also custom available)
EMCORE	Triple-Junction w/ Monolithic Diode	84 mg/cm ²	Germanium Triple Junction	28.0%	26.6 cm ² x 140 μm (also custom available)
EMCORE	Adv. Triple Junction (ATJ)	84 mg/cm ²	Germanium Triple Junction	27.5%	26.6 cm ² x 140 μm (also custom available)
EMCORE	Adv. Triple-Junction w/ Monolithic diode	84 mg/cm ²	Germanium Triple Junction	27.0%	27.5cm ² x 140 μm (also custom available)
Spectrolab	Next Triple Junction (XTJ) Solar Cells	84 mg/cm ²	Germanium Triple Junction	29.9%	Up To 60 cm ² x 140 μm
Spectrolab	Ultra Triple Junction (UTJ) Solar Cells	84 mg/cm ²	Germanium Triple Junction	28.3%	Up to 32 cm ² x 140 μm
Spectrolab	Improved Triple Junction (ITJ) Solar Cells	84 mg/cm ²	Germanium Triple Junction	26.8%	Up to 31 cm ² x 175 μm

Sources: 1) Emcore. (2006). 2) Spectrolab.(2010)

Manufacturers such as Emcore and Spectrolab design solar cells such as the Advanced Triple Junction (ATJ) and Next Generation Triple Junction (UTJ) depicted in Figure 2.4 which have multiple layers of substrate - GaInP₂, GaAs and Ge - with two junctions between the different semiconductor materials.

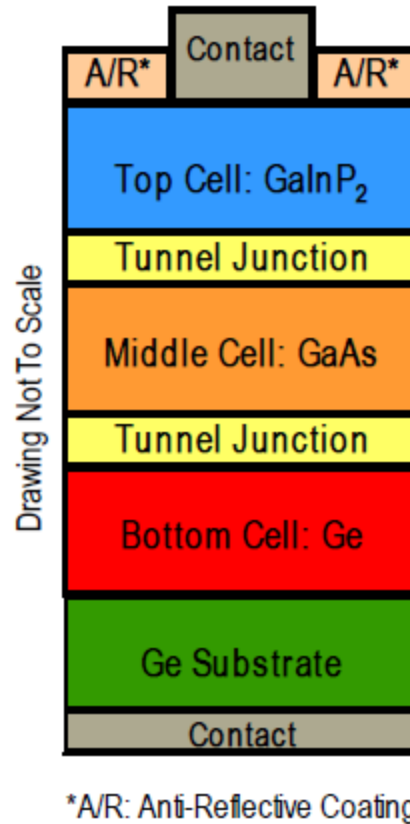


Figure 2.4: UTJ solar cell structure (Spectrolab, 2010)

The various levels of substrate address the movement of photons straight through the solar cell by increasing the total electron density of the solar cell, while anti-reflectives prevent the reflection of solar irradiance. These solar cells can produce efficiencies of up to 29.3% (Spectrolab, 2010).

These solar cells may be modelled using Kirchoff's voltage and current laws, described further in the following section.

2.3.2 Solar Cell Model

The aforementioned solar cells may be modelled using the circuit illustrated in Figure 2.5 from Harjai *et al.* (2010). The circuit consists of a current source (I_{ph}) used to represent the dislodging of electrons within the crystal lattice, while R_{se} is the equivalent series resistance of the solar cell and R_{sh} is the effective parallel resistance. The output of the current source is directly proportional to the light falling on the cell.

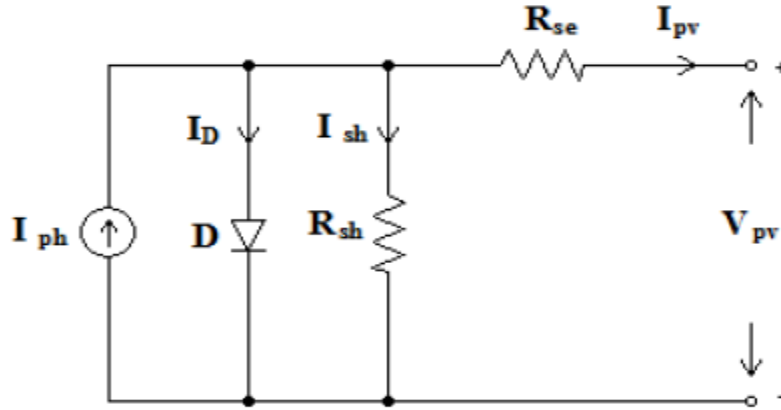


Figure 2.5: Solar cell model (Harjai *et al.*, 2010)

$$I_{pv} = I_{ph} - I_D - I_{sh} \quad (2.5)$$

$$I_{pv} = I_{ph} - I_{sat} \left(\exp \frac{q(V_o + I_{ph}R_s)}{nKT_{cell}Ns} - 1 \right) - \left(\frac{V_o + I_{ph}R_s}{R_p} \right) \quad (2.6)$$

Using the information acquired from the solar cell data sheet, various solar cell characteristics can be graphically illustrated using appropriate simulation packages. The output voltage and current strongly depend on the illumination (Figure 2.6) and temperature characteristics of the environment respectively. For this research, the 28.3% ultra-triple junction (UTJ) solar cells were simulated to obtain results similar to that of Walker (2001).

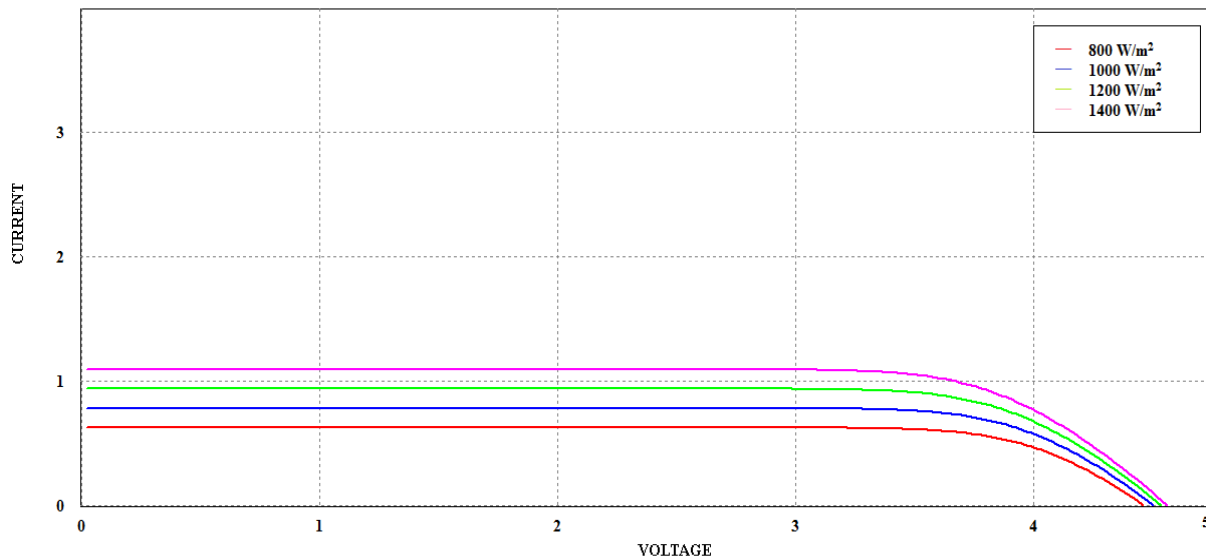


Figure 2.6: I-V characteristics at various levels of irradiance

The model used to simulate the solar cell was based on published Matlab code by González-Longatt (2005). The PSIM™ physical model was also used in conjunction with the Matlab code to verify the results. The results obtained indicate that the current output of the solar cell is highly dependent on the level of solar irradiance. It is seen that the maximum current occurs at 1400 W/m² typically the level of irradiance that LEO satellites experience in the space environment, as indicated in Figure 2.7. The current dramatically decreases as the level of solar irradiance decreases; hence, it is expected that the power output of the solar cell follows a similar trend (see Figure 2.7).

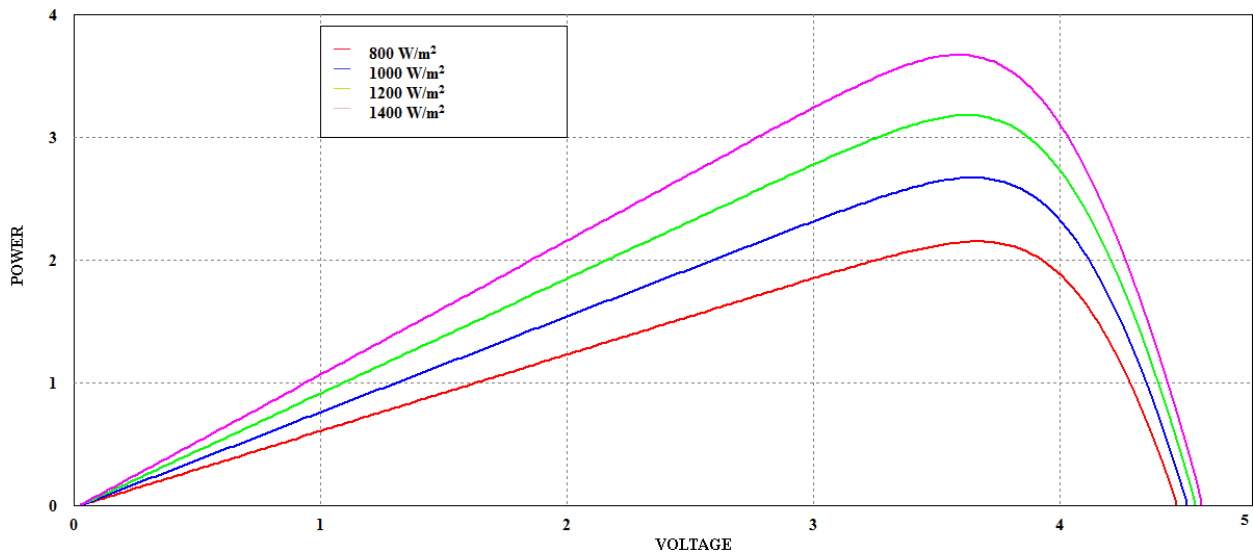


Figure 2.7: P-V characteristics at various levels of irradiance

It is noted that the power increases with an increase in solar irradiance. The maximum power voltage is found at 3.92V for all levels of irradiance, indicating that the solar cells can be connected in parallel even if they are not experiencing the same level of solar irradiance. Figure 2.8 and Figure 2.9 indicate that the operating temperature of the solar cells affect the output voltage and output power of the solar cell. The simulations indicate that as the temperature of the solar cells increases, the output voltage and power decrease. This is an important factor to note as the temperature of the CubeSat will be at a minimum as soon as it exits its eclipse period and the output power will be at a maximum.

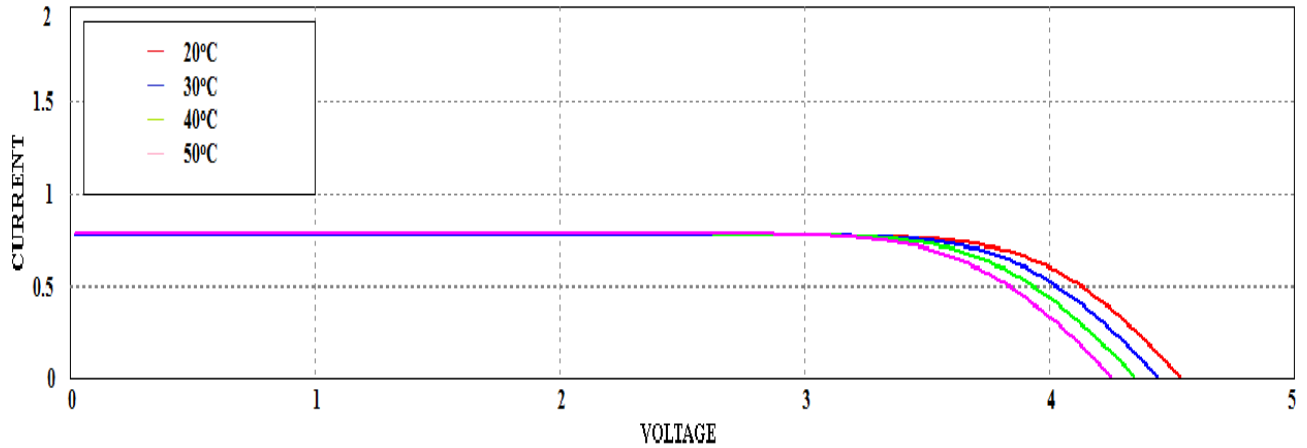


Figure 2.8: I-V characteristic curve and different operating temperatures

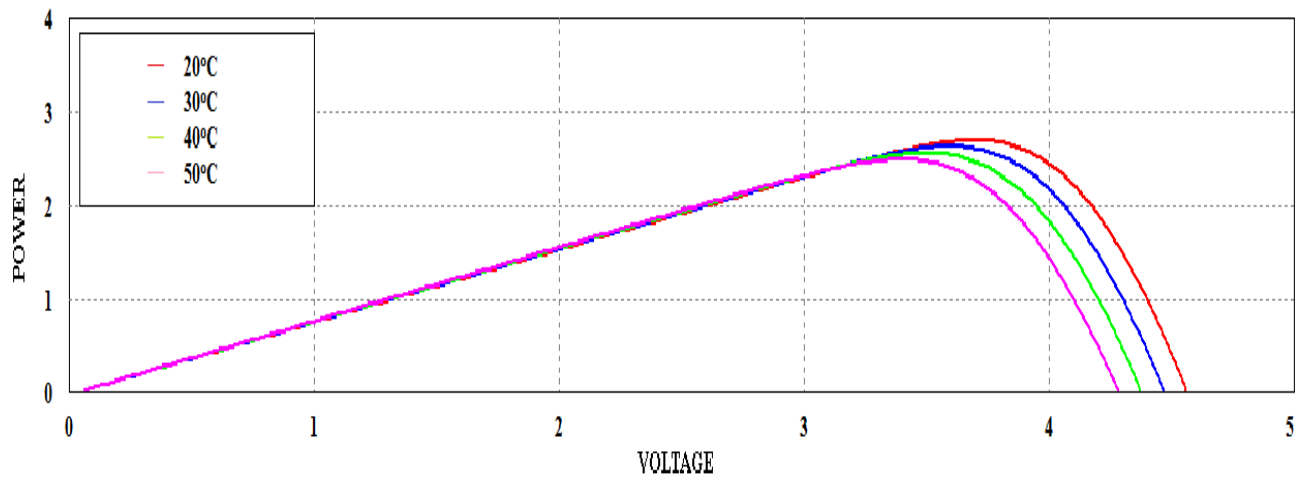


Figure 2.9: P-V characteristic curves at different operating temperatures

2.3.3 Angle of Incidence

The angle of incidence (AOI) affects the output power of a solar cell due to the change of the angle the sun makes with the solar cell while the satellite is in orbit (Bester, 2011). This change is subject to the cosine rule where the angle changes through 0° to 90° (Figure 2.10). Using Equation 2.7, the output power can be calculated at any instance in the orbit by knowing the angle between the incident light and the vector normal to the plane.

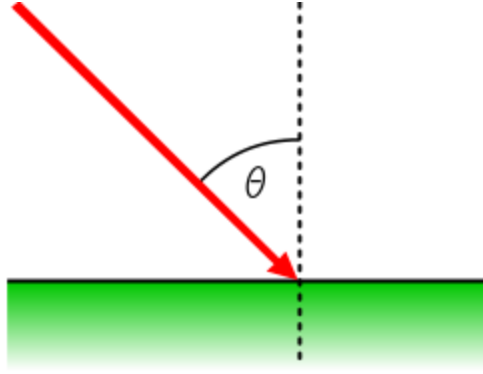


Figure 2.10: Angle of incidence

$$P_{out} = P_{avg} \cos \theta, \quad (2.7)$$

where P_{out} is the power at an incidence of 90° to the solar cell.

Maximum power can be generated from the solar array (SA) when three sides are exposed to solar irradiance; however, the AOI varies throughout the entirety of the orbit. The formula (Equation 2.8) describes the total power generated by three sides exposed to the sun with varying AOI:

$$P_{total} = P_{side1} \cos \phi \sin \theta + P_{side2} \sin \phi \sin \theta + P_{side3} \cos \theta \quad (2.8)$$

where P_{side} is power generated by the side at normal incidence.

The output power of the solar array can be calculated using Equation 2.7.

$$P_{out} = (n_s \times V_{mpp}) (n_p \times A \times J_{mpp}) \quad (2.9)$$

$$P_{out(side)} = P_{out(top)} \times \frac{n_{side}}{n_{top}} \quad (2.10)$$

Equations 2.9 and 2.10 can be used to calculate the solar panel average power using the datasheet information of the electrical characteristics of the solar panel provided by the manufacturer.

2.4 Secondary Power Source

Selecting the appropriate battery technology to be used in an electronic power system is a critical step of the design process. The battery technology must be chosen so as to conform to the size, weight and power limitations of the design. Due to the size and weight constraints of the CubeSat standard, Li-polymer and Lithium-ion battery technologies were selected for use as these batteries provide high volumetric energy densities as well as high gravimetric energy densities in relatively small packages.

2.4.1 Different Battery Technologies

Table 2.3 provides a comparison between the different battery technologies used: Nickel-Cadmium (NiCd), Nickel-Metal hydride (NiMH) and Lithium-Ion/Polymer Batteries.

Table 2.3: Battery technology comparison

<u>Type</u>	<u>NiCd</u>	<u>NiMH</u>	<u>Li- ion/ Po</u>
Nominal voltage (V)	1.2V	1.2V	3.7V
Density of energy (W.h/l)	140	180	200
Density of energy (W.h/kg)	39	57	83
Maximum discharge current	20C	4C	2C
Charging time	15min	30min	60min
Thermal range for charging	0 to +50	0 to +45	0 to +60
Thermal range for discharge	-20 to +50	-20 to +50	0 to +50
Resistance against overcharging	low	low	middle
Cathode material	NiOOH	NiOOH	LiPO
Anode material	Cd	Alloy	C
Max. number of cycles	1000	500	400

Sources: 1) Sunica (n.d). Eneritech International (2007); 2) Danionics (n.d.)

From Table 2.3 it can be seen that the volumetric and gravimetric energy densities are much higher for Li-Po batteries. The maximum number of discharge cycles for the Li-Ion batteries are 400 cycles; however, this is only the case when the DoD of the batteries are 100% which will not be allowed as this decreases a battery's life cycle. DoD will be regulated to 20%. These batteries have typical capacity ratings measured in mAh. A 1000mAh battery is able to supply 1000mA for an hour, or 100mA for 10 hours. In the design of the EPS sub-system, this capacity rating must be carefully considered as it will determine the depth of discharge of the secondary power source, the total number of cycles, and the charging current required to optimally charge the battery. For example, to charge a 1000mAh battery, 1000mA is needed to charge the battery in one hour if the battery is completely depleted. This is known as 1C or 100% of the rated battery capacity.

In order to optimally charge the selected battery, a battery charger needs to be selected to satisfy the charging conditions. This battery charger should take into consideration the battery chemistry and be able to detect the state of charge (SOC) of the battery. Ni-Cd, Ni-MH and Li-ion batteries are of different chemistries requiring their own unique charging methods and needing to be fully discharged before starting the charging process in order to avoid a decrease in capacity (a phenomenon known as the 'memory effect') while lithium-ion batteries require the implementation of the constant-current constant-voltage charging method to reach their fully charged state while having no danger of the memory effect (McLaren *et. al*, 2008; Davide, n.d.). However, these batteries should not be undercharged as this could lead to a decrease in the capacity of the lithium-ion battery. Figure 2.11 indicates the percentage loss against the percentage under charge.

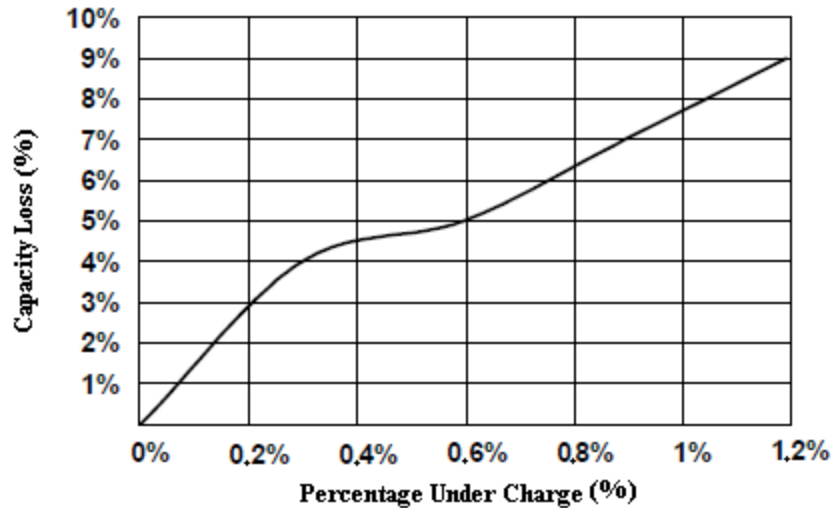


Figure 2.11: Capacity loss versus percentage undercharged (Microchip, 2004)

2.4.2 Li-ion Polymer Charging

During the recharge process, it is important to know when the battery has reached its fully charged condition. Without the ability to detect this condition, the charger will continue to source current into the battery even after it has reached the fully charged state, a situation which can damage the battery. Figure 2.12 indicates the different voltage levels associated with the different operating regions of Li-ion batteries.

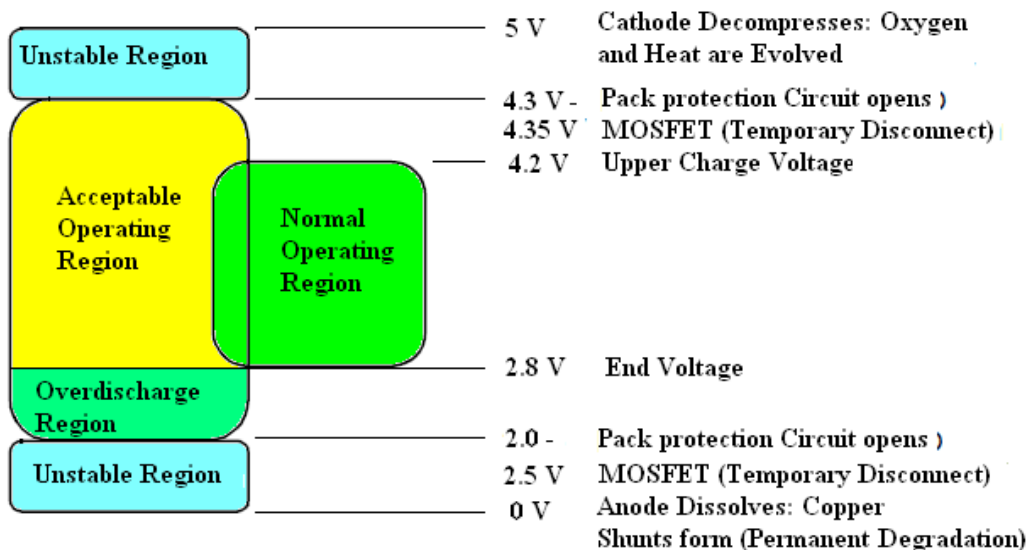


Figure 2.12: Operating regions of lithium-ion batteries (Microchip, 2004)

Figure 2.12 indicates that stability is lost above 4.3V and below 2.0V; however, starting the charging cycle should occur between the upper charge voltage and the end voltage to prevent damage to the battery. Operating outside these regions causes a decrease in capacity of the Li-ion battery (Microchip, 2004). All lithium-ion battery packs as well as single cells include a 'last resort' protection circuit consisting of MOSFETs that configure accordingly in either common drain, common source, p-channel series connected with positive electrode or n-channel series connected with negative electrode depending on the application. The circuit only operates when voltages fall within the unstable regions. The charging method use to charge Lithium-ion/polymer batteries is the constant current - constant voltage charging method (CC-CV) (Yi-Hwa & Jen-Hao, 2006). The CC-CV charging method is employed on commercial battery charging ICs such as the LTC 4054-4.2 stand-alone battery charging IC (Linear Technology, 2010) and ensures that the battery voltage levels do not enter the unstable regions. The charging method consists of three separate stages employed to ensure the safe charging of the lithium-ion battery (see Figure 2.13).

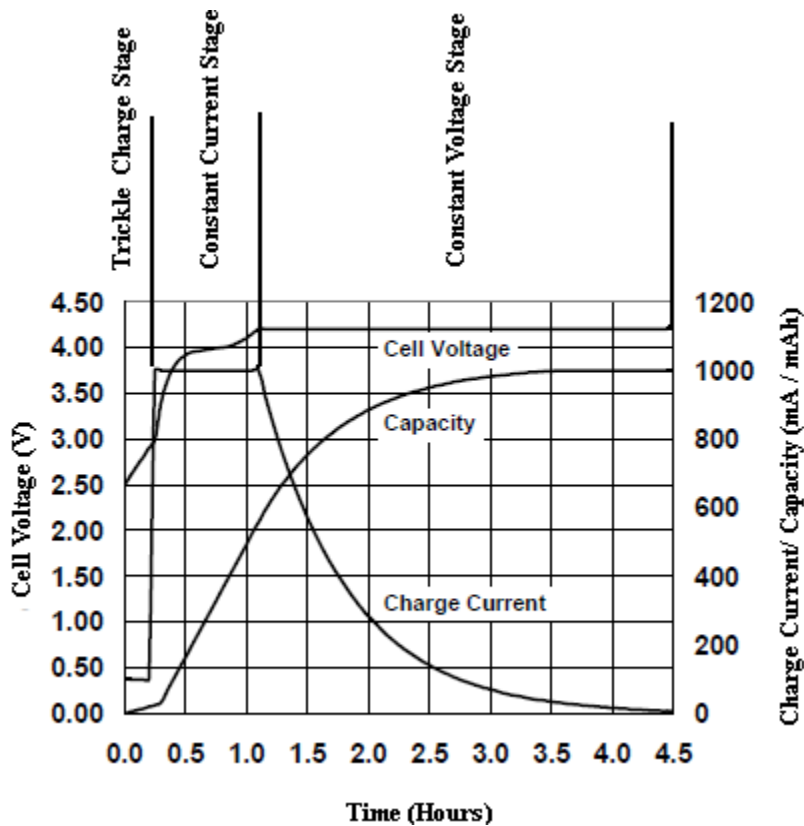


Figure 2.13: CC-CV charging profile (Dearborn, 2004)

Trickle Charge Stage: Trickle charge is employed to restore charge to cells that have been deeply depleted. Not utilising the trickle charge stage on deeply depleted cells damages the lithium-ion battery and decreases the capacity. Trickle charge is employed when the battery cell voltage falls within the 'over discharge' region. A constant current of 0.1C is used to charge the cell until the cell voltage has reached 3.8V.

Fast Charge Stage: Once the cell voltage has risen above the trickle charge threshold of 3.8V, the charge current is increased to less than 1.0C. Current is often ramped as the cell voltage rises. This is done in order to minimise heat dissipation.

Constant Voltage Stage: This mode is entered once the cell voltage has reached 4.2V. Charging at a voltage less than 4.2V may cause a decrease in battery capacity, as illustrated in Figure 2.14. The voltage should be regulated within a tolerance of $\pm 1\%$ in order to ensure maximum performance of the lithium-ion battery.

The charging process is terminated by sensing when the charge current drops below 7% of the battery capacity, or 0.07C. Another termination criterion is the implementation of a timer that times out the operation after a set amount of time, approximately two hours after the constant voltage stage is initiated. Advanced chargers implement a combination of the two or may even incorporate battery cell temperature, as this typically indicates when the battery has reached its optimal capacity.

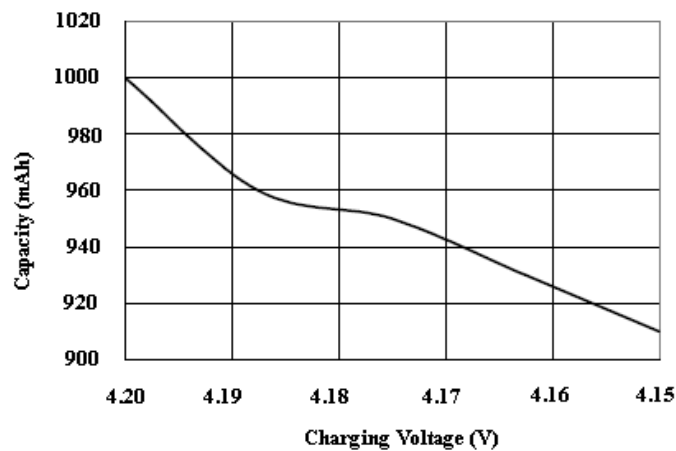


Figure 2.14: Loss in capacity at different charging voltages (Dearborn, 2004)

2.5 Field-Programmable-Gate-Arrays (FPGAs)

Digital Signal Processors (DSPs) and microcontrollers are most commonly used to implement algorithms (Wu, 2003; Hohm & Ropp, 2000); however, due to the flexibility of Field-Programmable-Gate-Arrays (FPGAs), FPGAs may offer equivalent or higher performance in comparison to DSPs. Table 2.4 provides a comparison between different FPGAs from different manufacturers. The features chosen for comparison are unique to the CubeSat design process as it addresses the SWAP constraints. The design requires an integrated analogue interface, a feature that allows the integration of multiple functions within the FPGA itself, while the FPGA itself should not require much board space.

Table 2.4: FPGA technology comparison

<u>Manufacturer</u>	<u>Product</u>	<u>Features</u>
Actel	SmartFusion	Up to 500 000 system gates Analogue Compute engine 8 direct analogue inputs 135 user I/O's
	IGLOO/e	Up to 3×10^6 system gates Flash*Freeze mode as low as 5 micro watt. No direct analogue inputs 135 user I/O's
	ProASIC3 nano	Up to 250 000 system gates No direct analogue inputs 71 user I/O
Xilinx	Spartan-6	Up to 150 000 Logic Cells No analogue inputs available 576 user I/O

	Virtex-6	Up to 760 000 Logic Cells Analogue inputs available 576 user I/O
	Virtex-7	Up to 2×10^6 Logic Cells Analogue inputs available 1 200 user I/O
Altera	Cyclone	Up to 20 060 Logic Elements No analogue inputs available 301 user I/O
	Cyclone II	Up to 68 416 Logic Elements Analogue inputs available 622 user I/O
	Cyclone III	Up to 119 088 Logic Elements Analogue inputs available 622 user I/O

Sources: 1) Microsemi SoC (2011); 2) Xilinx (n.d.); and 3) Altera. (n.d.)

It can be seen that FPGAs are able to integrate a large number of technologies within a single chip. Therefore, some functional blocks of the charging system may be implemented on an FPGA chip in order to streamline the design and prototyping process. Yi-Hwa, Jen-Chung, and Jen-Hao (2004) and Yi-Hwa and Jen-Hao (2006) proposed the design and implementation of a fully digital lithium-ion battery charging system using an FPGA. These papers discuss the use of an FPGA as the main controller, a multi-phase buck converter topology and a Graphical User Interface (GUI) for monitoring the parameters of the charge/discharge cycles. They were able to augment the charging of a lithium-ion battery to obtain an efficient charging cycle with charging ripple current of less than 1%. Person (2004) implemented a maximum power point tracking algorithm using an Altera FLEX 10K FPGA and produced an integrated MPPT system with ADC interface, FIR filter, dither generator, and DAC interface within the same FPGA, thus streamlining the prototyping process.

Table 2.5 provides FPGA technology and features from the Actel group. Products from Actel were considered primarily due to the close relationship between CP&T and ASIC Design Services, the sole vendor of Actel products in South Africa.

Table 2.5: Actel FPGA technologies (Microsemi SoC Product Group, 2011)

<u>Products</u>	<u>Features</u>
SmartFusion	Customisable System-on-Chip (cSoC)
Extended Temperature Fusion	Mixed signal integration down to -55 ⁰ C Reprogrammable digital logic and configurable analogue Embedded flash memory
IGLOO/e	Low power Small package footprint High logic density
IGLOO nano	Low power Small package footprint
IGLOO plus	Low power Small package footprint High I/O-to-Logic ratio
ProASIC 3/E	High logic density High performance Low cost
ProASIC 3L	High logic density High performance Low cost

The IGLOO devices of Actel have a power consumption as low as 5µW implementing their flash freeze mode with 30 000 available system gates and offering In-System Programming (ISP). Xilinx offers top of the range FPGAs, with the Artix-7 having the lowest power consumption mainly due to differences in available logic cells. The Artix-7 offers Agile Mixed Signal (AMS)/XADC with 12-bit resolution, 600 I/O pins with 19Mb of blockRAM.

Considering these technologies, together with availability and cost, the SmartFusion FPGA was selected as the main controller in this design.

The SmartFusion FPGA produced by Actel offers a customisable System-on-Chip (cSoC) that integrates an ARM Cortex – M3 processor, programmable analogue together with the standard FPGA fabric. The SmartFusion (cSoC) contains up to 500 000 system gates, a microcontroller sub-system with I²C interface, and a 32KHz low power oscillator, 1 ADC (8-12 bit-SAR) and one 12-bit sigma-delta DAC. The structure and operation of this FPGA will be discussed in the following section.

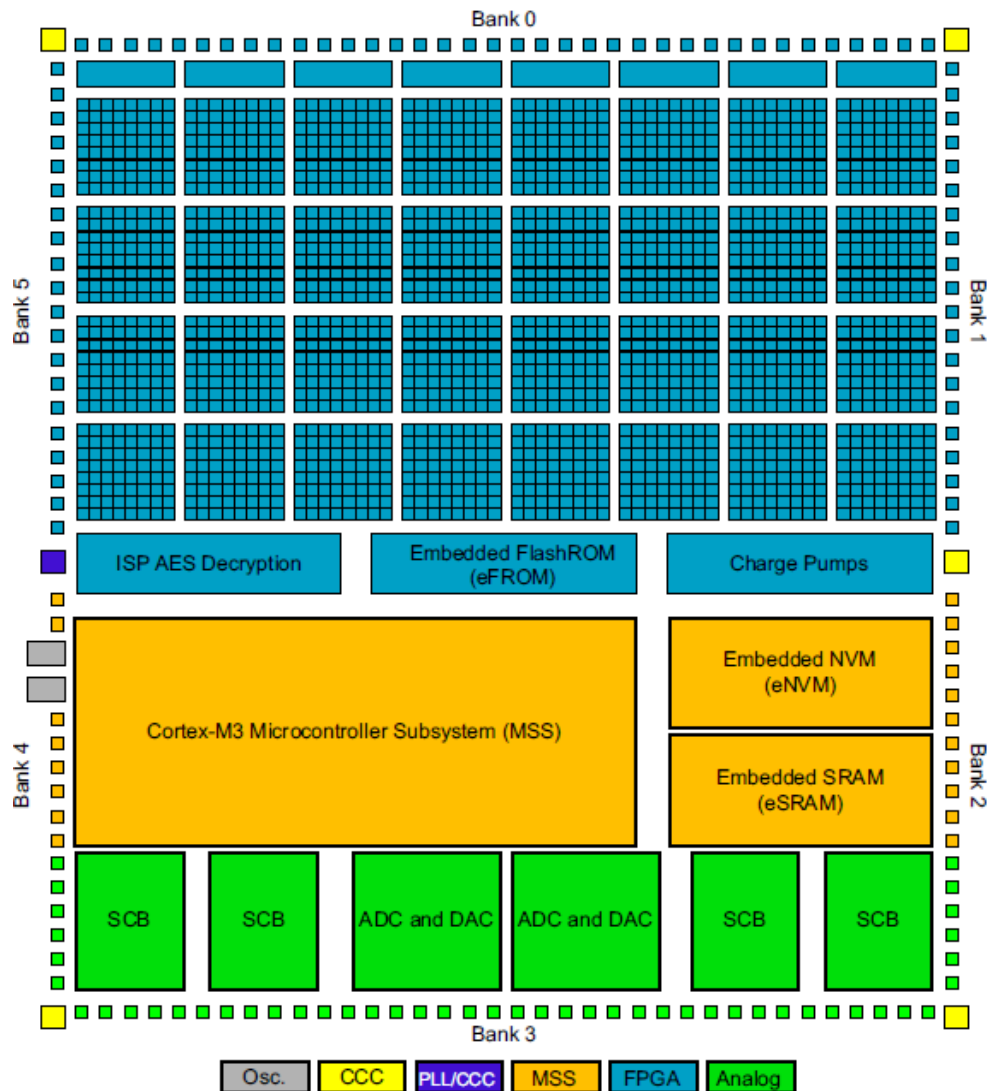


Figure 2.15: SmartFusion FPGA structure (Microsemi SoC Product Group, 2012)

2.5.1 Microcontroller Sub-System (MSS)

The MSS illustrated by the yellow section in Figure 2.15 possesses a 100 MHz Cortex-M3 processor capable of performing 125 million instructions per second (MIPS), and a multi-layer AHB bus matrix (AHB) that connects various peripherals. The AHB bus matrix allows either the Cortex-M3 processor, FPGA fabric master, Ethernet Message Authentication controller (MAC) or peripheral DMA (PDMA) controller to act as masters to the integrated peripherals. These integrated peripherals may include the FPGA fabric, embedded non-volatile memory (eNVM), embedded synchronous RAM (eSRAM), external memory controller (EMC), and analogue compute engine (ACE) blocks. This becomes an important factor as the MSS can handle multiple operations required for the operation of the EPS sub-system (Actel Corporation, 2010).

2.5.2 Analogue Front-End (AFE)

The AFE consists of a successive approximation register of analogue-to-digital converters (SAR ADC), first order sigma-delta digital-to-analogue converters (SDD DAC) and signal conditioning blocks (SCBs). These SCBs are made of a combination of active bipolar prescalers (ABPS), comparators to monitor fast signal thresholds without using the ADC, current monitors and temperature monitors which allow the SmartFusion FPGA to handle multiple analogue signals simultaneously, while the ABPS modules allow larger bipolar voltages to be fed to the ADC. An external sense resistor is used to convert voltages into a suitable range for the ADC while the temperature monitor is able to convert current internally by reading the current through an external p-n junction.

2.5.3 Analogue Compute Engine (ACE)

The various input signals are controlled and connected by the ACE. The ACE is a dedicated processor designed to relieve the Cortex-M3 processor from handling the analogue blocks, thereby allowing the Cortex-M3 processor to operate faster and with better overall power consumption. The ACE is built to handle sampling, sequencing, and post-processing of the ADCs, DACs, and SCBs. Figure 2.16 shows a block diagram of the ACE.

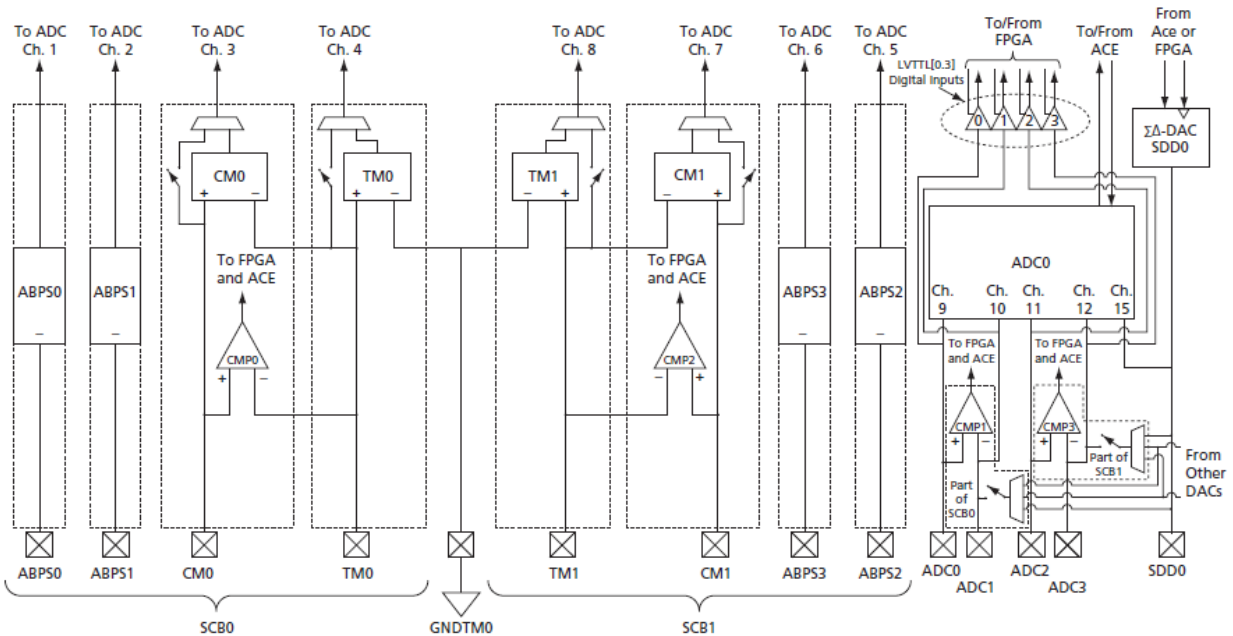


Figure 2.16: Analogue Compute Engine partial block diagram (Actel Corporation, 2010)

2.5.4 SmartFusion Power Usage

Power consumption of the SmartFusion FPGA is a function of the total amount of active functional blocks. These functional blocks form part of the four basic power components that contribute to the total power usage of the system: 1) in-rush power, 2) configuration power, 3) static power, and 4) dynamic power (Microsemi SoC Product Group, 2012).

2.5.4.1 In-Rush Power

The in-rush power is dependent on the amount of current available from the power supply. This occurs during the start-up stage of the FPGA as it requires logic array in-rush current to ramp up V_{cc} to its correct voltage level. The in-rush power is not required when V_{cc} reaches 90% of its final value (Microsemi SoC Product Group, 2012).

2.5.4.2 Configuration Power

During the configuration period of the FPGA, current is drawn to reset the device registers and enable the user I/O pins. This occurs due to the SRAM capability of the SmartFusion FPGA; however, the SRAM function does not need to be utilised in order to operate the SmartFusion FPGA. When this function is utilised, configuration data is stored in the erasable programmable

read only memory (EPROM) which requires current to read from the look-up table (LUT). This current is proportional to configuration power (Microsemi SoC Product Group, 2012).

2.5.4.3 Static Power

Static power refers to the idle condition of the FPGA; hence, no I/O activity and no clock inputs. This occurs after the FPGA has been powered up and configured: static current flows proportionally to the static power (Microsemi SoC Product Group, 2012).

2.5.4.4 Dynamic Power

The dynamic power of the SmartFusion FPGA is a function of all the operational activities of the device. These activities include the operation of internal gates, registers in use, number of clock lines, buffers, internal memory and any other switching of capacitive loads such as user I/O. It is noticed that the dynamic power consumption is highly dependent on the switched capacitance, routing capacitance and operating frequency (Microsemi SoC Product Group, 2012).

2.5.5 SmartFusion Power Calculation

The power consumption can be calculated using Equation 2.11 while including the number of Phase Locked Loops (PLLs), clock conditioning circuits (CCCs), as well as the number and frequency of each output clock, the internal clock frequencies and the number of I/O pins used in the design, the analogue block used in the design, the temperature monitor, current monitor, voltage monitor, ABPS, sigma-delta DAC, comparator, low power crystal oscillator, RC oscillator and main crystal oscillator. Figure 2.17 provides the power supply configuration of the SmartFusion FPGA.

$$P_{TOTAL} = P_{STAT} + P_{DYN} \quad (2.11)$$

where,

P_{STAT} is the total static power consumption and

P_{DYN} is the total dynamic power consumption.

The total power consumption of the SmartFusion FPGA can be further reduced by allowing the device to operate either in standby mode or time keeping mode. Microsemi has provided users of the SmartFusion FPGA with an easy to use Power Calculator using a basic Microsoft Excel

spread sheet. The user is asked to provide the MSS and analogue peripherals used in the design configuration as well as information concerning the I/O used in the design.

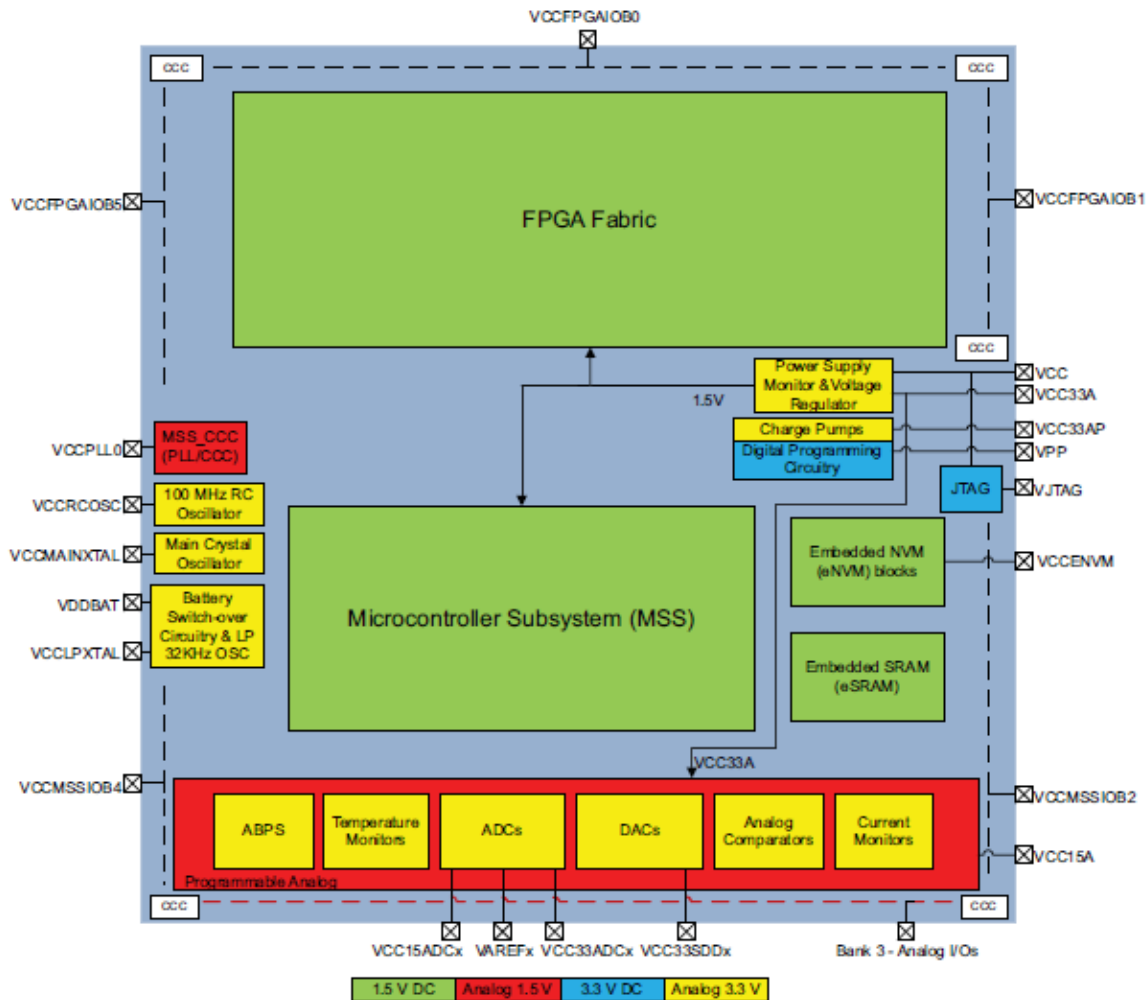


Figure 2.17: SmartFusion power supply configuration (Microsemi SoC Product Group, 2012)

2.6 Direct Energy Transfer (DET)

Direct Energy Transfer (DET) systems are shunt regulated systems whereby excess energy generated by the solar arrays are dissipated through resistor banks. These systems have no active components between the solar arrays and the satellite load. Figures 2.18 and 2.19 indicate DET systems with unregulated and regulated bus voltages:

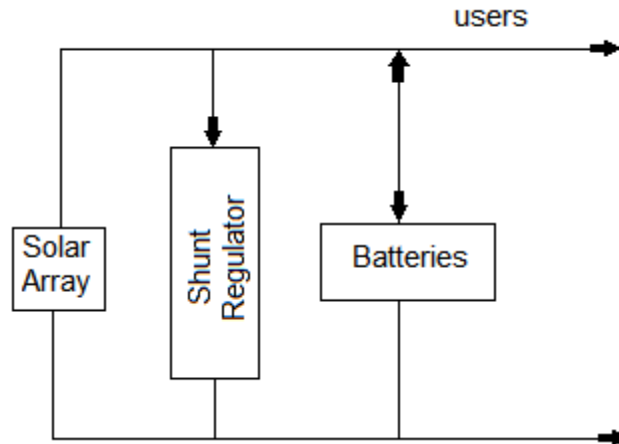


Figure 2.18: Shunt regulated DET system without bus regulation (Bester, 2011)

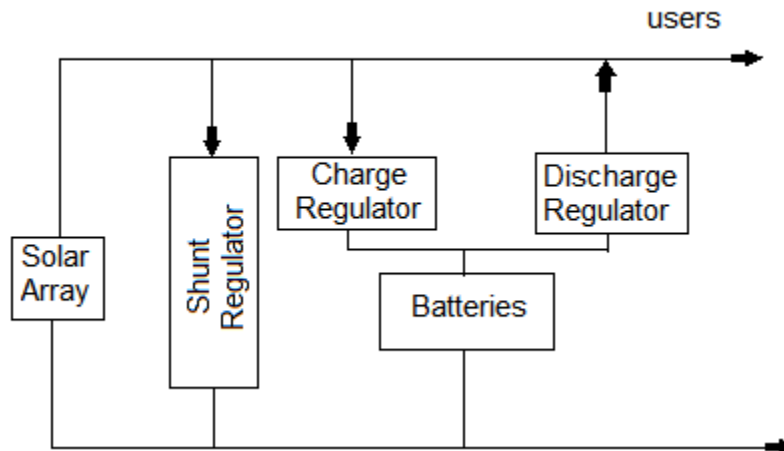


Figure 2.19: Shunt regulated DET system with bus regulation (Bester, 2011)

This topology was initially considered as a solution to the research problem; however, seeing that this topology only allows for near maximum power operation (Snyman & Enslin, 1993), it was not investigated any further.

2.7 Maximum Power Point Tracking (MPPT) Algorithms

Some satellites employ direct energy transfer (DET) methods whereby the solar array is connected directly to the satellite loads. The drawbacks that have arisen from such a topology are that the design requires using components that operate within a large range of input voltages, and also, the maximum power is not always delivered to the load as there is a

mismatch between the source and load impedances. As illustrated in Figure 2.20, the maximum power is a product of the solar cells characteristic open-circuit voltage and short-circuit current. This point varies with increasing and decreasing levels of solar irradiance as well as changing levels in operating temperatures, as discussed in Section 2.3.2. MPPT is achieved through the implementation of algorithms to change the duty cycle of a dc-dc converter in order to match the source and load impedances (Harjai *et al.*, 2010). Some of these algorithms are discussed in the next section.

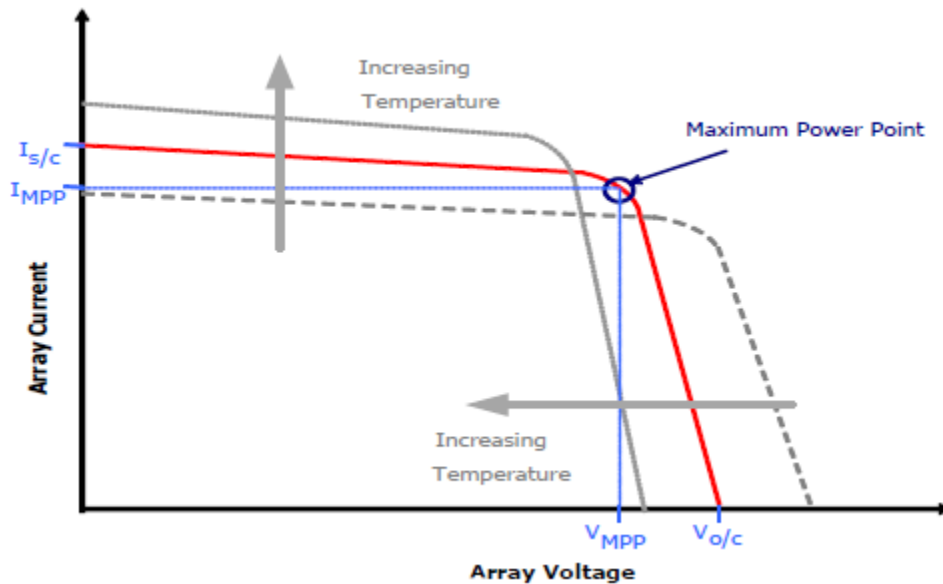


Figure 2.20: Maximum power point (Clark & Simon, 2007)

2.7.1 Perturb-and-Observe

The implementation of this algorithm requires only one voltage sensor or an optional current sensor in order to sense the voltage or current of the solar array. The perturb-and-observe (P&O) algorithm is thus the most cost-effective and least complex method when compared to other MPPT algorithms. The algorithm works by making small perturbations in the direction of maximum power. However, this method does not consider rapid changes in the level of irradiance which can lead to the calculation of the incorrect maximum power point.

2.7.2 Incremental Conductance

This method incorporates the use of two voltage and current sensors to sense output voltage and current of the solar array. This algorithm (see Equation 2.12) calculates the slope of power

change to voltage of the solar array and suggests that at maximum power the slope of the solar array is 0 watts.

$$(dP / dV)_{MPP} = d(VI) / dV , \quad (2.12)$$

$$0 = I + VdI / dV_{MPP} ,$$

$$dI / dV_{MPP} = -I / V .$$

By sensing both voltage and current, the rapid change in irradiance does not cause the calculation of the wrong maximum power point, thus reducing the error due to rapid changes in solar irradiance as opposed to the P&O method where this error is predominant (Ping *et al.*, 2011).

2.7.3 Fractional Open Circuit Voltage

A near linear relationship exists between the voltage at maximum power and the open circuit voltage of the Solar Array. This relationship holds for variations in temperature levels and irradiance. The implementation of this method works by creating a fractional open circuit in order to measure the open circuit voltage and then compute the maximum power point voltage using the linear relationship. This, however, causes a small interrupt in the power supply as the converter is required to shut down momentarily.

2.7.4 Fractional Short Circuit Current

Similarly to the fractional open circuit voltage method, the fractional short circuit current method relies on an approximated linear relationship between short circuit current and current at maximum power under varying atmospheric conditions. The implementation of this method requires an additional switch in order to periodically cause a short circuit across the Solar Array in order to determine the value of the short circuit current and then determine the maximum power point current using the linear relationship.

2.7.5 Neural Networks

Neural networks can consist of a large number of input parameters or nodes. These nodes are embedded into the three layers of the neural network: 1) input layer, 2) hidden layer, and 3) output layer. Neural networks are well-adapted for large microcontrollers as various input

parameters - open circuit voltage, short circuit current, temperature, and irradiance, for example - determine the change in a single or multiple output reference signal to drive the MPPT circuit (Harjai *et al.*, 2010).

The Table 2.6 summarises the implementation of these maximum power point tracking techniques:

Table 2.6: MPPT algorithm comparison (Harjai, Bhardwaj & Sandhibigraha, 2010)

<u>MPPT technique</u>	<u>Convergence speed</u>	<u>Implementation complexity</u>	<u>Periodic tuning</u>	<u>Sensed parameters</u>
Perturb-and-Observe	Varies	Low	No	Voltage or Current
Incremental conductance	Varies	Medium	No	Voltage, current
Fractional Open circuit	Medium	Low	Yes	Voltage
Fractional Short circuit	Medium	Medium	Yes	Current
Neural network	Fast	High	Yes	Varies

From the study of the various maximum power point tracking algorithms, the perturb-and-observe (P&O) method was implemented in the design due to its ease of implementation and low level of complexity. Considering the SWAP constraints, saving FPGA resources directly influences the power consumption of the device. Since only current or voltage can be used as the input parameter, only a single current or voltage monitor needs to be initialised for the implementation of the design, thereby decreasing the level of complexity of the design and also minimising the component count. The shortcomings of the P&O algorithm, as previously mentioned, may be addressed by the dedicated ACE of the SmartFusion FPGA as well as the high sampling rate, allowing the MSS to implement the P&O more effectively as the microcontroller sub-system does not need to spend resources on analogue to digital conversion, sample sequencing or post-processing of the measured signal.

Chapter 3

Prototype Design and Simulation

3.1 Overview of Design Solution

This section gives a detailed description of the design process followed to obtain the objectives of the EPS sub-system. A brief overview of the proposed solution is discussed, taking into consideration the environment in space, average orbit power produced, sizing of the secondary power source, maximum power point tracking and FPGA implementation. The section also provides simulation results for the above mentioned factors as well as the distribution system and active load design.

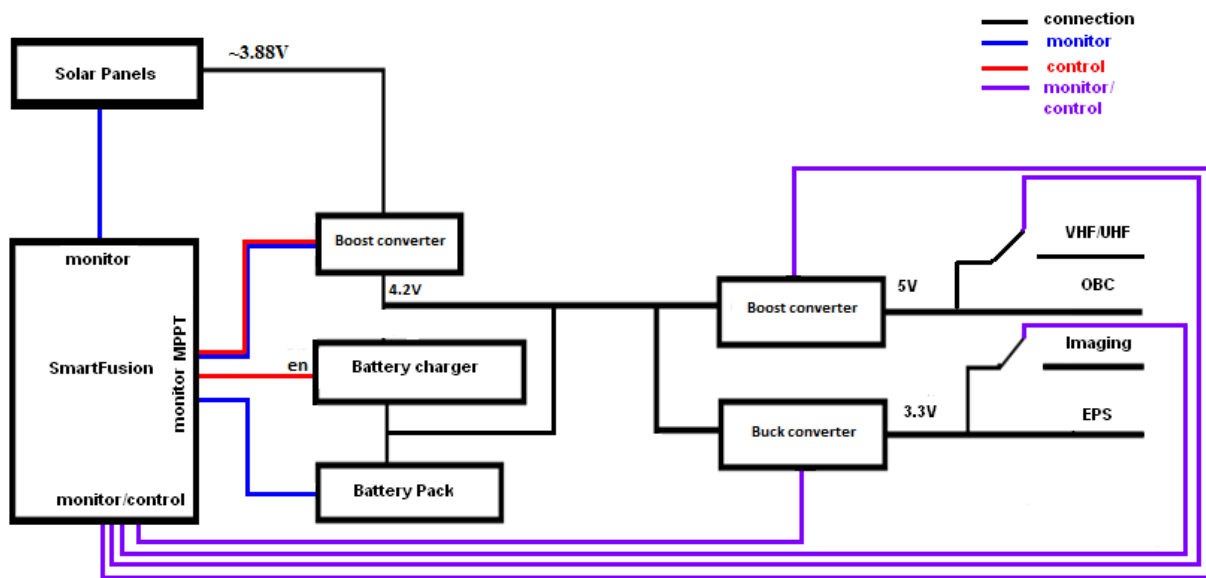


Figure 3.1: Proposed EPS design solution

Figure 3.1 provides a design overview of the proposed EPS sub-system. It consists of the SmartFusion FPGA as the main controller implementing the MPPT algorithm on the solar cells. The SmartFusion FPGA monitors various currents and voltages and provides the appropriate control signal in order to maintain system stability. The solar cells produce an output voltage of approximately 3.88V which is then boosted to 4.2V. This is done due to the normal operating voltage of Li-ion batteries being 3.7V and charging occurring at 4.2V. The battery charger receives an enable signal from the SmartFusion FPGA as soon as the battery voltage falls below a pre-set value. The battery charger implements the CC-CV charging strategy, ensuring that the optimal battery capacity is maintained. The distribution system consists of a boost converter as well as a buck converter regulating the output voltages at 5V and 3.3V respectively. The power delivery capability of each bus will be determined by completing a high level power budget. The power budget will take into account various factors such as input power, power losses, duration of sub-system activity and the power requirements for that duration from which a secondary power source may be sized accordingly.

3.2 Orbital Parameters

Orbital parameters form part of the top-level mission specifications. Parameters such as orbital height, inclination and orbital period play important roles in the mission as they will define the type of payload that can be used. These parameters determine the amount of time spent in the sun and thus the amount of time available for charging and the time spent in eclipse. The time spent in eclipse is a critical window as it is vital that the CubeSat stay operational within this window. The following equations are used to determine these critical parameters and are summarised in Table 3.1.

$$T_{orbit} = 2\pi\sqrt{\frac{a^3}{\mu}} \quad (3.1)$$

From Equation 3.1:

$$T_{orbit} = 2\pi\sqrt{\frac{(6378 + 800)^3}{3.986005 \times 10^{14}}}$$

$$T_{orbit} = (1.6585 \times 10^{14}) a^{3/2}$$

$$T_{orbit} = 100.86 \text{ min}$$

At an orbital height of 800km, an orbital period of approximately 100.86 minutes is expected.

Equations 3.2 and 3.3 provide an indication of the approximate time spent exposed to solar irradiance and time spent in eclipse respectively:

$$T_{sun} = \left(\frac{180^\circ + 2\alpha}{360^\circ} \right) T_{orbit} , \quad (3.2)$$

$$T_{eclipse} = \left(\frac{180^\circ - 2\alpha}{360^\circ} \right) T_{orbit} , \quad (3.3)$$

Equation 3.4 is used to calculate the value of α :

$$\alpha = \cos^{-1} \left(\frac{6378}{6378 + 800} \right) , \quad (3.4)$$

$$\alpha = 27.3086^\circ .$$

Using the value obtained from Equation 3.4, Equations 3.2 and 3.3 yield the following results:

$$T_{sun} = \left(\frac{180^\circ + 2(27.3086^\circ)}{360^\circ} \right) 100.86 \text{ min} ,$$

$$T_{sun} = 65.7319 \text{ min} .$$

$$T_{eclipse} = \left(\frac{180^\circ - 2(27.3086^\circ)}{360^\circ} \right) 100.86 \text{ min} ,$$

$$T_{eclipse} = 35.1281 \text{ min} .$$

Table 3.1: Orbital parameters

<u>Orbital Parameter</u>	<u>Specification</u>
Orbit classification	LEO
Orbital height	800 km
Inclination of orbit	27.3086 ⁰
Period of orbit	101 min
Time spent in the sun	66 min
Time spent in eclipse	35 min
Orbits per day	14.26
Orbits during extent of mission life time	5204

The calculated parameters indicate that a total time of 66 minutes of the 101 minute orbit is spent exposed to the sun. Sixty six minutes constitute 65.3% of the orbit allowed for battery charging while providing the CubeSat with the necessary power for operation of payloads and communication. Thirty five minutes is spent in eclipse, only allowing the operation of the critical sub-systems to ensure that the CubeSat continues to receive commands (Rx) so as not to lose contact/control of the CubeSat. The power budget will take these parameters into account and is further developed later in this chapter.

3.3 Solar Cell Power Produced

The average orbit power is a function of the solar cell characteristics, total area of the solar cell, and the angle of incidence as illustrated in Figure 3.2. Table 3.2 provides the electrical characteristics of the UTJ solar cells from Spectrolab while Figure 3.2 provides the total area of the aforementioned solar cells.

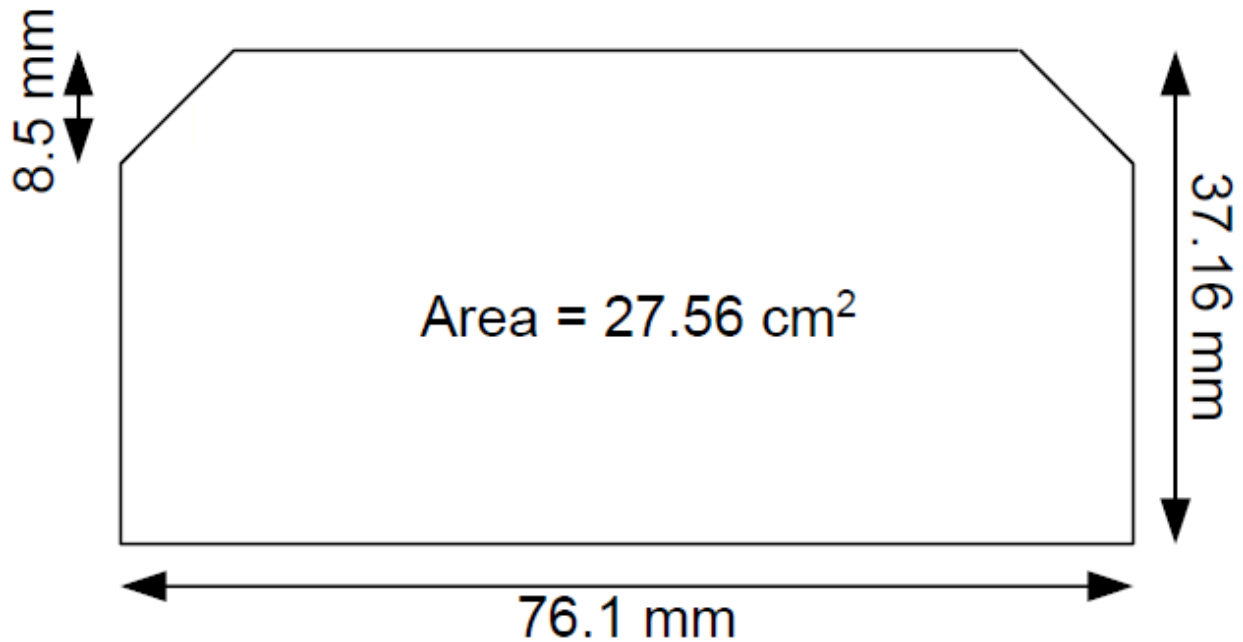
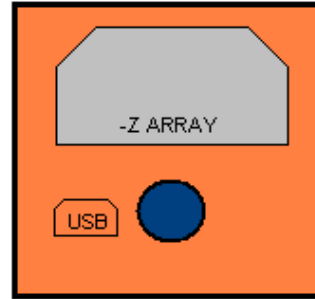
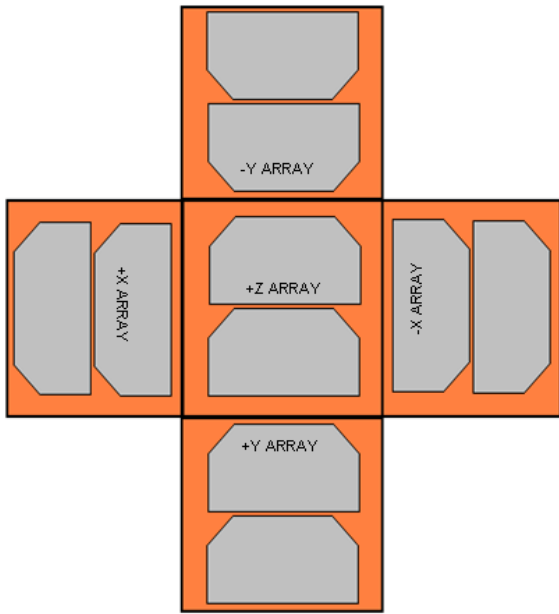


Figure 3.2: Solar cell area (Kjaer, 2002)

With the inspection of the solar cell layout (illustrated in Figure 3.3), it can be seen that each side can only house two of these solar cells. Figure 3.4 shows a three dimensional rendition of the solar cell layout. These solar cells are connected in parallel forming a one- series- two-parallel (1s2p) configuration. The solar cells can be connected in a 2s1p configuration; however, this would increase the total voltage of the system while the current produced remains that of one cell. Connection in the 1s2p configuration allows for an increase in current output of the solar cell while the voltage remains within the design limits. With the solar cell configuration decided upon, area known and electrical characteristics identified, the average orbit power may be calculated using the formula as indicated in Chapter 2. Equation 2.7 is used to calculate the power at 90° angle of incidence; however, this is the maximum power that can be produced by the solar cells, since the angle of incidence is always changing due to the CubeSat orbiting the earth, as well as the fact that spin stabilisation is implemented in order to control the attitude of the CubeSat. Equation 2.8 is used to calculate the power produced by the three sides as the angle of incidence changes. Thus the maximum power per side can be calculated using Equation 2.9, as this equation allows us to calculate the power produced according to the solar cell (1s2p) configuration as discussed earlier. Equation 2.10 provides a relation between the different sides. This formula becomes more effective when the solar cells are not of a symmetrical configuration. A MATLAB[®] code (Appendix C) was implemented using Equation 2.8 in order to obtain the average orbit power produced by the solar cells.



b) Bottom solar cell configuration

a) Top and side solar cell configuration

Figure 3.3: Solar cell layout

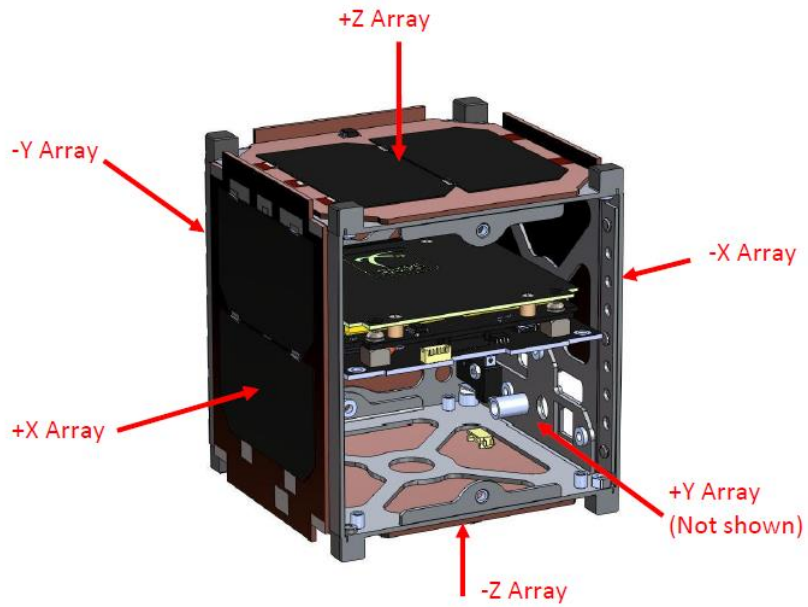


Figure 3.4: 3-D rendition of proposed solar cell layout

Table 3.2: UTJ electrical properties

<u>Parameters</u>	<u>< 32cm²</u>	<u>> 50cm²</u>
Jsc	17.05mA/cm ²	17.05mA/cm ²
Jmp	16.30mA/cm ²	16.30mA/cm ²
Jload _{min avg}	16.40mA/cm ²	16.40mA/cm ²
Voc	2.660V	2.660V
Vmp	2.350V	2.350V
Vload	2.310V	2.310V
Cff	0.85	0.85
Effload	28.0%	28.0%
Effmp	28.3%	28.3%

Table 3.3: Solar cell average power

<u>Parameters</u>	<u>Calculated values</u>
P _{mpp(top)}	2.11W
P _{mpp(side)}	2.11W
P _{max(array)}	2.9840W
P _{avg(array)}	2.1941W

The average power calculations were based on the MATLAB[®] script from Bester (2011). The script file was modified and adjusted to meet the specifications of the solar cell layout as well as the electrical characteristics of the UTJ 28.3% solar cell. The results are tabulated in Table 3.3.

Table 3.3 indicates that the expected average orbit power using the 1s2p solar cell configuration yields an output of 2.19W while the maximum power is expected to be 2.9840W. The power produced forms part of the CubeSat mission constraints as this factor would determine the operating power available to the payloads and other critical sub-systems.

3.4 Power Budget and Secondary Power Source Sizing

Traditionally the power budget is the starting point of the satellite design process as this contains information regarding the satellite payload and operational requirements of critical sub-systems. The size of the satellite thus depends on the power required to be harnessed as the primary source of power needs to be sized accordingly. However, the CubeSat design process starts by calculating the amount of power available for the particular design, then determining the power budget for the CubeSat and its payloads, and finally the prototype design.

As previously noted, simulations indicate that the average orbit power is expected to be 2.11W and maximum power of 2.9840W. From this it can be determined whether or not the solar cells are able to drive the necessary sub-systems as well as the size of the secondary power source in order to overcome the eclipse period.

A high-level power budget was constructed using information from the existing ZA-CUBE 01 mission and CubeSat missions as specified in Appendix A. Appendix E shows the power budget as constructed using Microsoft Excel. The power budget indicates the various sub-systems to be included in the CubeSat, and the amount of power these sub-systems utilise during the various periods of operation indicated in by the duty cycle column. The power budget is further analysed and summarised in Table 3.4 while Table 3.5 and Table 3.6 indicate the active sub-systems during the eclipse period and the period while exposed to the sun, respectively, also indicating expected operating voltages and power.

From the power budget, which includes a design margin of 5% and a minimum expected system efficiency of 76.5%, the power delivery capability of each distribution bus is determined. The 5V distribution bus is expected to deliver a total amount of 1747.6mW, while the 3.3V distribution bus is expected to be able to deliver a total amount of 1024.78mW. Calculations determine the amount of current required by each distribution bus. Equation 3.5 is used to determine the current of each of the two distribution busses.

Table 3.4: Power budget summary

<u>Sub-system</u>	<u>3.3V bus</u>	<u>5V bus</u>
FPGA	330mW	—
OBC	—	110mW
Battery Heater	220mW	—
VHF(Rx)	—	250mW
Imaging	247.5mW	—
UHF(Tx)	—	1000mw
Sub-Total	797.5mW	1360mW
Design margin (5%)	39.87mW	68mW
Power System efficiency (76.5%)	187.41mW	319.6mW
Total	1024.78mW	1747.6mW

$$P = VI \quad (3.5)$$

$$1027.78mW = 3.3(I)$$

$$1747.6mW = 5(I)$$

$$I = 311.48mA$$

$$I = 349.52mA$$

$$I_{total} = 661mA$$

The total amount of current required is the sum of the currents. This can be converted to milli-amp hours (mAh) which can be used to determine the battery capacity in watt-hours. Equation 3.6 is used to calculate the capacity of the battery.

$$E = C \times V_{avg} \quad (3.6)$$

where,

E = Energy stored in watt-hours

C = Capacity in amp-hours

V_{avg} = Average voltage during discharge

$$E = 661mAh \times 4.2V ,$$

$$E = 2.77Wh .$$

This indicates that the minimum capacity of the secondary power source in order to provide sufficient power to the sub-systems for a period of one hour after the loss of input power from the primary source of power is 2.77Wh. However, the secondary power source should be rated according to the power requirements during the eclipse period. Table 3.5 provides a breakdown of power consumption during the eclipse period.

Table 3.5: Power usage during eclipse

<u>Sub-system</u>	<u>3.3V bus</u>	<u>5V bus</u>
EPS	330mW	—
OBC	—	110mW
VHF	—	250mW
Design margin	22mW	18mW
efficiencies	115.5mW	94.5mW
Total	467.5mW	472.5mW

The minimum battery capacity required to overcome the eclipse period can be calculated using the fundamental formula $P = VI$.

Thus the 3.3V bus required capacity:

$$I_{e_{3.3}} = \frac{467.5mW}{3.3V} ,$$

$$I_{e_{3.3}} = 141.7mA.$$

5V bus required capacity:

$$I_{e_{5}} = \frac{472.5mW}{5V},$$

$$I_{e_{5}} = 94.5mA,$$

Where $I_{e_{3.3}}$ is the current required during eclipse on the 3.3V bus and $I_{e_{5}}$ is the current during eclipse on the 5V bus.

Thus, the total current can be calculated as follows:

$$I_{e_{total}} = I_{e_{3.3}} + I_{e_{5}}, \quad (3.7)$$

$$I_{e_{total}} = 141.7mA + 94.5mA,$$

$$I_{e_{total}} = 236mA.$$

The total eclipse period constitutes 34.82% of the total time spent in orbit amounting to 35.1281 minutes in eclipse. The secondary power source must be able to supply 236.2mA for 35.1281 minutes to overcome the eclipse period. The battery would therefore be operating at 236.2mAh for a period of approximately 35.1281 minutes. The total amount of energy removed from the battery during this period was found to be 580.808mWh.

Using Equation 3.6

$$\begin{aligned} E &= C \times V_{avg}, \\ &= 236.2mA \times 4.2V, \\ &= (992.04mWh / 60) \times 35.128, \\ &= 580.808mWh. \end{aligned}$$

Calculating Depth-of-Discharge (DoD)

$$= 580.808mWh / 4.2V ,$$

$$= 138.287mA ,$$

$$= 138.287mA / 1000mA .$$

= 13.828% discharge if a 1000mAh battery is used.

Discharging the battery to a DoD of 13.828% increases the number of charge/discharge cycles that the battery can undergo. This would then increase the battery lifetime as well as meet the end-of-life requirements. Similar steps are followed in order to determine the DoD if the batteries were allowed to operate during the period of exposure to the sun.

Table 3.6: Power usage while exposed to sun

<u>Sub-system</u>	<u>3.3V bus</u>	<u>5V bus</u>
EPS	330mW	-
OBC	-	110mW
VHF/UHF	-	401.5mW
Imaging	24.75mW	-
Design margin	17.738mW	25.575mW
Efficiencies	93.122mW	134.268mW
Total	465.61mW	671.34mW

The minimum battery capacity required to overcome the period while exposed to the sun can be calculated using the fundamental formula $P = VI$.

Thus the 3.3V bus required capacity:

$$I_{s_3.3} = \frac{465.61mW}{3.3V} ,$$

$$I_{s_3.3} = 141.094mA .$$

5V bus required capacity:

$$I_{s_5} = \frac{671.34mW}{5V},$$

$$I_{s_5} = 134.268mA.$$

where $I_{s_3.3}$ is the current during sun exposure on the 3.3V bus and I_{s_5} is the current during sun exposure on the 5V bus.

Thus the total current can be calculated as follows:

$$I_{s_total} = I_{s_3.3} + I_{s_5},$$

$$I_{s_total} = 141.094mA + 134.268mA,$$

$$I_{s_total} = 275.362mA.$$

The total sun period constitutes 65.18% of the total time spent in orbit, amounting to 65.73217 minutes of sun exposure. The secondary power source must be able to supply 275.362mA for 65.73217 minutes to overcome the period of sun exposure if the solar cells were to fail. The energy required was found to be 1267.009mWh and is calculated below:

Using Equation 3.6

$$E = C \times V_{avg},$$

$$= 275.362mA \times 4.2V,$$

$$= (1156.520mWh / 60) \times 65.73217,$$

$$= 1267.009mWh.$$

Calculating Depth-of-Discharge:

$$= 1267.009mWh / 4.2V,$$

$$= 301.669mAh,$$

$$= 301.669mAh / 1000mAh,$$

= 30.167% discharge.

From the above calculations, Table 3.7 summarises the energy utilisation during the period of eclipse, exposure to the sun, and total energy; however, in order to calculate the capacity of the secondary source of power, only the parameters during eclipse are considered as a battery's main function is to provide enough energy to the CubeSat sub-systems in order to remain functional throughout the eclipse period.

Table 3.7: Energy utilisation

<u>Parameter</u>		<u>Eclipse</u>	<u>Sun exposure</u>	<u>Total per orbit</u>
Current	3.3V bus	141.7mA	141.094mA	282.794mA
	5V bus	94.5mA	134.268mA	228.768mA
Energy		580.808mWh	1267.009mWh	1099.25mWh
DoD		13.828%	30.167%	n/a

Table 3.8 indicates the battery characteristics in order to achieve the desired DoD and overcome the eclipse period. These characteristics fall well into the SWAP constraints of the CubeSat design as the battery technology chosen is of the Li-Ion/Polymer type and weighs approximately 16g.

The average orbit power of 2.19W should be able to supply the payloads and sub-systems during the period while exposed to the sun. This is calculated to determine whether or not the batteries will be able to supply the loads if maximum power is drawn (i.e. all the loads are operating at the same time) which is not advantageous as this would decrease the lifetime of the batteries. Table 3.6 reveals that the total power on during the period while exposed to the sun yields 1.137W, allowing for 1.053W to be utilised in order to charge the secondary source of power.

Table 3.8: Battery characteristics required

Minimum Capacity		960mAh
Typical capacity		1000mAh
Nominal Voltage		3.7V
Charging method		CC-CV
Charging Voltage		4.2V
Discharge voltage (cut-off)		2.75V
Charging current		500mA
Ambient temperature	Charge	0-40 ⁰ C
	Discharge	-20-60 ⁰ C
	Storage	-20-45 ⁰ C
Weight		16g±2g
Volumetric energy density		387Wh/l
Gravemetric energy density		200Wh/kg
Cycle life		More than 500 cycles (to 80% initial capacity)
AC-impedance		60mΩ (at 1Khz frequency)
Nominal energy		3.7Wh (2W power load from 4.2V to 3.0V)

3.5 Perturb-and-Observe Maximum Power Point Tracking Algorithm

The Perturb-and-observe (P&O) maximum power point tracking algorithm is the most basic and therefore the most commonly used MPPT algorithm. The algorithm was chosen due to the ease of implementation and level of complexity, and because only a current or voltage input is required to perform the algorithm. This becomes critically important as we are trying to save

FPGA resources utilised in this design as the amount of FPGA resources used directly affects the power consumption of the FPGA device.

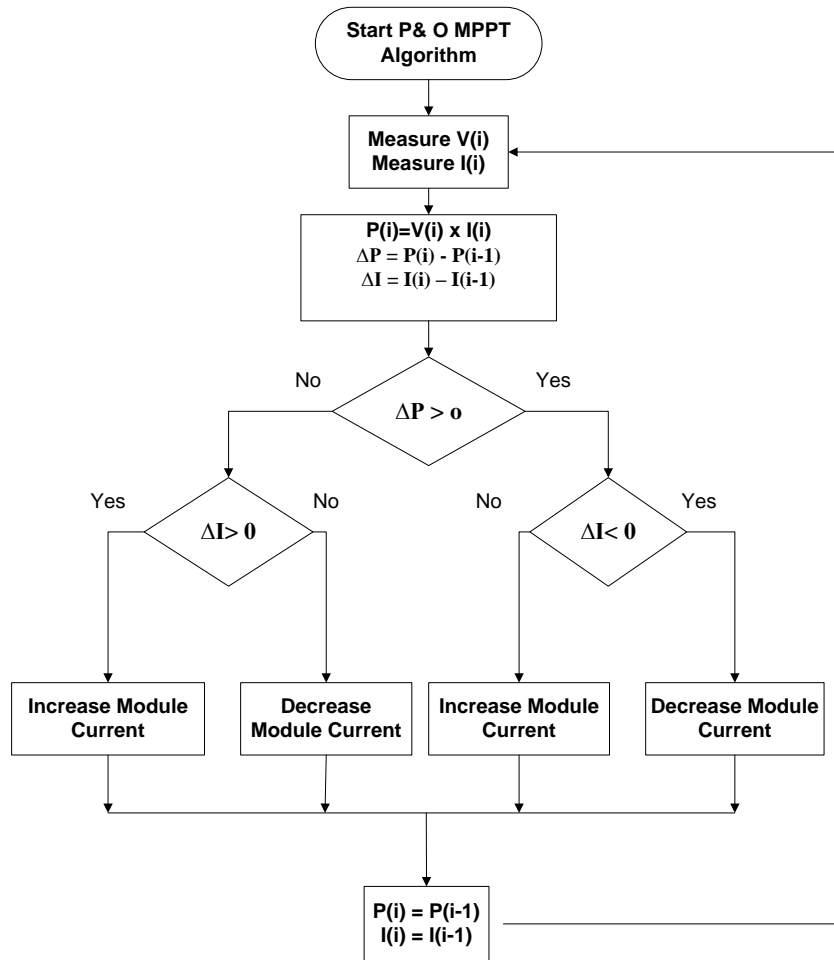


Figure 3.5: Perturb-and-observe MPPT algorithm

Figure 3.5 shows a flowchart of the P&O algorithm which starts by measuring the voltage $V(i)$ and current $I(i)$ of the module. These values are used to calculate the power of the module. These parameters are then stored and used to calculate the change in the total power dissipation and voltage. When the difference between the last two power and current measurements are positive or both are negative, an increase in module current is brought about by increasing the duty cycle of the converter depicted in Figure 3.6 with a calculated value. This value can be configured as the gradient of the power vs. voltage curve (Mellit et al., 2010) ensuring that the perturbations of the duty cycle are well-matched with changes in environmental conditions (i.e. changing level of solar irradiation). A decrease in the duty cycle of

the converter is brought about through a decrease in the difference between the power and an increase in the difference of the current of the last two measurements. A decrease in duty cycle can also be brought about by an increase in the difference between the power and a decrease in the difference of the current between the last two measurements. This logic is summarised in Table 3.9. Figure 3.6 shows the MPPT circuit diagram and indicates the closed loop control path that is implemented in the dc-dc converter used in its implementation.

Table 3.9: P&O logic decisions

<u>Power</u>	<u>Current</u>	<u>Duty cycle</u>	<u>Decision</u>
$\Delta P > 0$	$\Delta I > 0$	$+\Delta D$	Increase module current
$\Delta P < 0$	$\Delta I < 0$	$+\Delta D$	Increase module current
$\Delta P > 0$	$\Delta I < 0$	$-\Delta D$	Decrease module current
$\Delta P < 0$	$\Delta I > 0$	$-\Delta D$	Decrease module current

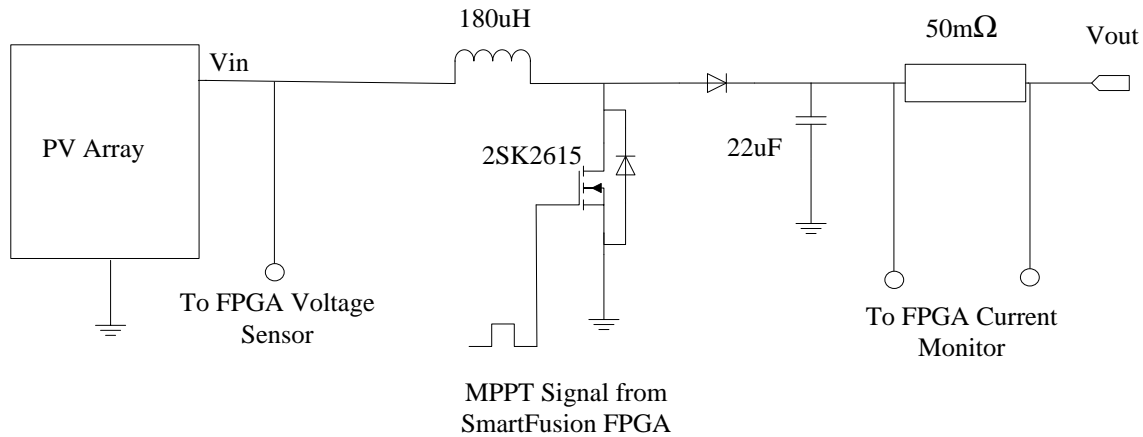


Figure 3.6: MPPT implementation

The circuit diagram in Figure 3.6 shows the parameters to be measured by the SmartFusion FPGA as well as the PWM control output signal required for maximum power point tracking operation. The circuit design and design parameters are found in Appendix F.

3.6 Distribution System and Load Switching

3.6.1 5V Bus design

A typical boost converter was chosen as the converter topology for this design. The components design can be found in Appendix J. Figure 3.7 shows the dc-dc converter topology as well as the various control signals from the SmartFusion FPGA.

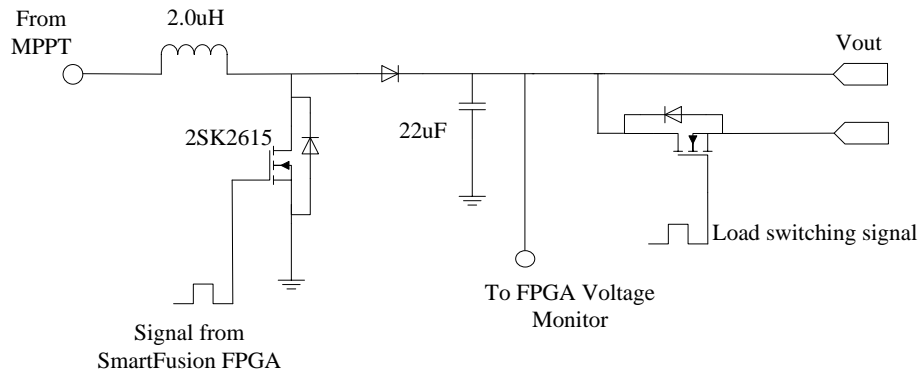


Figure 3.7: Boost converter circuit

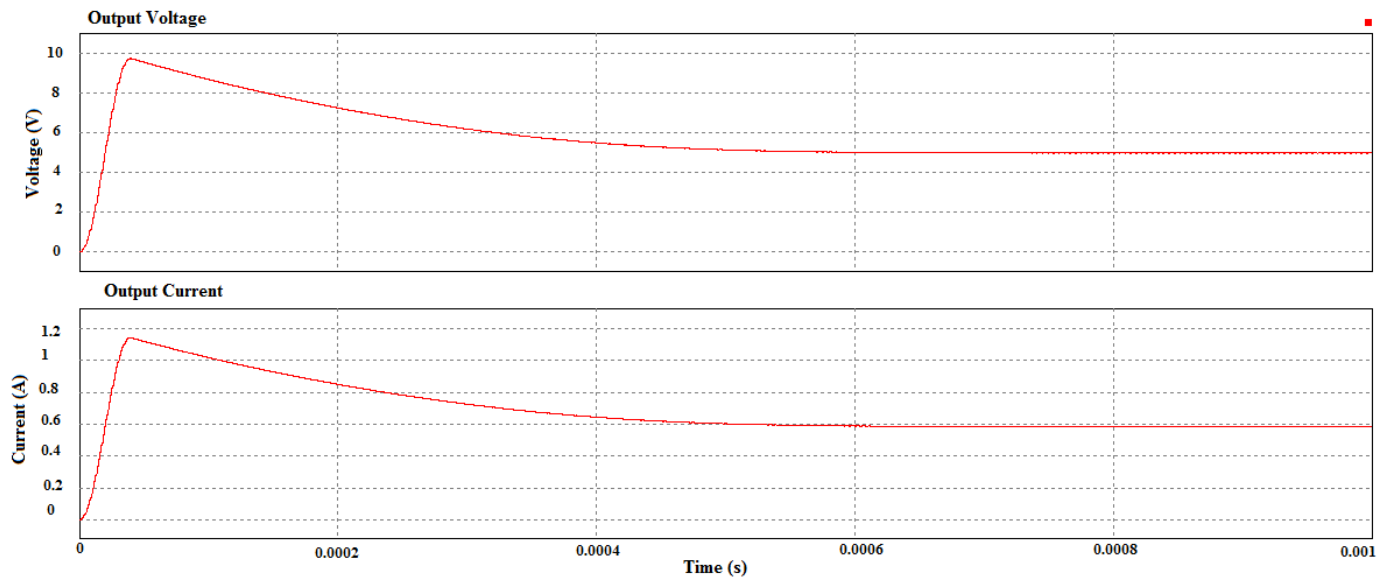


Figure 3.8: Boost converter output voltage and current

Simulations were conducted using PSIM[®] simulation software. Figure 3.8 shows an output voltage of 5V with an output current of approximate 590mA.

3.6.2 3.3V Bus Design

The buck converter topology illustrated in Figure 3.9 was chosen to decrease the voltage from 4.2V to 3.3V. The components design can be found in Appendix J.

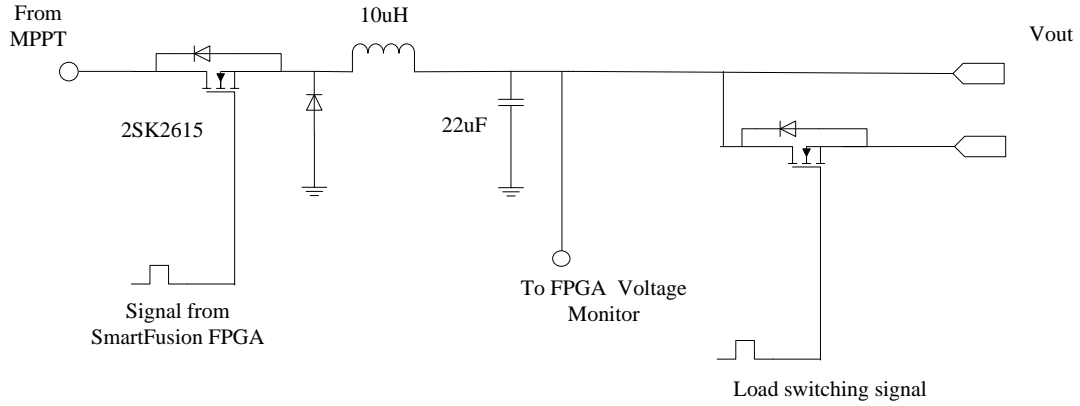


Figure 3.9: Buck converter circuit

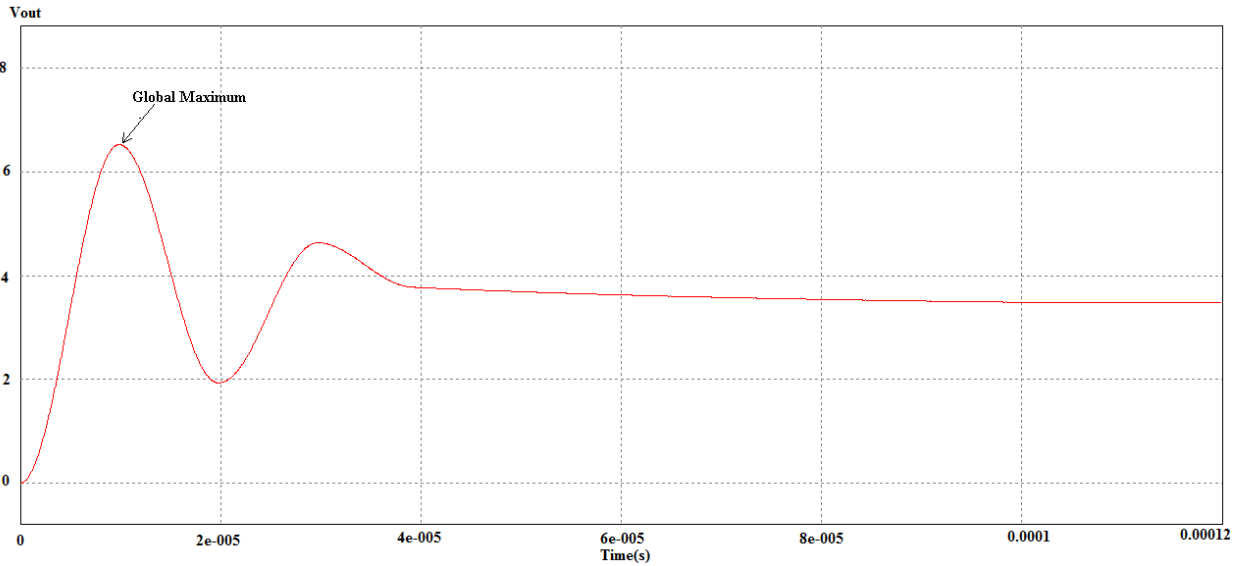


Figure 3.10: Buck converter output voltage

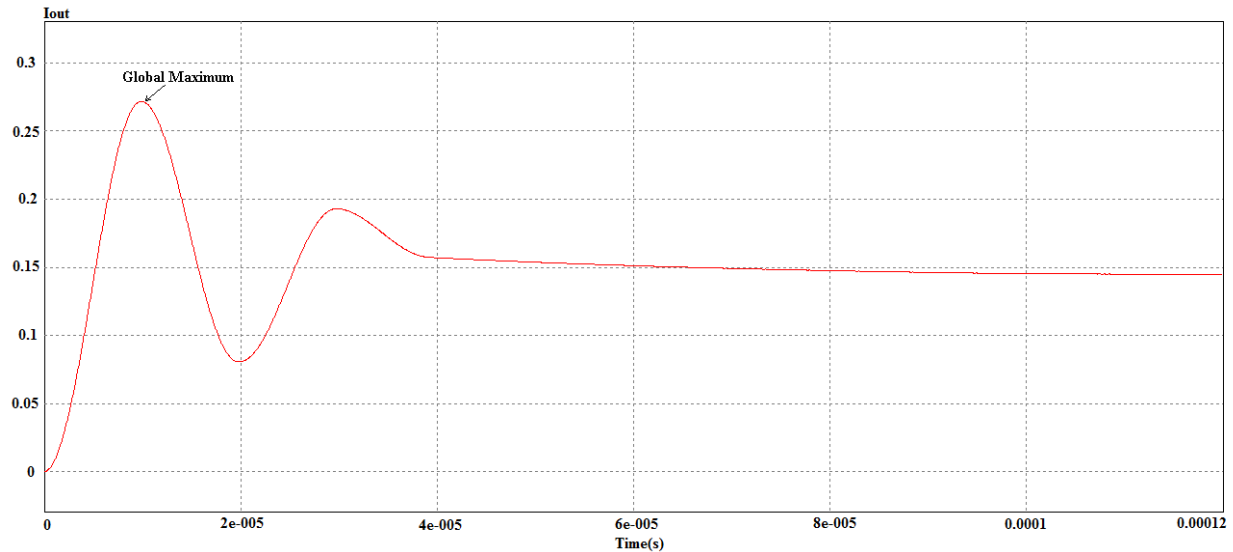


Figure 3.11: Buck converter output current

Simulations were conducted using PSIM[®] simulation software. Figures 3.10 show an output voltage of 3.3V with an output current of approximately 140mA indicated in Figure 3.11.

3.7 Active Load Design

The TIP 122 was used to produce an active load that can be used as a “dummy” load in order to simulate the various payloads and sub-systems. The payloads and sub-systems to be simulated by the active load are the following: battery heater, OBC, Imaging, and VHF and UHF antennas. The active load was designed with a 10k Ω potentiometer in series with a 2k Ω resistor. A diode D2, as illustrated in Figure 3.12 and Figure 3.14, was used to ensure current flowing through the emitter to allow the correct operation of the TIP 122 power transistor. Circuits were designed to be used on the 3.3V bus and 5V bus as illustrated by the aforementioned figures respectively.

The circuits were designed to handle a maximum of 5W on the 3.3V bus and 13W on the 5V bus. This was done to simulate various load handling capabilities of the system. By varying the potentiometer, the system response to changing load conditions can be examined.

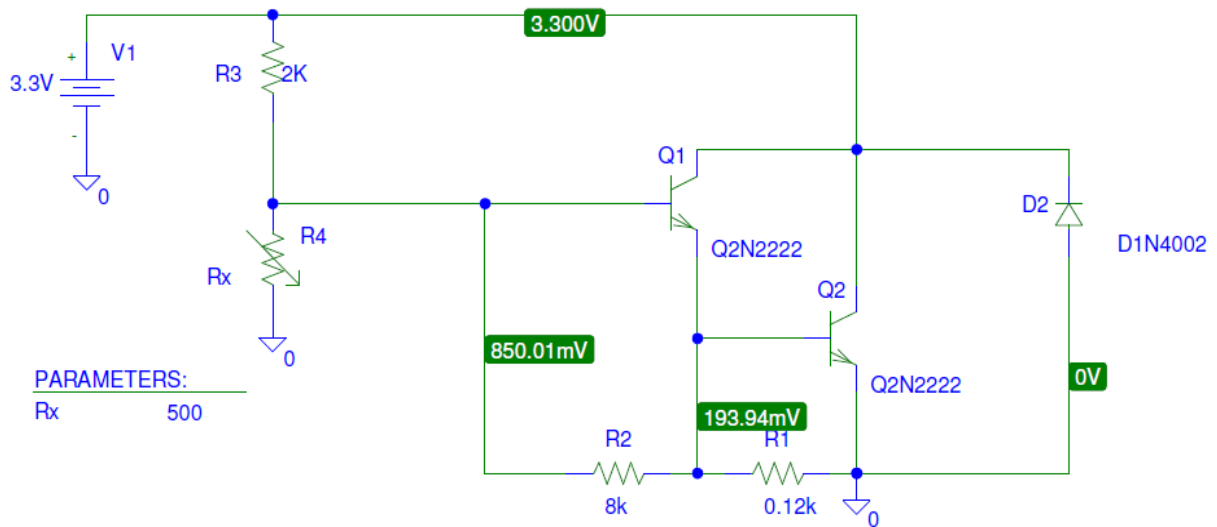


Figure 3.12: TIP 122 circuit diagram 3.3V bus

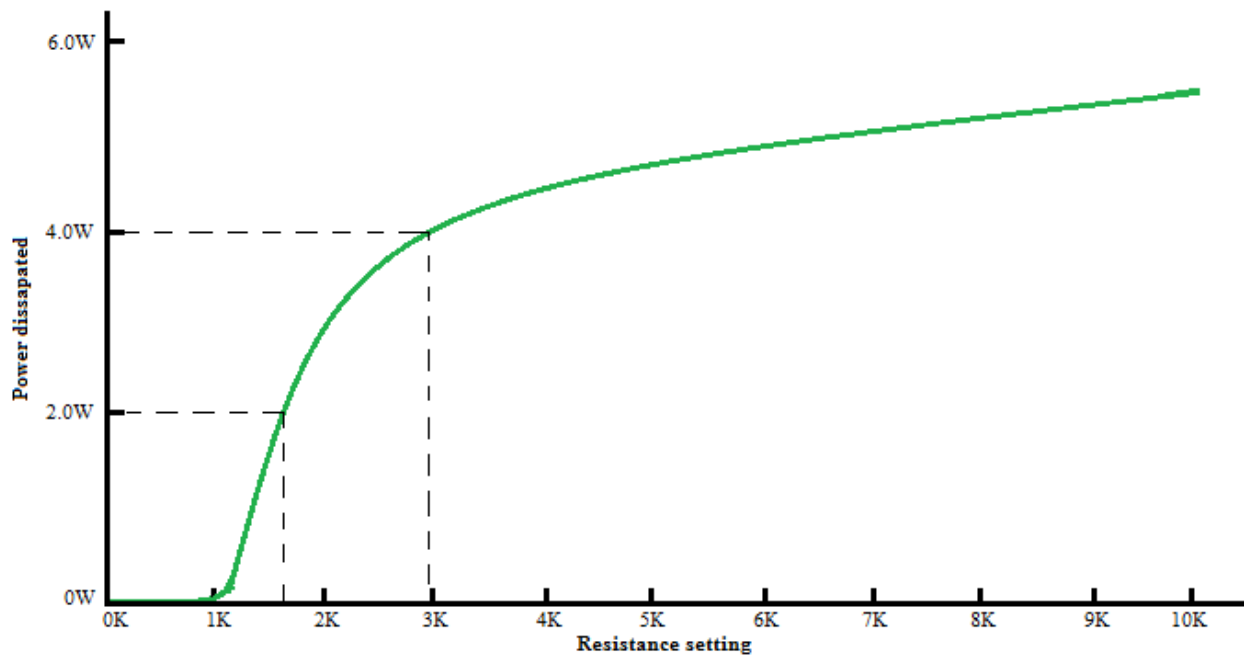


Figure 3.13: TIP 122 3.3V bus simulation results

Figure 3.13 shows that by varying the potentiometer located on the 3.3V bus between 1kΩ and 1.6kΩ, a maximum of 2W can be dissipated. Similarly Figure 3.15 indicates that varying the potentiometer located on the 5V bus between 500Ω and 1kΩ yields a maximum power dissipation of 5W.

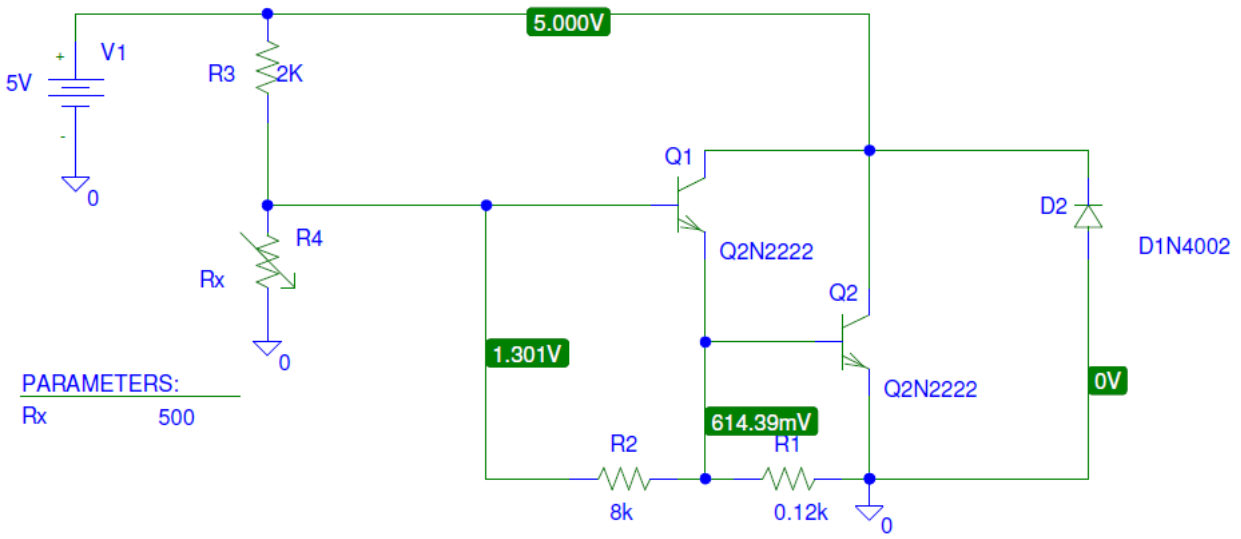


Figure 3.14: TIP 122 circuit diagram 5V bus

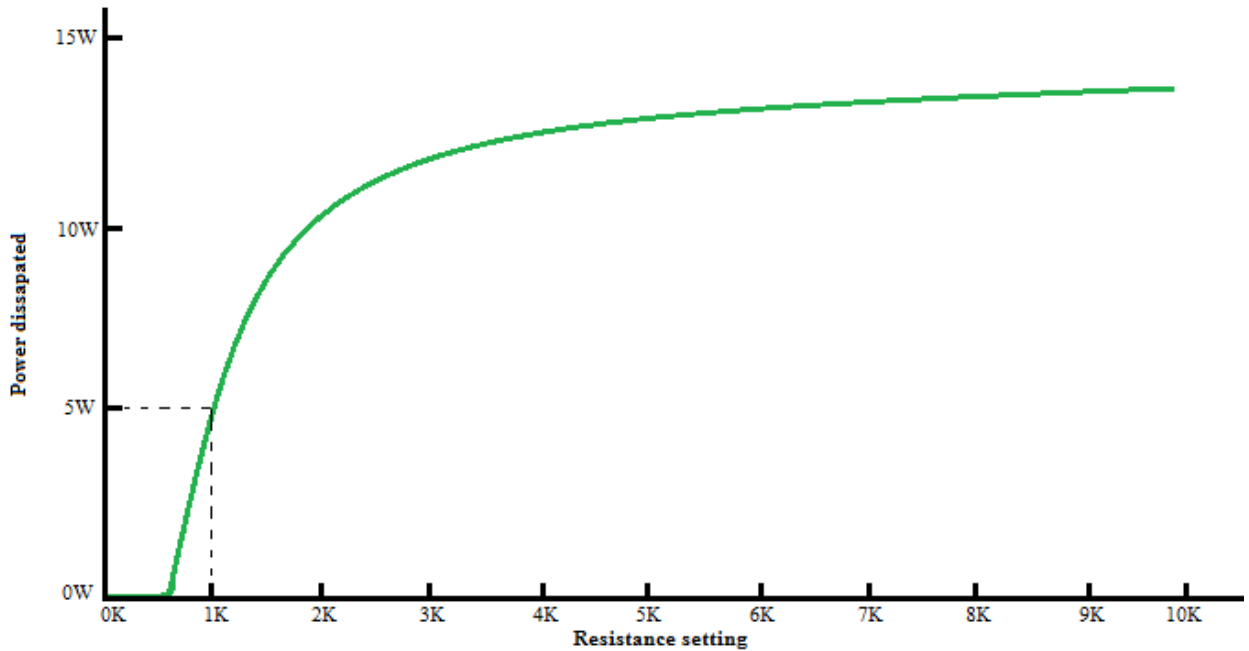


Figure 3.15: TTP 122 5V bus simulation results

In order to effectively dissipate the heat generated by the power transistor and thereby protect the active load circuitry, an effective heat sink has to be used. The appropriate heat sink was selected through the utilisation of the following heat transfer equations.

$$T_j = Pd(\Theta_{jc} + \Theta_{cs} + \Theta_{sa}) + T_a \quad (3.8)$$

$$\Theta_{ja} = \Theta_{jc} + \Theta_{cs} + \Theta_{sa} \quad (3.9)$$

$$T_j = Pd\Theta_{ja} + T_a \quad (3.10)$$

Thus,

$$P = \frac{T_j - T_a}{\Theta_{ja}} \quad (3.11)$$

$$P = \frac{150 - 30}{62.5}$$

$$P = 1.92W$$

1.92W is less than the required 10W.

Therefore,

$$\Theta_{ja} = \frac{T_j - T_a}{P} \quad (3.12)$$

$$\Theta_{ja} = \frac{150 - 30}{10}$$

$$\Theta_{ja} = 12^{\circ}C/W$$

To find the heat dissipating capability of the required heat sink, calculate Θ_{sa} :

$$\Theta_{sa} = \Theta_{ja} - \Theta_{jc} - \Theta_{cs} \quad (3.13)$$

$$\Theta_{sa} = 12 - 1.92 - 0.52$$

$$\Theta_{sa} = 9.56^{\circ}C/W$$

A heat sink with 9.56 °C/W was chosen to ensure the safe operation of the active load.

3.8 FPGA Functionality and Layout

The design uses analogue, software and hardware features of the SmartFusion FPGA. Table 3.10 provides a more detailed description of all the features to be utilised in the design of the EPS sub-system.

Table 3.10: Utilisation of SmartFusion features

<u>SmartFusion FPGA</u>	<u>Features Utilised</u>
Cortex-M3	Management of all components and functions Processing and simple calculation Software execution of less critical functions
UART,I ² C	Communication protocols with external device/host/peer
Flash	Code and parameter storage
SRAM	Temporary code storage or boot
ADC and ACE	Converts current into digital (used in Clark Transform) Converts voltage into digital (used in Back-EMF) Comparators used to catch faults
Analogue I/Os	Analogue input of motor current and voltage
FPGA	Hardware implementation of system critical tasks Customised protocols and communication (CAN) Customised algorithm (PID, SVPWM, etc.)
FPGA I/Os	PWM outputs, encoder feedback, Hall sensor feedback

It can be noted that a large amount of hardware that would be required to perform specific functions in non-FPGA-based systems are omitted as this is included within the SmartFusion FPGA. Features such as the ADC and ACE, which include a Sample Sequencing Engine (SSE), Post Processing Engine (PPE) and comparators, decrease the number of components used in the design, in turn simplifying the design and reducing the cost of implementation. These features also have a positive effect on the prototyping time. To further decrease the time needed for prototyping, the SmartFusion A2F200 Evaluation Kit (from here on referred as SmartFusion Eval-Kit) (see Figure 3.16 together with the mixed signal daughter card (see Figure 3.17), will be implemented in the design to serve as proof of concept. The SmartFusion Eval-Kit provides users with the necessary hardware and firmware to explore the features of the SmartFusion FPGA, while the mixed signal daughter card provides easy to access test points, as it has a 100mil connector that connects directly to the mixed signal header of the SmartFusion FPGA.

The mixed signal daughter card 50-100-CONV-SA pin-outs are illustrated in Figure 3.18. The pins that are of greatest concern are the pins of the pad inputs to the voltage sensors, currents sensors and GPIO, pins 61 - 66, pins 49 - 54 and pins 29 - 38.

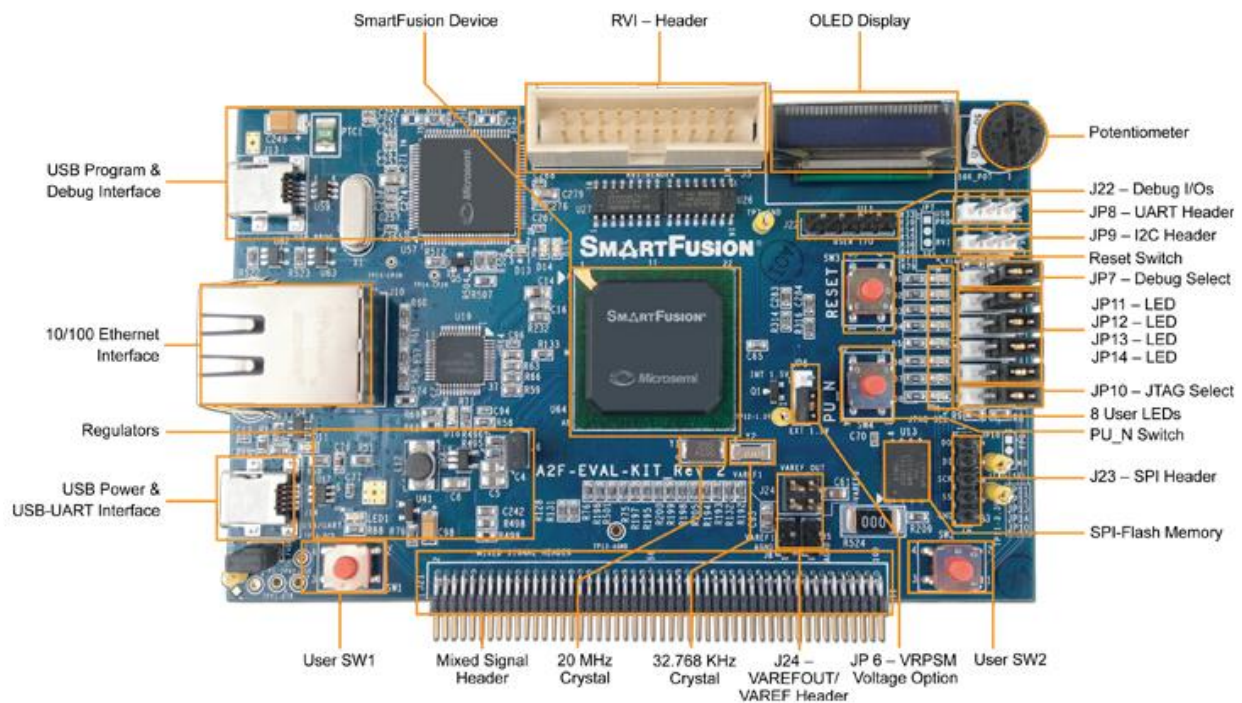


Figure 3.16: SmartFusion Eval-Kit

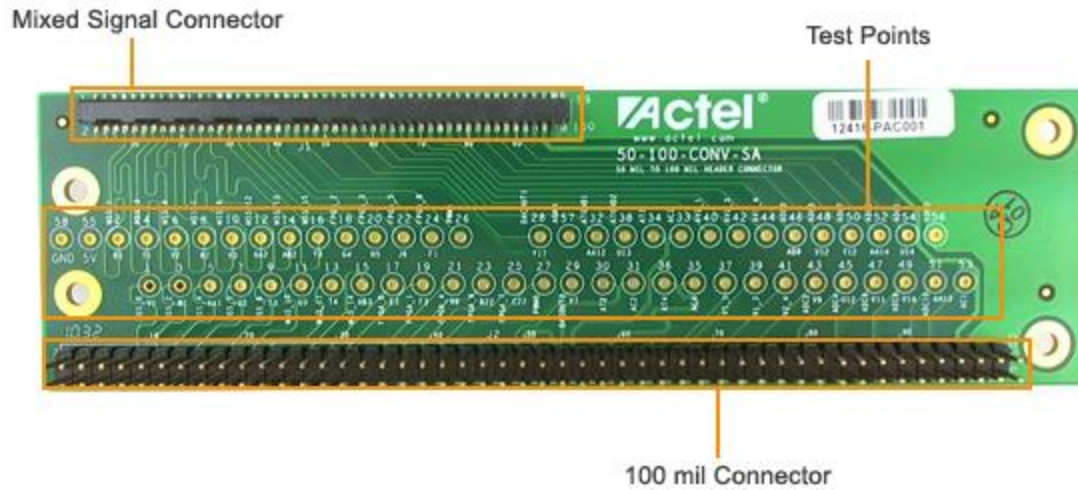


Figure 3.17: Mixed signal daughter board

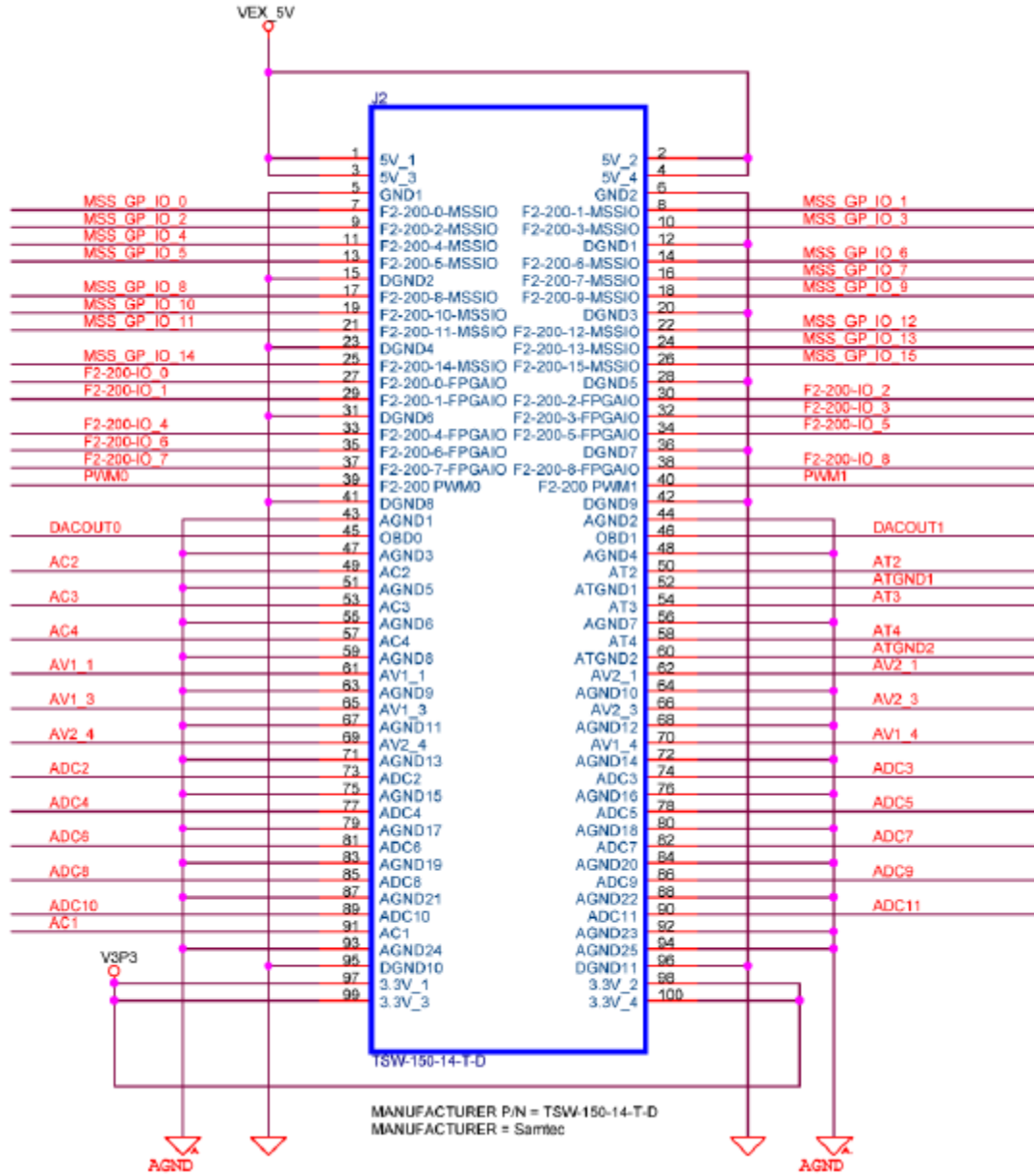


Figure 3.18: Mixed signal connector

3.9 Matlab® Simulations

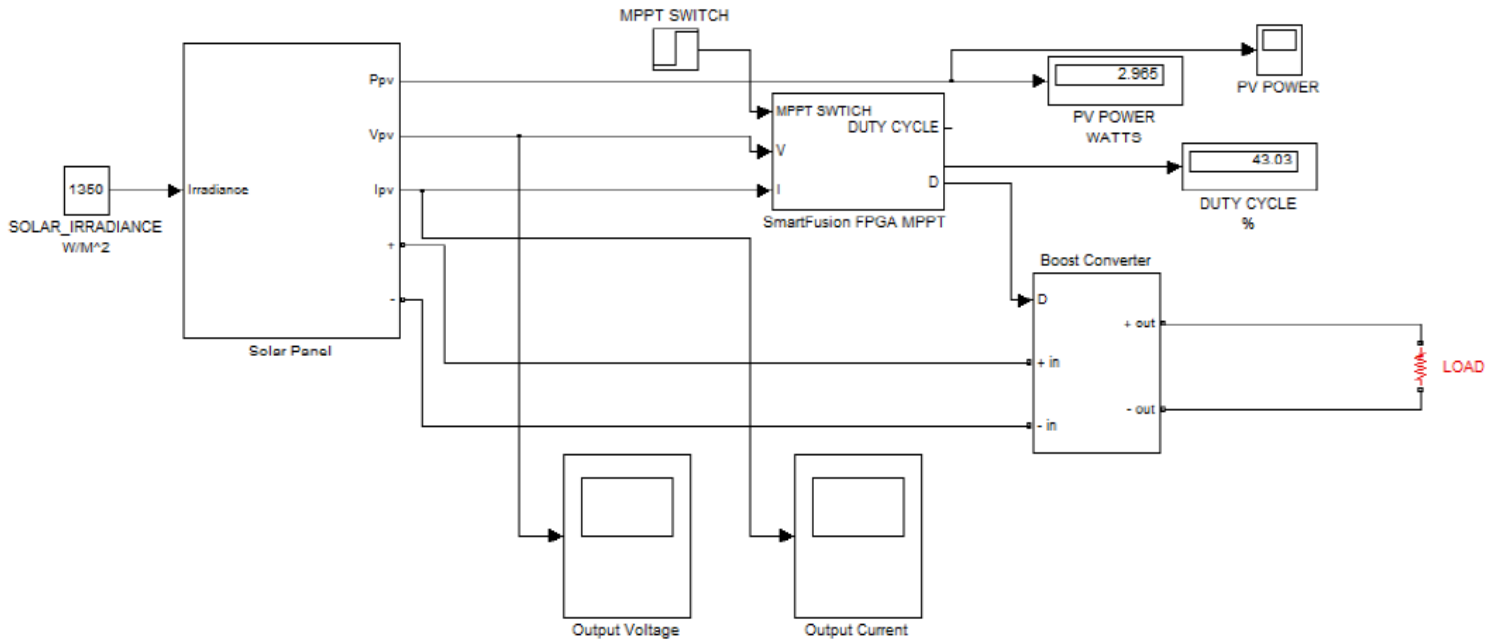


Figure 3.19: Matlab Simulation of MPPT implementation

The Simulink™ model from Neeraj *et al.*, illustrated in Figure 3.19, was modified with the solar and MPPT characteristics used in this design. The model was modified to allow changes in the solar irradiance that the CubeSat will experience in its operational environment. Figure 3.20 shows the series connection of six solar cells. The solar cell parameters are entered into the block model, indicated in Figure 3.21. The block models the solar cell according to Equation 3.14, indicating the solar cell as a parallel combination of a current source, two exponential diodes and a parallel resistor R_p , which is connected in series with R_s .

$$I_{pv} = I_{ph} - I_{sat} \left(\exp \frac{q(V_o + IR_s)}{N_s * V_t} - 1 \right) - I_{s2} \left(\exp \frac{q(V_o + IR_s)}{N2 * V_t} - 1 \right) - \frac{V + IR_s}{R_p} \quad (3.14)$$

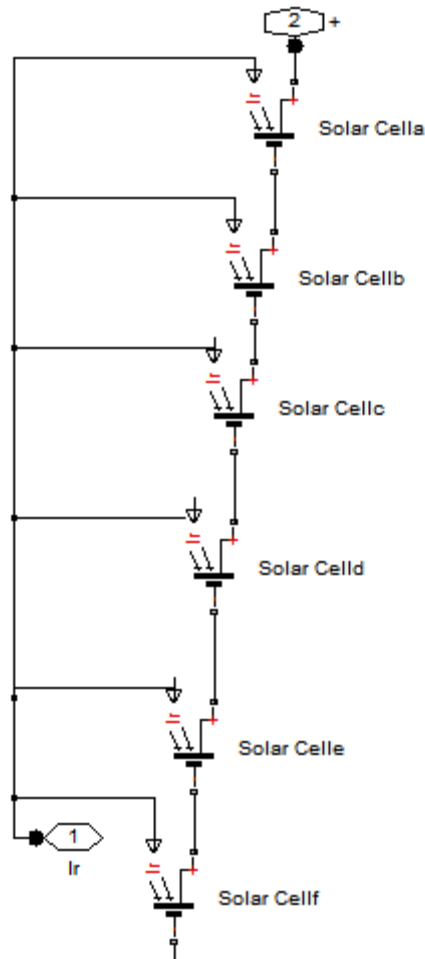


Figure 3.20: Solar cell model

Main	Temperature
Parameterize by:	By s/c current and o/c voltage, 5 parameter
Short-circuit current, I_{sc} :	242 mA
Open-circuit voltage, V_{oc} :	0.5388 V
Irradiance used for measurements, I_{r0} :	1000 W/m ²
Quality factor, N:	1.2
Series resistance, R_s :	5.1e-3 Ohm

Figure 3.21: Solar cell characteristics

The six solar cells indicated in Figure 3.20 are connected in parallel with three more of these models, equalling a total of 24 solar cells. The solar cell connections used closely resemble the characteristics of the solar cells to be used in the design. The solar cells used in prototyping are further tested in Chapter 5. These solar cells have a typical open-circuit voltage of 0.538V, short circuit current of 242mA and an assumed ideality factor (emission coefficient) of 1.2.

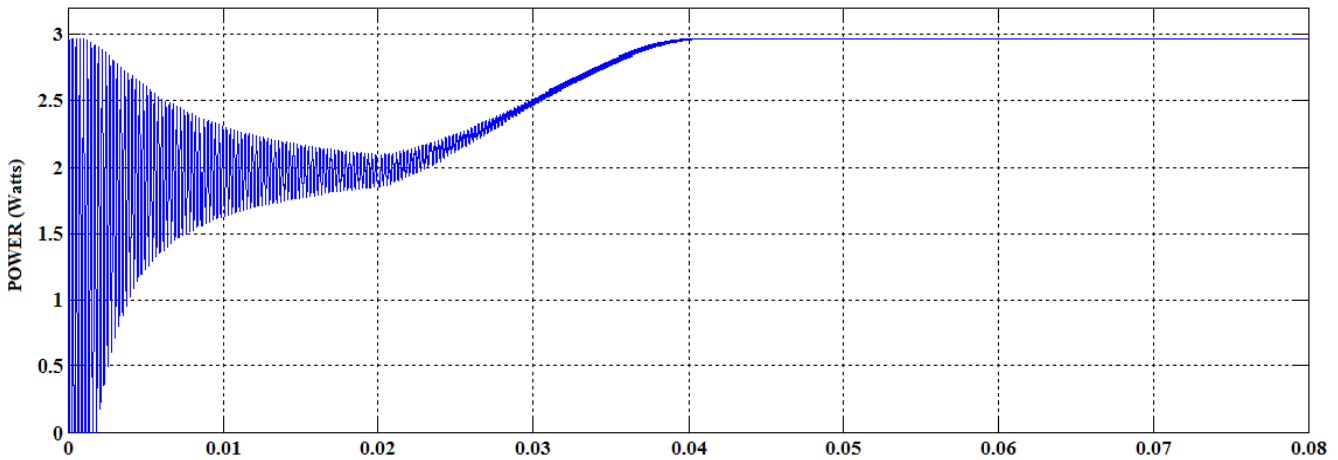


Figure 3.22: MPPT output waveform

The P&O algorithm was implemented in the FPGA MPPT controller using a Matlab script file attached in Appendix D. The output power, after the MPPT switch is enabled, was found to be approximately 2.9W, illustrated in Figure 3.22. The maximum power point was found after approximately 0.04 seconds, 0.02 seconds after MPPT activation (a detailed flowchart of the algorithm implemented is presented in Section 4.6). By varying the irradiation level, the duty cycle of the boost converter changes in order to keep the solar array operating at maximum power.

Chapter 4

Prototype Construction

4.1 Circuit Level Design Overview

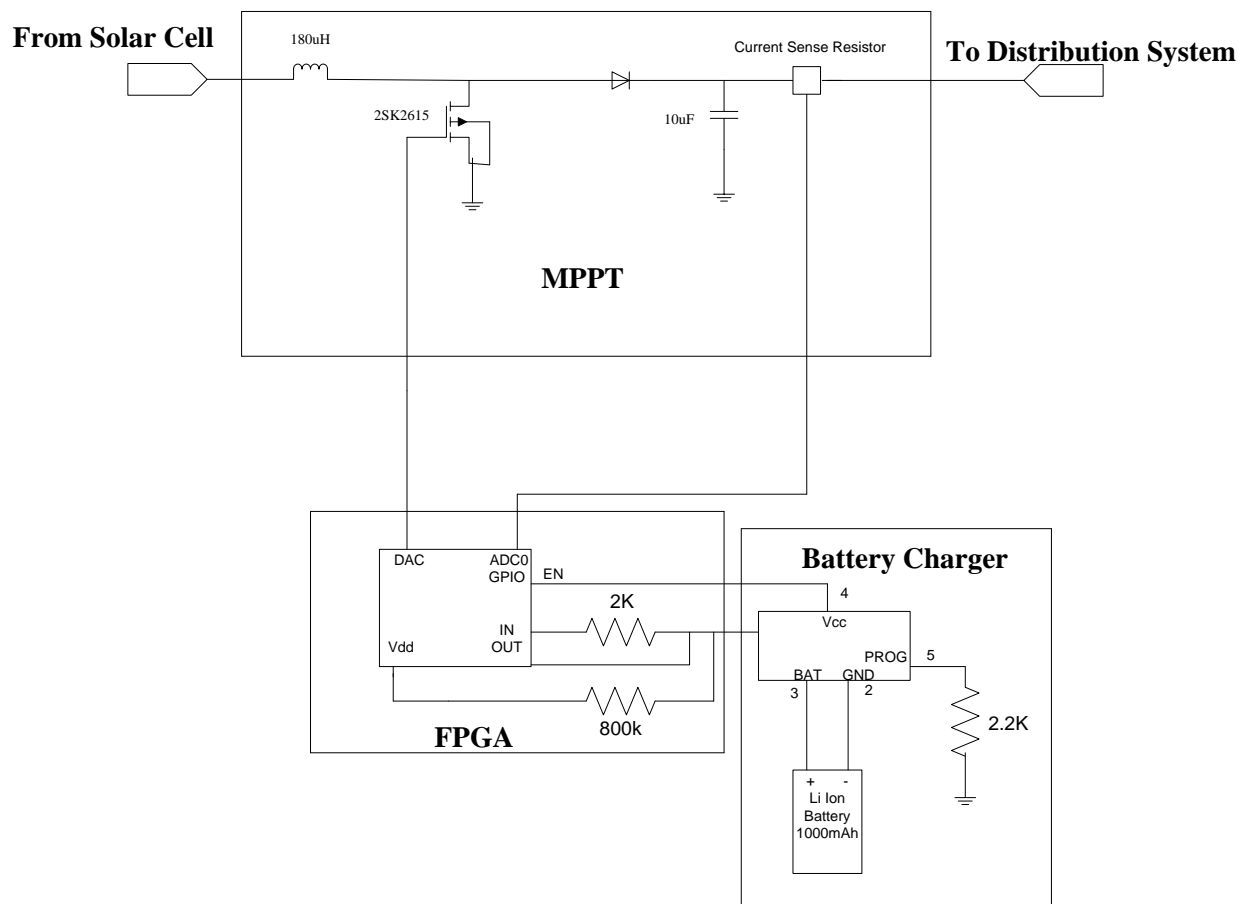


Figure 4.1: Basic circuit level design overview

The circuit shown in Figure 4.1 is a summarised version of the electronic power supply system. A modular approach was taken in the circuit design to allow interconnection between various circuit boards. This approach will allow the testing of different sub-circuits of the EPS individually to determine each one's functionality and operation, and then an orbital simulation test in which the various systems are connected to each other will allow the testing of the full functionality of

the EPS prototype. The various sections of the design will be discussed in this chapter and illustrate the prototypes constructed from the various designs.

4.2 Solar Cell

The solar cells (see Figure 4.2) obtained are from Futurlec.com. Ideally, solar cells from Spectrolab (NeXt Triple Junction Solar Cells) can be used to increase the power produced; however, due to both cost and availability, these solar cells were used in the test setup. Three of these panels were obtained in order to provide the simulated environment to test to EPS sub-system. The electrical properties are tabulated in Table 4.1.



Figure 4.2: Solar cell used in simulated environment

The 968mW solar cells have a high output current of approximately 242mA at maximum power while producing a voltage of 3.88V. Various configurations were tested in order to provide the power that closely resembles the conditions under which the EPS system is required to operate.

Table 4.1: Futurlec solar cell parameters

<u>Parameter description</u>	<u>Parameter value</u>
Solar Cell Composition	Polycrystalline
Peak Voltage (V_{mp})	3.88V
Open-Circuit Voltage (V_{oc})	4.0V - 4.5V
Peak Current (I_{mp})	242mA
Short Circuit Current (I_{sc})	242mA – 261mA
Maximum Power (P_{max})	968mW
Dimensions (L x W x D)	120mm x 90mm x 2.8mm

4.3 Battery Charge/Discharge Circuit

The battery charge/discharge circuit forms a critical part of the EPS system. By using the information from the power budget, a single lithium-ion battery was selected as the secondary source of power of the nano-satellite. This is due to the sub-system requirements as stated in Section 3.4. The battery characteristics state that a maximum charge current of 500mA is required in order to charge the battery at C/2 while the solar cells are able to produce 726mA at maximum power. The power budget indicates that a total of 275.362mA is required to power the sub-system on both the 3.3V and 5V bus during period of sun exposure, leaving 450mA available for charging.

There are a large range of commercially available lithium-ion battery charger integrated circuits. The LTC4054 is a single cell lithium-ion battery charger using a constant-current/constant-voltage algorithm, able to deliver up to 800mA of charge current. This charger would be ideal for the system as it only requires 5V DC for operation, as indicated in Figure 4.3.

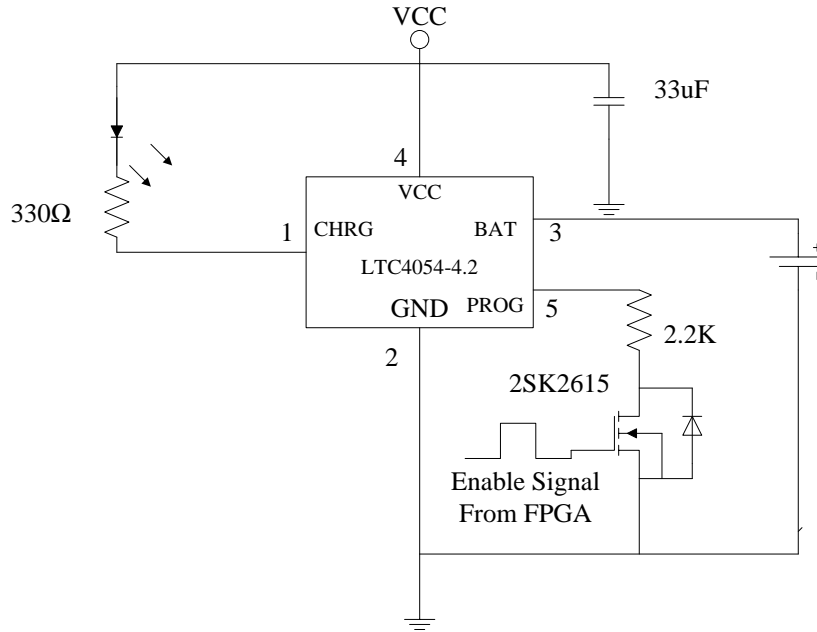


Figure 4.3: LTC4054-4.2 Lithium-ion battery charger

The charge current is programmed using Equation 4.1, where R_{PROG} is a single resistor from the PROG pin to ground:

$$I_{chg} = \frac{1000V}{R_{PROG}} \quad (4.1)$$

Thus, in order to obtain a charge current of 450mA, a PROG resistor of 2.2kΩ is required. However, in order to accommodate excess energy that may be generated during periods of low power, a 1.2kΩ resistor may be utilised to dissipate excess energy and transfer this energy into the secondary source of power. The battery charger will be used to maintain the charge of the battery. This can be monitored using the FPGA by configuring the LTC4054-4.2 with two different pull-up resistors, as indicated in Figure 4.4.

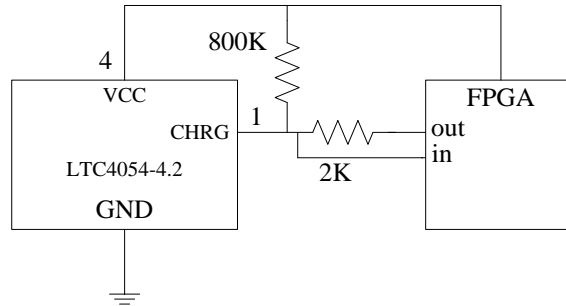


Figure 4.4: State of charge detection

Detecting the state of charge of the LTC4054 is accomplished by forcing the digital output high and then measuring the voltage at the CHRG pin. Table 4.2 shows the parameters as well as the test conditions used to control the operation of the battery charging circuit.

Table 4.2: Battery charge control logic

<u>Parameter</u>	<u>Condition</u>
Solar cell current	>0A
Battery voltage	<4.05V
Charge	1

The control logic ensures that charging starts when the solar cell current is greater than zero, indicating exposure to the sun and a battery voltage below 4.05V - a discharged battery. At this stage, the control variable “Charge” will change state from its initialised zero state to become a 1, ensuring that the charge cycle is only stopped once a battery voltage of 4.2V is reached. Figure 4.5 shows a flow chart of the control logic.

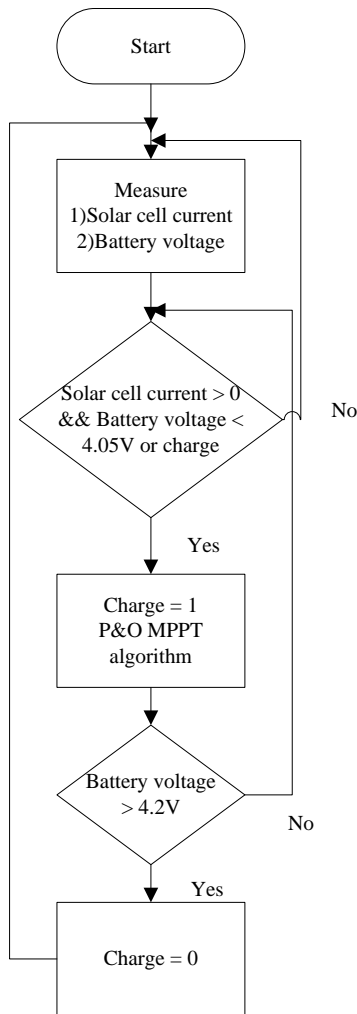


Figure 4.5: Battery charge algorithm

The LTC4054 continuously monitors the voltage at the BAT pin by using a comparator. The BAT pin, pin 3 on the LTC4054-4.2, is connected to the lithium-ion battery providing the charge current and regulating the voltage at 4.2V. The charge cycle automatically restarts when the voltage falls below 4.05V which corresponds to approximately 10% depth-of discharge ensuring the that secondary source of power is kept at or near its fully charged state, reducing the need for longer charge cycles. The picture in Figure 4.6 shows the MPPT prototype.

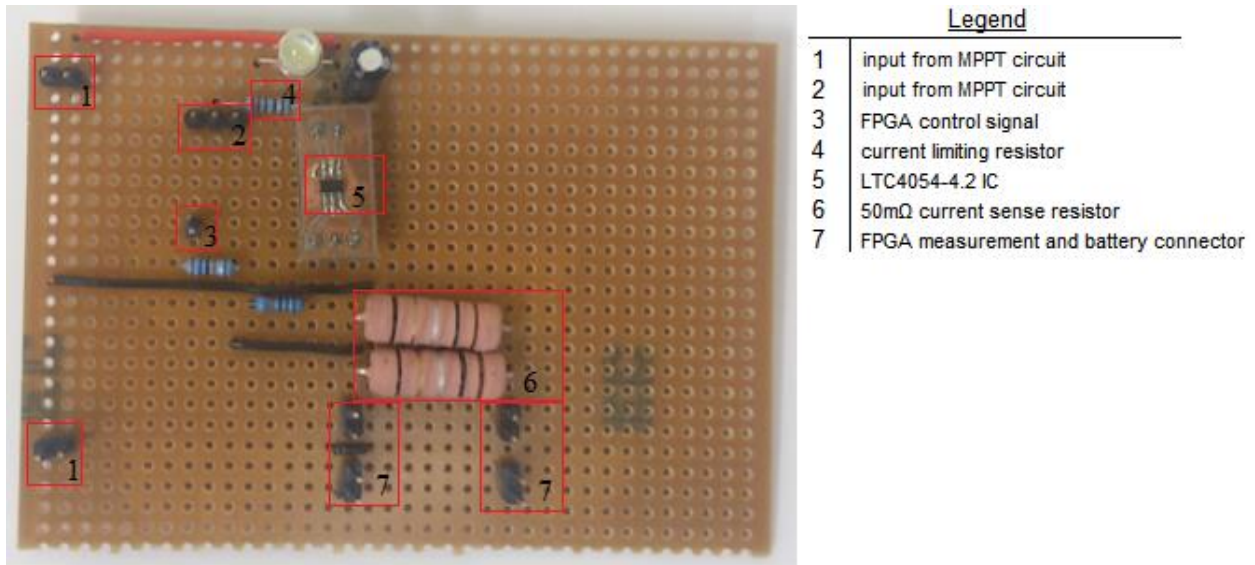


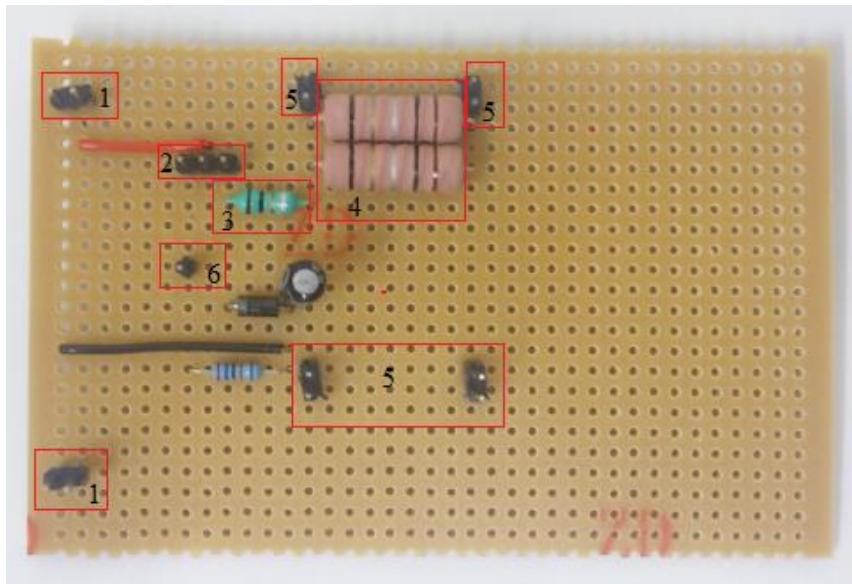
Figure 4.6: Battery charge/discharge circuit

The battery charger circuit shows the current sense resistors placed in parallel to produce an effective resistance of 50mΩ. Connector pin 2 is used to connect the high frequency MOSFET while connector pin 3 provides the enable signal from the SmartFusion FPGA, and connector pin 7 connects the secondary power source to the charging circuit. Various connector pins are placed throughout the board serving as test points as well as interconnection between the other sub-circuits of the EPS prototype.

The functionality and performance of the battery charge/discharge circuit were tested and are documented in the following chapter.

4.4 Distribution System

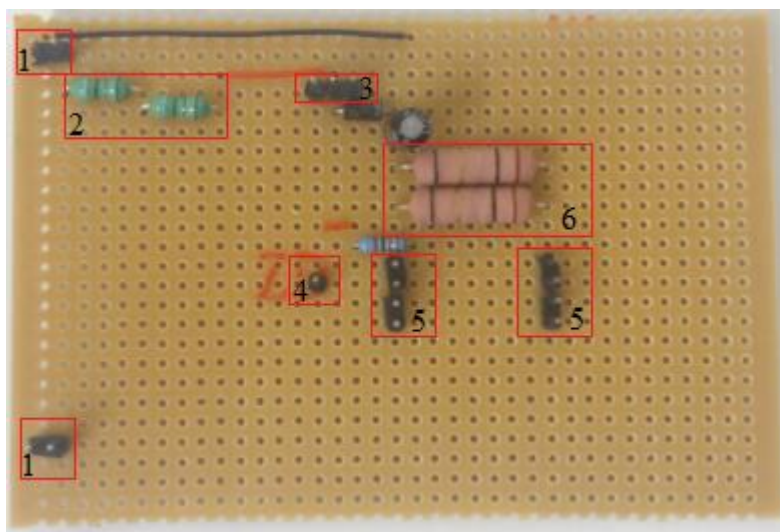
The distribution system was designed in order to simulate various load conditions. The design of the distribution system can be found in Appendix J. The layout of the board follows that of the MPPT circuit board with the various connectors allowing connection between the high frequency MOSFET, input power, output signal and various test points. The functionality and performance of the dc-dc converters was tested and is documented in the following chapter.



Legend	
1	input from MPPT circuit
2	MOSFET Input
3	10 μ H inductor
4	50m Ω current sense resistor
5	FPGA measurement and output points
6	FPGA gating signal input

Figure 4.7: 3.3V Buck converter prototype

Figure 4.7 shows the veroboard layout of the 3.3V buck converter prototype. Pins 1 and 2 are the same as for the previous illustration. Current is measured through the 50m Ω current sense resistor at pin 5, while the closed loop control signal provided by the FPGA is provided by pin 6. The veroboard layout of the 5V boost converter is shown in Figure 4.8 where pin 1 is the input from the MPPT circuit, the MOSFET is connected to pin 3, while the control signal from the SmartFusion FPGA is provided by pin 4. Pin 5 provides the measurement and output points of the circuit.



Legend	
1	input from MPPT circuit
2	2 μ H inductor
3	MOSFET input
4	FPGA gating signal input
5	FPGA measurement and output points
6	50m Ω current sense resistor

Figure 4.8: 5V Boost converter prototype

4.5 Active Load

The active load, designed using the TIP122 Darlington pair power transistor, uses variable resistors as indicated in Figure 4.9 to increase or decrease the current and thus cause a change in power dissipation. Two of these active load circuits were designed and connected to the 3.3V and 5V distribution busses. The active loads were tuned according Figure 3.13 and Figure 3.15 which illustrate the various resistance levels in order to dissipate 467.5mW and 472.5mW on the 3.3V bus and 5V bus respectively. Figure 4.10 shows the final prototype of the active load.

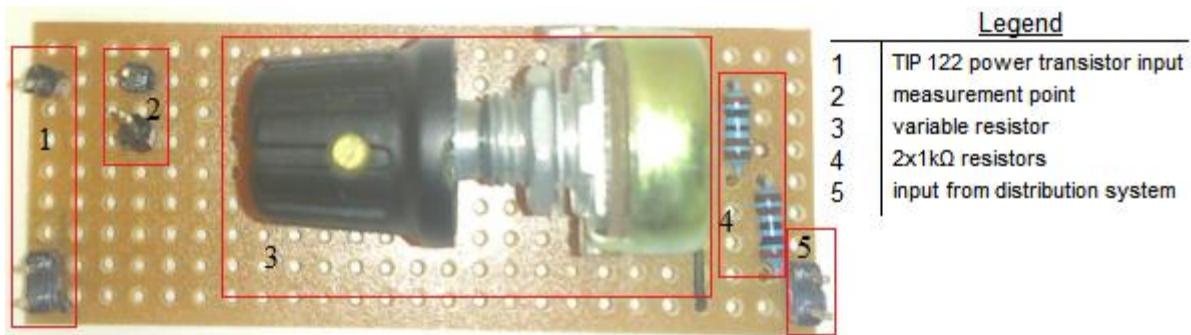


Figure 4.9: Active load circuit

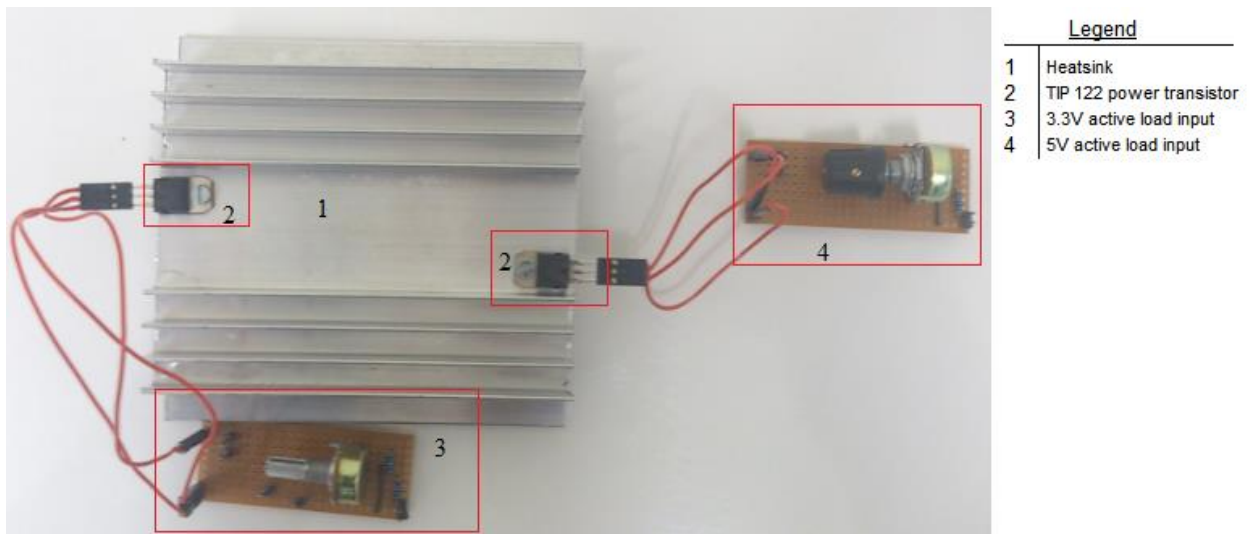


Figure 4.10: Active load setup

4.6 FPGA

The SmartFusion FPGA is programmed using Libero[®]. The following major steps are executed in order to programme the SmartFusion FPGA:

- create the design;
- implement the design;
- programme the device; and
- develop the firmware.

The bulk of the design layout is made during the 'create design phase' while the 'implement design phase' is used to verify the design and undergo various design rule checks. Synthesis of the design, test bench simulations and placing the various I/Os are also completed during this phase. Programming the SmartFusion device is done using FlashPro where an .fdb file is generated containing the hardware configuration of the FPGA. The firmware development phase is used to write the application code which controls and directs the MSS, written in C or C++. The following section addresses FPGA design implementation in more detail.

4.6.1 Creating Design

The smart design MSS is a graphical user interface (GUI) that contains a number of representative peripheral images that are actually configurable software interfaces to determine the functionality of the SmartFusion design. The MSS design canvas has different coloured blocks: the blue blocks are for hardware configuration and the green blocks are not configurable; and the grey blocks are disabled. Blocks that have a small check box can be disabled to conserve FPGA resources and power. For this particular design application only the UART_0 and ACE blocks are checked while all other check boxes are unchecked. If I²C interfaces are required, these can be included in this step as they fall beyond the scope of this document. Figure 4.11 shows the design canvas with the UART_0 and ACE block checked.

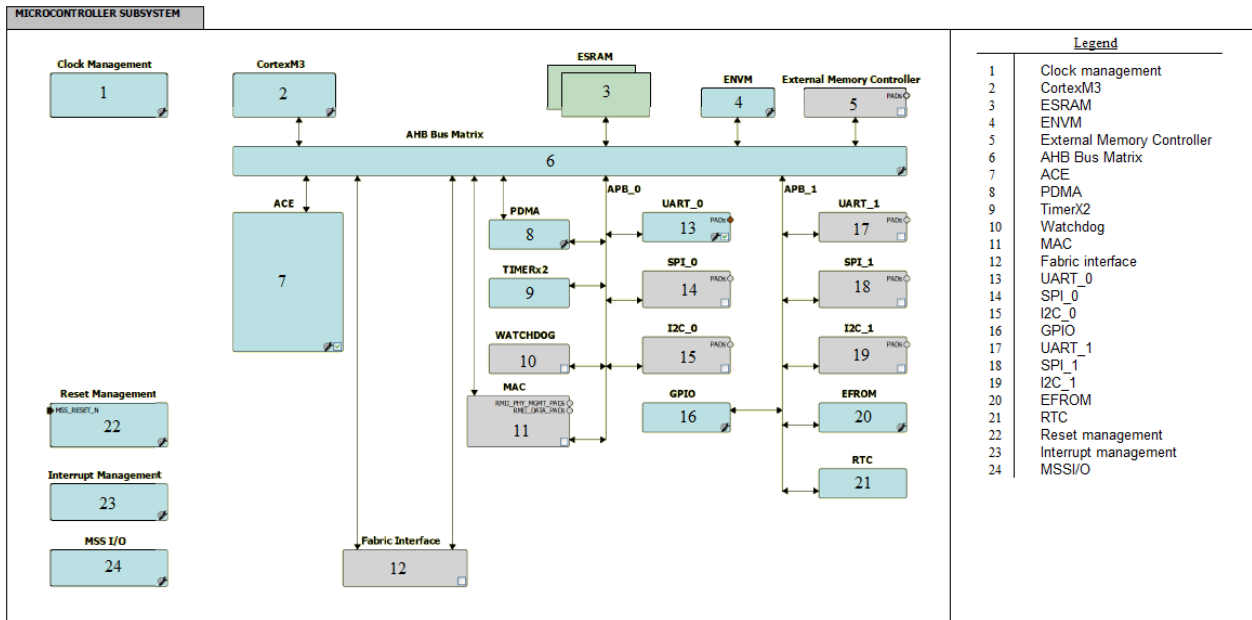


Figure 4.11: Smart design canvas

4.6.1.1 Clock Management

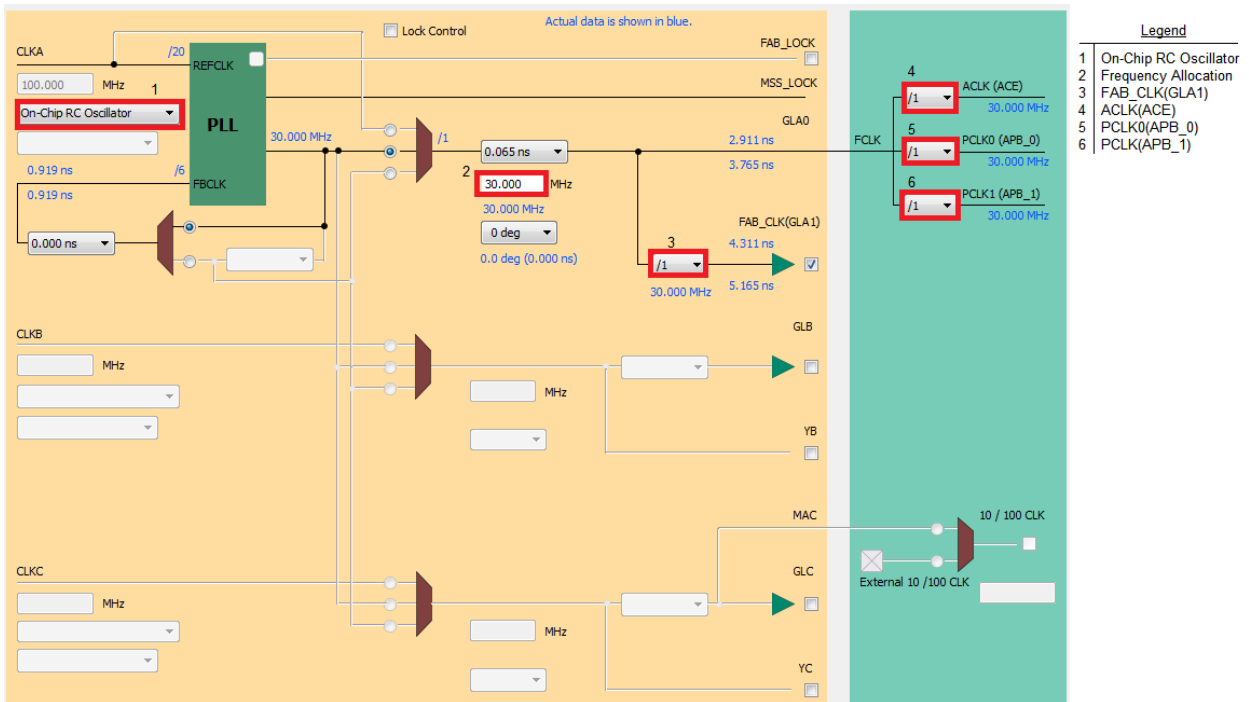


Figure 4.12: Clock configuration

Figure 4.12 shows the clock management configuration used in the design which can be found in the top left corner of the MSS design canvas. The On-Chip RC oscillator was selected as the

clock input and the Phase Lock Loop (PLL) output of 30Mhz was selected. The ACLK, PCLK0, PCLK1 and the FAB_CLK are divided by 1 to maintain the 30Mhz output frequency. FAB_CLK is used as the input clock to the PWM module described later in this chapter. Once the system clock is verified, the analogue compute engine (ACE) can be configured.

4.6.1.2 Analogue Compute Engine (ACE)

The ACE is configured by clicking the wrench icon illustrated in the smart design canvas as shown in Figure 4.11. This user interface allows for the configuration of various analogue inputs. This design requires the configuration of four Active Bipolar PreScalers (ABPS) and two current monitors with a 12-bit resolution for increased accuracy. The ABPS senses the voltage on an input pad and scales it to fit the range of the ADC which is between 0 - 2.56V. The design is shown in Figure 4.13. An operational amplifier arranged in an inverted configuration with a configurable feedback resistor and current source are able to provide four nominal gains and offset ranges, of which the full range of +/- 15V was chosen for this design so as to allow measurement over a large input range.

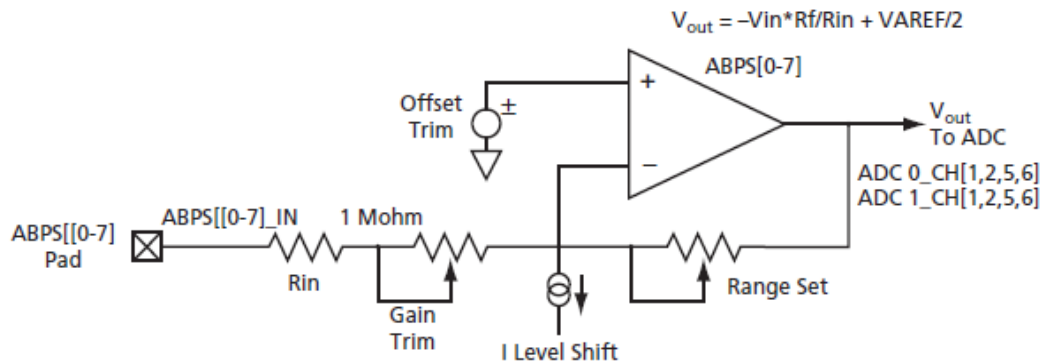


Figure 4.13: ABPS internal configuration

The voltages to be measured are the solar cell voltage, battery voltage, and the 3.3V and 5V bus voltages. These voltages are applied as a negative feedback loop to provide closed loop control in the converter design. Figure 4.14 shows the four ABPS used as well as their pin assignments. These pin assignments were confirmed using the mixed signal daughter card user guide.

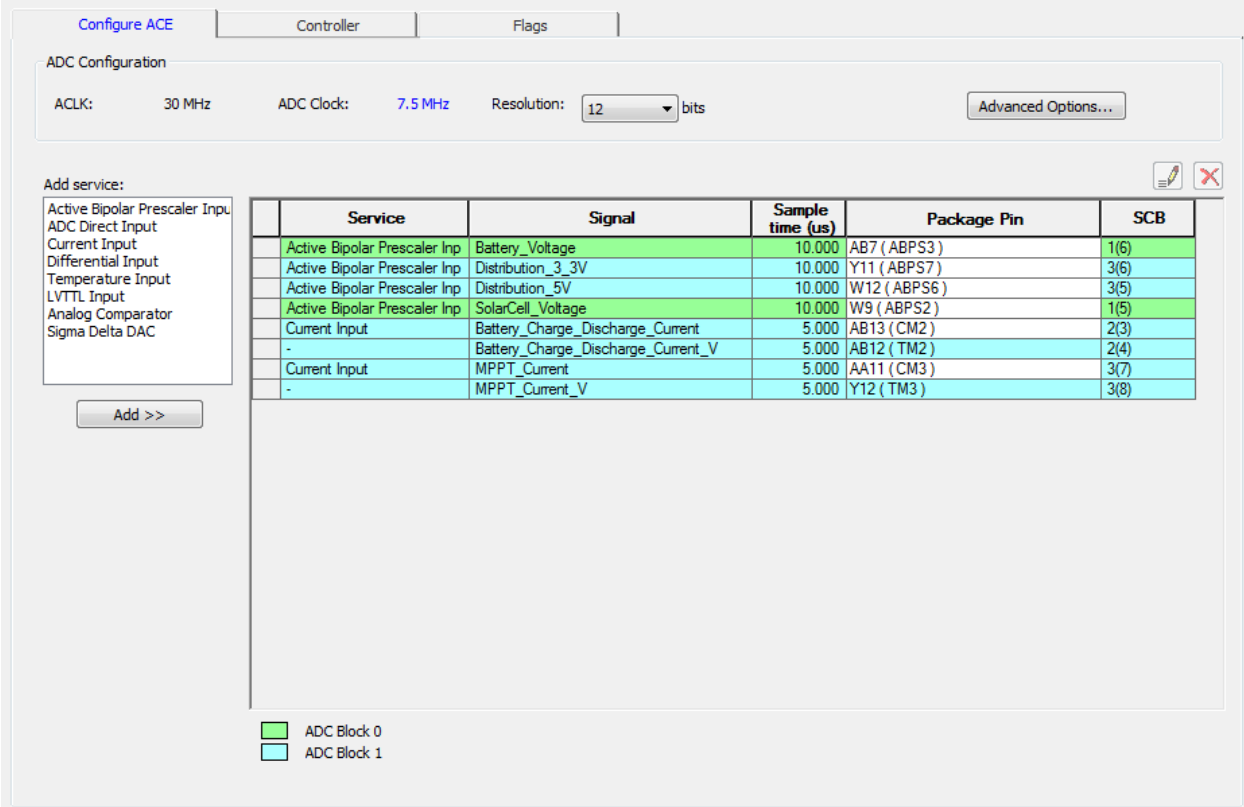


Figure 4.14: ACE configuration

Monitoring the output current of the dc-dc converter used in the MPPT circuit is one of the current monitors which can also be configured using the ACE. The second current monitor is used to monitor the battery charge and discharge currents. The current monitors are constructed from switched-capacitor circuits. This allows the current monitors to have a high common mode input voltage range, a large common mode voltage rejection ratio, as well as relatively high input impedance (Actel Corporation, 2010). The internal design (Figure 4.15) shows that the high input signal (CM[n]_H) is attached to the CM[n] pad, low input signal (CM[n]_L) is attached to the TM[n] pad. This is important as the current monitors are only able to measure positive differential voltages indicating that CM[n]_H must be greater than CM[n]_L. The current sensor uses an external current sense resistor of 0.05Ω, allowing current measurements between 250uA and 1.02375A as suitable for the design application. Figure 4.14 shows that CM2 and TM2 are used to measure the battery charge and discharge voltage while CM3 and TM3 are used to measure the output current of the MPPT circuit.

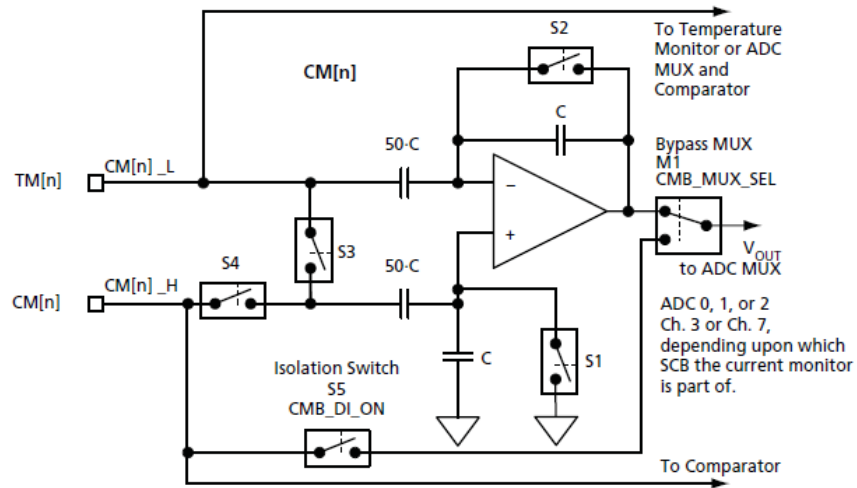


Figure 4.15: Current monitor

Following the selection of the different inputs required in the design, the sampling sequence engine (SSE) is configured in the controller tab (see Figure 4.14) in order to continuously sample the different input signals. Figure 4.16 shows the sample sequence of ADC1_Main as well as the time it takes to complete each sample. ADC0_Main can be viewed as well.

Configure ACE Controller Flags

Procedures

Name
ADC0_MAIN
ADC1_MAIN

Operating sequence entry: Auto Manual

Details of procedure: **ADC1_MAIN**

Available signals: [] Sampling rate:

Signal	Actual Rate (ksps)
Battery_Charge_Discharge_Current	21.100
MPPT_Current	21.100
Distribution_3_3V	21.100
Distribution_5V	21.100

Calculate Sequence and Actual Rate Total sampling rate: **84.400** kbps

Operating sequence

Instruction	SSE Execution Time (us)
Sample Battery_Charge_Discharge_Current	10.667
Sample MPPT_Current	10.667
Sample Distribution_3_3V	12.733
Sample Distribution_5V	12.733
Restarts the execution sequence for this timeslot	0.267

Figure 4.16: Sample Sequence Engine (SSE) configuration

4.6.1.3 GPIO Configuration

The GPIOs are configured in a similar manner as the previously mentioned clock management and analogue compute engine. GPIOs 0 - 7 are selected as outputs and are connected to the FPGA fabric in order to promote these pins to top level pins to be able to assign package pins to these user I/Os. GPIOs 0 - 6 are used as a 7-bit input to the VHDL PWM module, while GPIO 7 is used as an interrupt enabling the MPPT algorithm.

GPIO	Use as MSS I/O Pad	or connect to Fabric
GPIO_15	Not Used	Not Used
GPIO_14	Not Used	Not Used
GPIO_13	Not Used	Not Used
GPIO_12	Not Used	Not Used
GPIO_11	Not Used	Not Used
GPIO_10	Not Used	Not Used
GPIO_9	Not Used	Not Used
GPIO_8	Not Used	Not Used
GPIO_7	Not Used	Input
GPIO_6	Not Used	Output
GPIO_5	Not Used	Output
GPIO_4	Not Used	Output
GPIO_3	Not Used	Output
GPIO_2	Not Used	Output
GPIO_1	Not Used	Output
GPIO_0	Not Used	Output

Figure 4.17: GPIO configuration

This completes the MSS configuration; however, to complete the design, a VHDL PWM module needs to be created which is described in the following section.

4.6.1.4 VHDL PWM

The VHDL PWM is written using very-high-speed-integrated-circuit-hardware-description-language (VHDL) which can be found in Appendix G. The VHDL component is generated under the 'create design' tab in the design flow window and by selecting 'create new HDL file' option. In the design hierarchy window, the HDL file is listed allowing for an HDL syntax check. Once the syntax check has finished, the VHDL module can be instantiated into the MSS design allowing the connection between the MSS and VHDL PWM module, as shown in Figure 4.18.

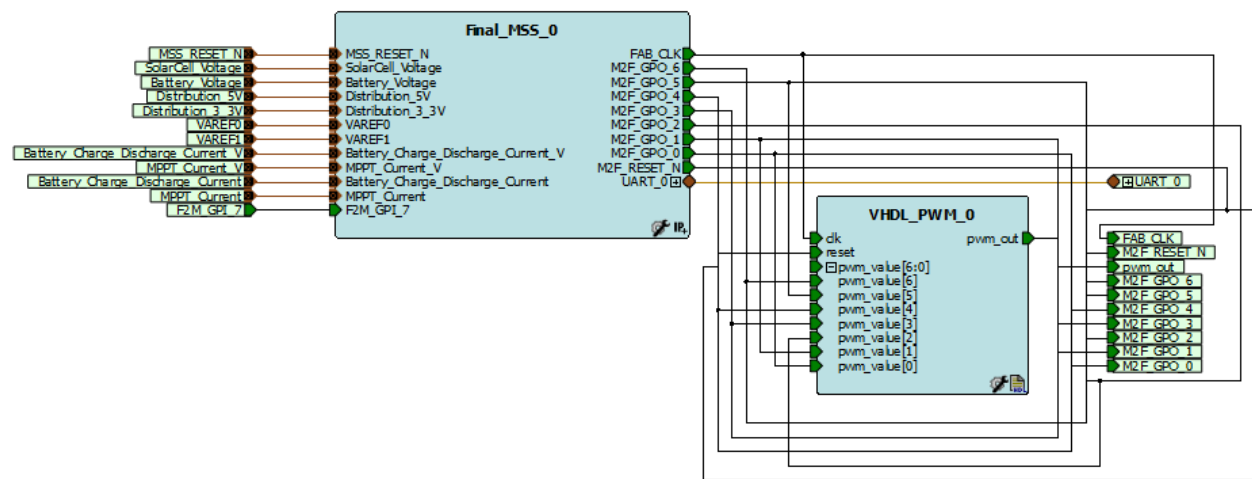


Figure 4.18: MSS and VHDL PWM

The VHDL PWM module is a 7-bit counter that counts to a value of 2^7-1 (127) and subsequently restarts. The GPIOs 0 - 6 from the MSS outputs binary a value between 0 -127. The pwm_out signal remains at a logic high for all values of the 7-bit pwm_value which are greater than the counter value and switches to a logic low as soon as the pwm_value is less than the counter value. This logic is confirmed through the implementation of a user test bench explained in the following section.

4.6.1.5 VHDL Test Bench

The user test bench is written using VHDL and can be found in Appendix H. The test bench is written in order to confirm the operation of the VHDL module. The test bench produces simulated results by testing the operation of the module under various input conditions, as illustrated in Figure 4.19. The conditions used to test this module involved the setting of the `pwm_value` signal to represent different input signals from the MSS GPIOs in order to induce changes in the `pwm_out` signal. The number of clock periods before a change in the state of the `pwm_value` signal and the reset conditions were also set. The simulation runtime was set to 60 μ s. The test bench allowed the value from the MSS GPIOs to change from 0, 32, 64, 95 and 127, representing 0%, 25%, 50%, 75% and 100% duty cycles respectively.

4.6.2 Implement Design

The design implementation involves synthesis, place and route and also generating the programming data. Synthesis performs a design rule check on the MSS design and allows the process to continue if the VHDL components are successfully generated. Choosing to interactively place and route the MSS design opens the Designer window which provides an option for I/O attributor. This action should be performed before continuing with the FPGA layout generation and the Flash Pro data generation.

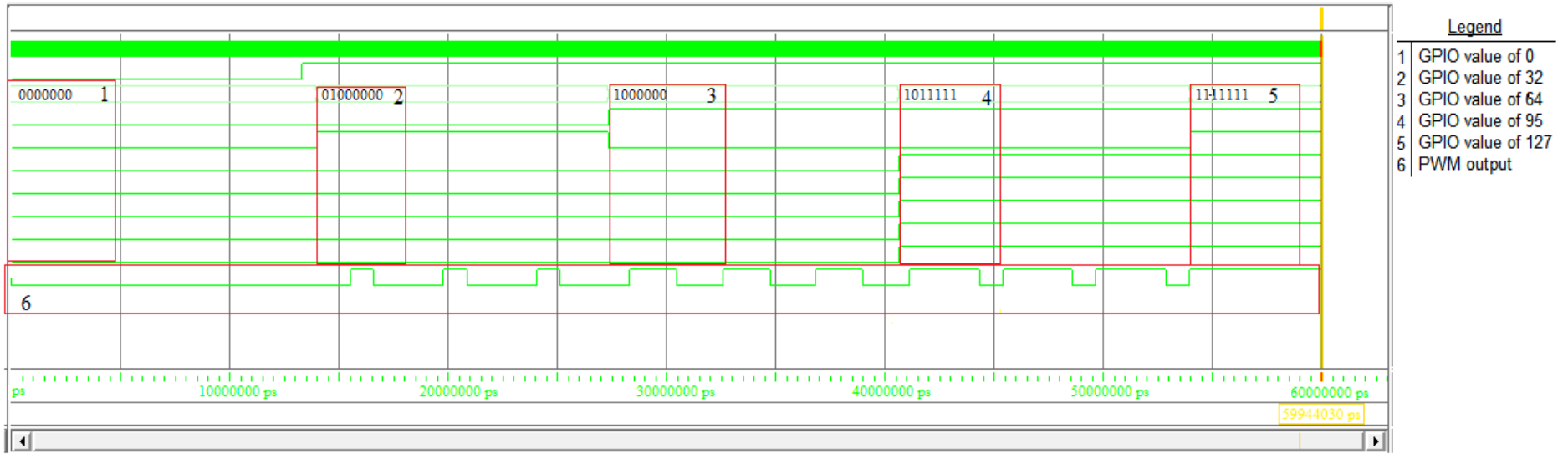


Figure 4.19: Test bench output

Table below indicates the pin assignment used in the break out board:

Table 4.3: MSS signal and pin assignments

<u>Port Name</u>	<u>Pin Number</u>
Distribution_3_3V	Y11
Distribution_5V	W12
F2M_GPI_7	G19
FAB_CLK	H6
M2F_GPO_0	B19
M2F_GPO_1	B20
M2F_GPO_2	C19
M2F_GPO_3	H17
M2F_GPO_4	H20
M2F_GPO_5	C21
M2F_GPO_6	D21
M2F_RESET_N	G21
MPPT_Current	AA11
MPPT_Current_V	Y12
pwm_out	C22
pwm_5V_out	F1
pwm_3_3V_out	B22
SolarCell_Voltage	W9
Battery_Charge_Discharge_Current	AB13
Battery_Charge_Discharge_Current_V	AB12
Battery_Voltage	AB7
MSS_RESET_N	R1

The 'commit and check' option is used to confirm the pin and signal assignments, after which the FPGA design layout and programming data can be generated.

4.6.3 Programming Device

The data files generated during the place and route procedure required for programming can be accessed using FlashPro®. FlashPro® allows for the configuration of the device loading the .pdb file onto the FPGA flash memory. The SmartFusion FPGA Eval-kit jumpers should be placed in the correct positions to allow for FlashPro® programming.

4.6.4 Firmware Development

After the FPGA has been programmed, Softconsole® is used to write the application code used in the firmware development phase.

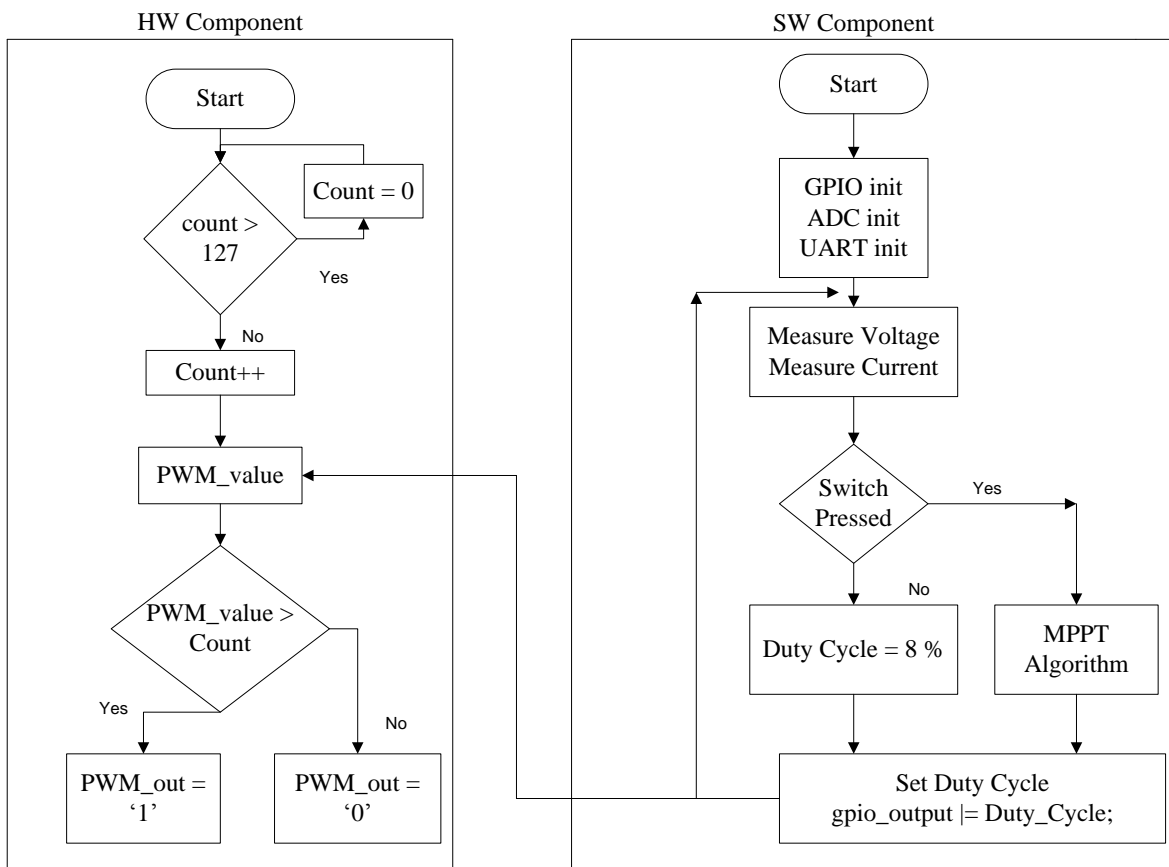


Figure 4.20: Application code flowchart

Figure 4.20 shows the application code flowchart for both the hardware and software components. The hardware component indicates the VHDL flow chart of the VHDL PWM where a counter was initialised whose value is compared to that of the 7-bit GPIO PWM_value signal. The software component shows the sequence in which the program is executed. A feature that was added is that of the switch, allowing the programme to enter MPPT mode or exit it. This feature may become important when the CubeSat is not required to operate in MPPT mode. A default duty cycle was chosen as this duty cycle was calculated in Chapter 3 as the duty cycle required by the MPPT to produce the 4.2V output.

4.7 MPPT Circuit

The MPPT circuit has three connector pins on the left of the layout, as shown in Figure 4.21. The connector pins are configured in a 1s3p configuration to which the solar panels are connected, increasing the current that the solar panels can produce from 242mA to 726mA. The MPPT circuit has the HF MOSFET to be connected to connector 1 and the MPPT PWM signal from the SmartFusion FPGA to be connected to connector 2. The 50mΩ current sense resistors allow for current measurements between 250µA and 1.23A. Connectors 3 and 4 connect to the SmartFusion FPGA current sensor while providing test points for data capturing. The functionality and performance of the MPPT prototype were tested and are documented in the following chapter.

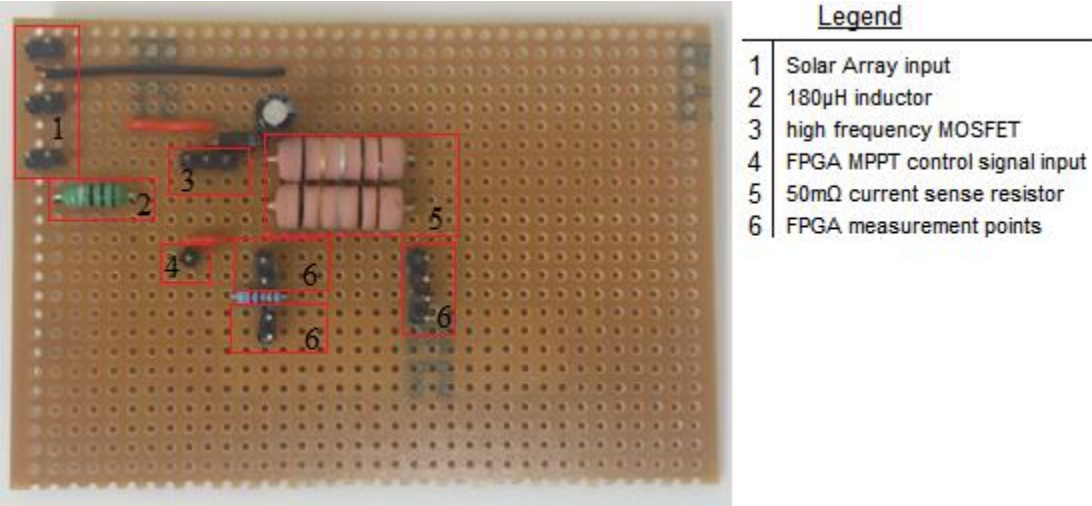


Figure 4.21: MPPT Prototype

Chapter 5

Prototype Evaluation and Tests Results

5.1 Prototype Overview

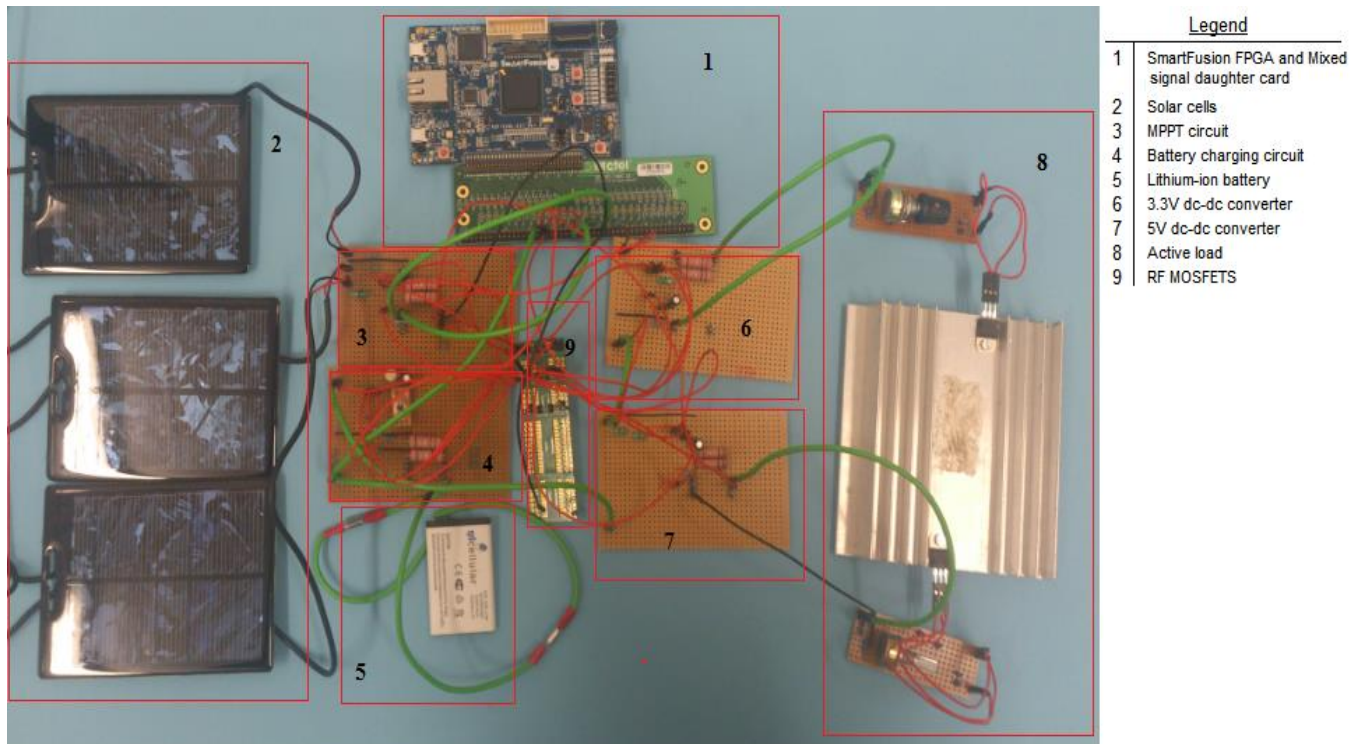


Figure 5.1: Electronic Power Supply (EPS) prototype

Various tests were conducted in order to verify the operation of the satellite power system using the SmartFusion FPGA as the main controller. Figure 5.1 shows the interconnection of the various EPS sub-circuit modules that were developed. Preliminary tests involved the verification of the PWM output frequency, duty cycle verification, maximum power point tracking verification, battery charging and discharging, as well as verification of operation of the distribution system.

Once these tests produced satisfactory results, a system integration test was conducted. Test equipment included a Digital Multi-meter (DMM), DSO 1002A Oscilloscope, two N2863B low-cost passive probes which provide 10:1 attenuation and have an impedance of 10MΩ, and connector leads from the mixed-signal daughter card to the circuit boards housing the different modules of the EPS. An important aspect of testing was the calibration of the test probes as the test probes have a certain reactance causing noise on the signal being measured. The probe was calibrated and is shown in Figure 5.2. Another concern was the use of test leads as this introduces noise within the system which can be viewed on the various output screens presented as figures throughout this chapter.

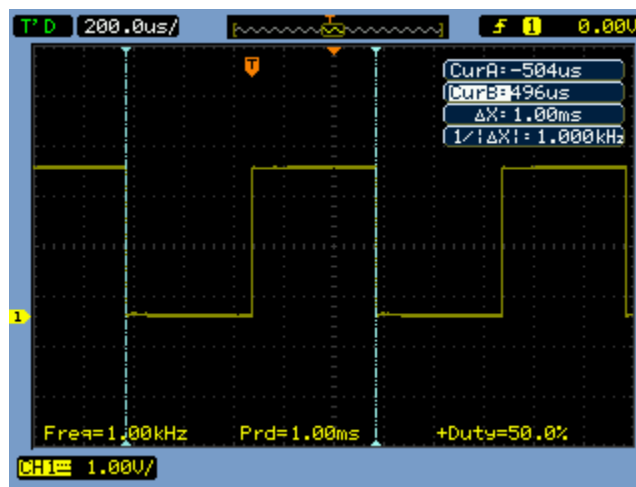


Figure 5.2: Probe calibration

The test data was captured using the USB to UART interface and displayed using HyperTerminal. The FPGA was programmed to communicate using the following settings tabulated below:

Table 5.1: HyperTerminal port settings

<u>Bits per seconds</u>	<u>Data Bits</u>	<u>Parity</u>	<u>Stop Bits</u>	<u>Flow Control</u>
9600	8	None	1	None

A screen shot of the HyperTerminal output is illustrated in Figure 5.3. HyperTerminal was only used as a method of data capturing and not intended for use on the satellite as the data on the satellite is processed by the command and data handling sub-system. This data is sent using I²C communication interface which can easily be included in the FPGA smart design. Data is sent using a data string with the following format:

Date:time:battery voltage:state of charge:SA voltage:SA current:Power:distribution
 3.3V:distribution 5V

12042013:145943:4.01:1:3.68:0.653:2.403:3.43:4.94

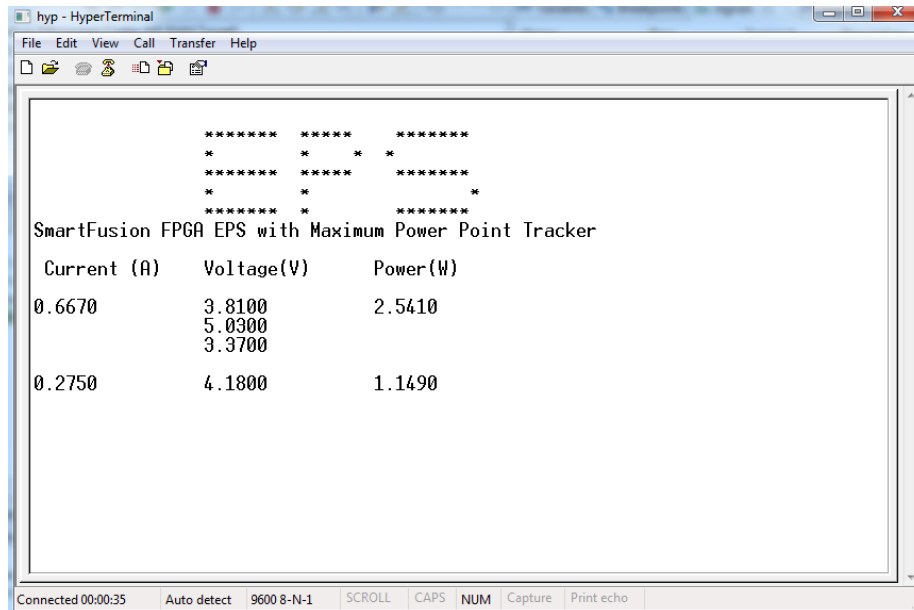


Figure 5.3: HyperTerminal output screen

The above data is tabulated below:

Table 5.2: EPS data

<u>Battery</u>	<u>Solar array</u>	<u>Solar array</u>	<u>Output</u>	<u>3.3V bus</u>	<u>5V bus</u>
4.18V	3.81V	667mA	2.541W	3.37V	5.03V

The information gathered from the EPS prototype shows that the battery voltage is 4.18V and discharging at 0.27C. The solar array is operating close to maximum power point providing 667mA at 3.81V. The distribution system bus voltages are regulated to 3.37V on the 3.3V distribution system and 5.03V on the 5V distribution system.

5.1.1 PWM Output Frequency

The PWM output frequency is a function of the bit-width. As the counter has 7-bits with a binary decimal equivalence of $2^7 = 128$, the output frequency may be calculated as in Equation 5.1.

$$PWM_{of} = \frac{Fab_clk}{128}, \quad (5.1)$$

$$PWM_{of} = \frac{30Mhz}{128},$$

$$PWM_{of} = 235kHz.$$

This step has certain significance as the dc-dc converters were designed using this frequency shown in Appendix F and Appendix J.

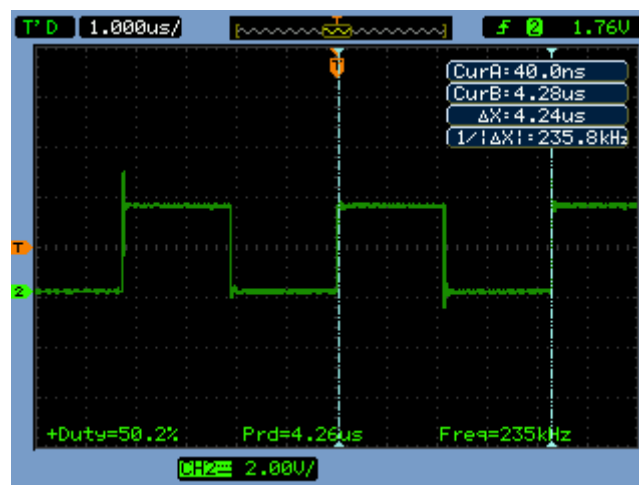


Figure 5.4: Measured output frequency

Shown in Figure 5.4 is the output waveform of the PWM. The frequency was measured at 235kHz.

5.1.2 Duty Cycle Verification

The duty cycle verification test was conducted in order to ensure that the values programmed into the GPIO output register produce the desired duty cycle. Figure 5.5 shows duty cycles of 25.7%, 50.2%, 74.8% and 100% at a frequency of 235 kHz. Exact duty cycles can be achieved; however, this required the use of more GPIO inputs to increase the resolution of the PWM circuit.

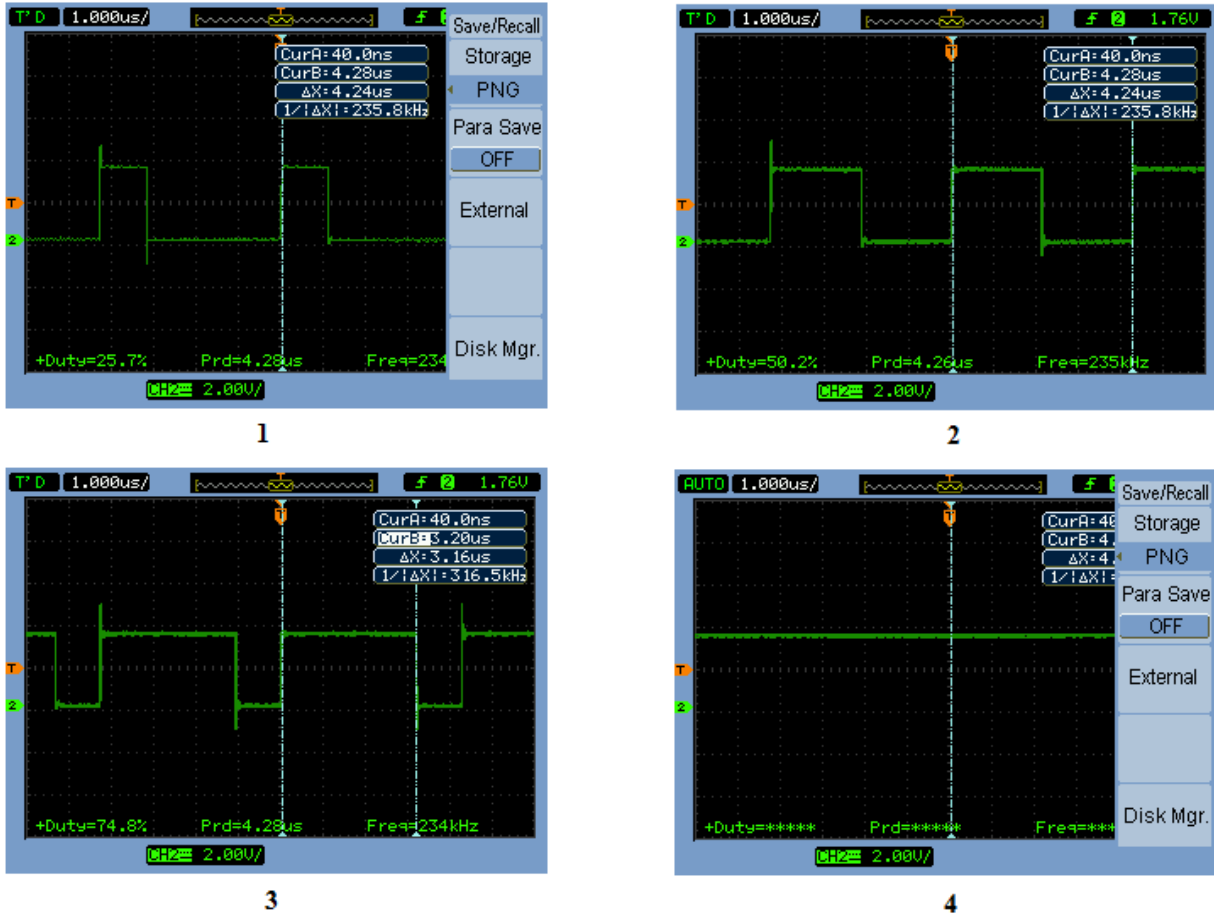


Figure 5.5: Duty cycle verification

For instance, currently seven GPIOs are used giving a maximum count of 2^7 . The GPIO output value for 1% duty cycle is calculated using Equation 5.2:

$$GPIO_value = \frac{Duty_Cycle}{100} \times 2^n, \quad (5.2)$$

where n is the number of GPIOs:

$$GPIO_value = \frac{1\%}{100} \times 127,$$

$$GPIO_value = 1.27.$$

However, only positive integer values can be programmed; thus by sending a value of 1 to the GPIO output register, 0.78 increments can be made. Using an 8-bit input yields a maximum count of 2^8 ; therefore, using equation 5.2, the GPIO_value is calculated as follows:

$$GPIO_value = \frac{1\%}{100} \times 255,$$

$$GPIO_value = 2.55.$$

By sending a value of 2.55, 1% increments are possible; however, if a value of 1 is sent to the GPIO output register, 0.38 increments are possible, thereby increasing the resolution of the PWM output.

5.1.3 MPPT Verification

The experimental setup shown in Figure 5.6 determined the performance of the maximum point tracking circuit. The solar cells were connected in a 1-series-3-parallel connection with the active load tuned to 6Ω to draw maximum current. The sample sequencing engine is able to take a MPPT current measurement every 47.067μs, as indicated in Figure 4.16. This indicates that in order to achieve a time scale of 1000ms, 21246.308 samples need to be taken; however, one sample was taken every 4ms and consequently only 250 samples were required to obtain a 1000ms time scale.

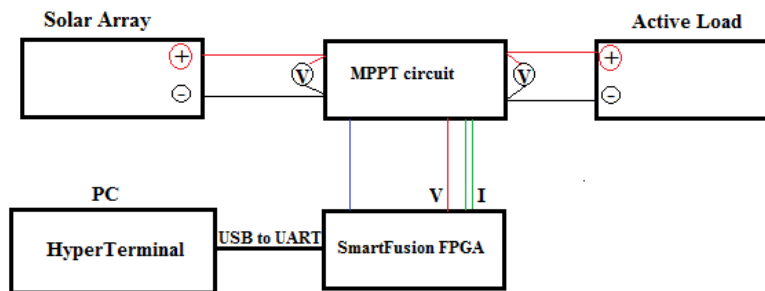


Figure 5.6: MPPT experimental setup

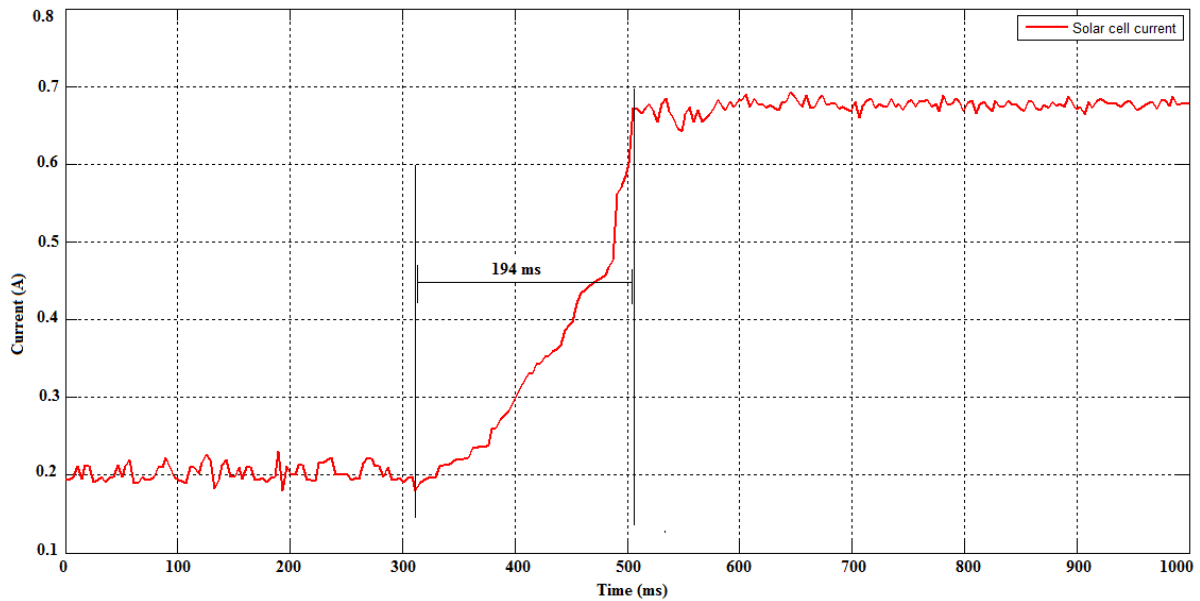


Figure 5.7: MPPT performance switching from low level to high level of solar irradiance

While the maximum power point tracking algorithm was not allowed to operate, approximately 200mA was drawn from the solar panels. Figure 5.7 indicates that at 310ms, the maximum power point tracking algorithm was allowed to operate and an increase in solar cell output current is evident. The output current increased from 200mA and fluctuated between 653mA and 681mA. The input current at this moment was measured at 721mA, showing an efficiency of 90.56% and 94.45%, a satisfactory result as power system efficiency of 76.5% was set as a design requirement. The fluctuation is due to the perturbation around the maximum power point which may be addressed by decreasing the size of the perturbation. The efficiency shows that the maximum power point circuit dissipated 7% of the solar power available. The results indicate that 194ms is required to determine the maximum power point when switching from a low level of solar irradiance to a high level of solar irradiance while Figure 5.8 shows that 347ms is required to move from a high level of solar irradiance to a low level of solar irradiance.

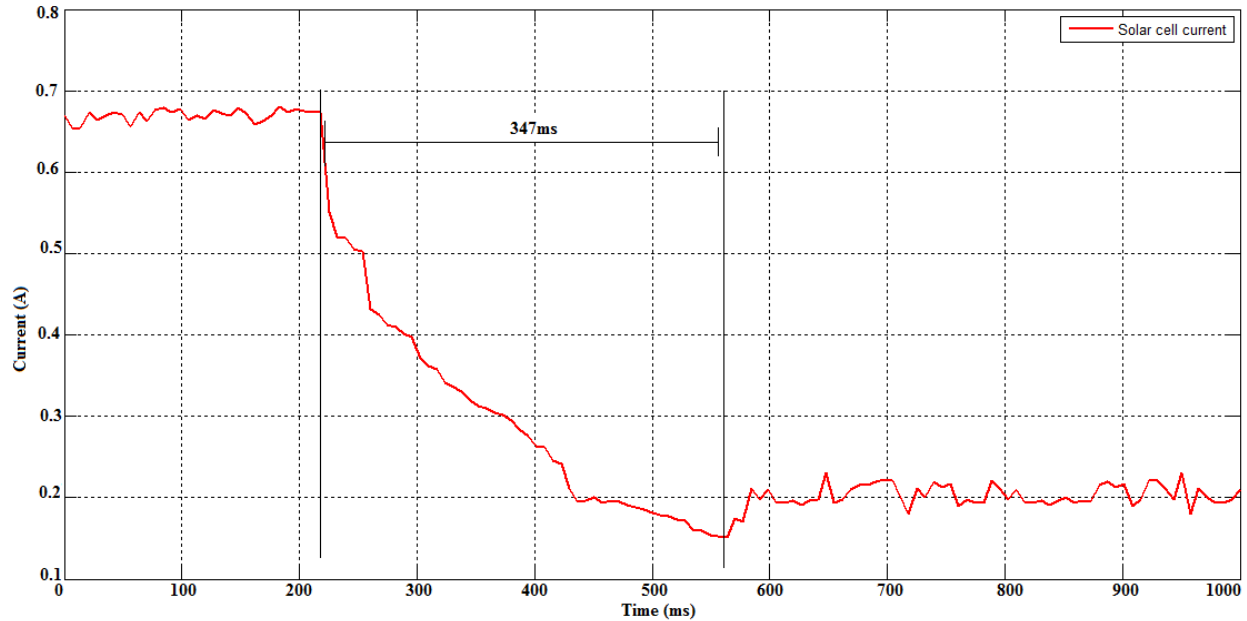


Figure 5.8: MPPT performance switching from high level to low level of solar irradiance

The maximum power point was achieved in 347ms at worst case, slightly faster than that of Bester (2011) who achieved 419ms at worst case, as well as the 1s settling time achieved by Lee, Bae and Cho (2006). The power consumption of the EPS was estimated as 330mW as indicated in the power budget; however, the SmartFusion FPGA consumes only a worst case of 148.93mW, showing a 55% decrease in power consumption from the estimate.

5.1.4 Battery Charging Circuitry

In order to determine the performance of the battery charging circuitry, the lithium-ion battery was discharged to a voltage of 4.05V, corresponding to the start of the charge period. As the LTC 5404-4.2 integrated circuit employs a ‘constant current-constant voltage’ charging method, the maximum current during the constant current was set using a 2.2 k Ω resistor and measured as fluctuating between 445mA and 420mA. The battery voltage indicated in Figure 5.9 increases steadily until point 1, approximately five minutes into the charging cycle. At this point the current has already started to decrease (see Figure 5.10) which indicates the start of the constant voltage mode.

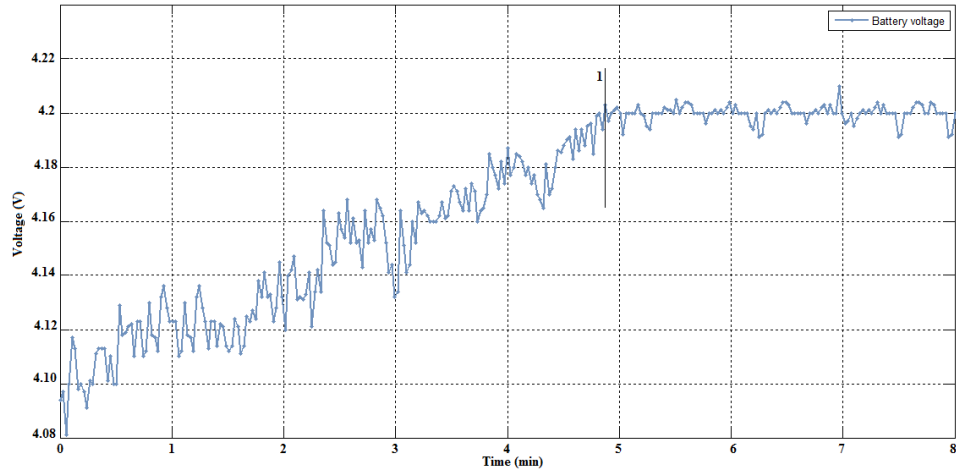


Figure 5.9: Battery voltage during charge period

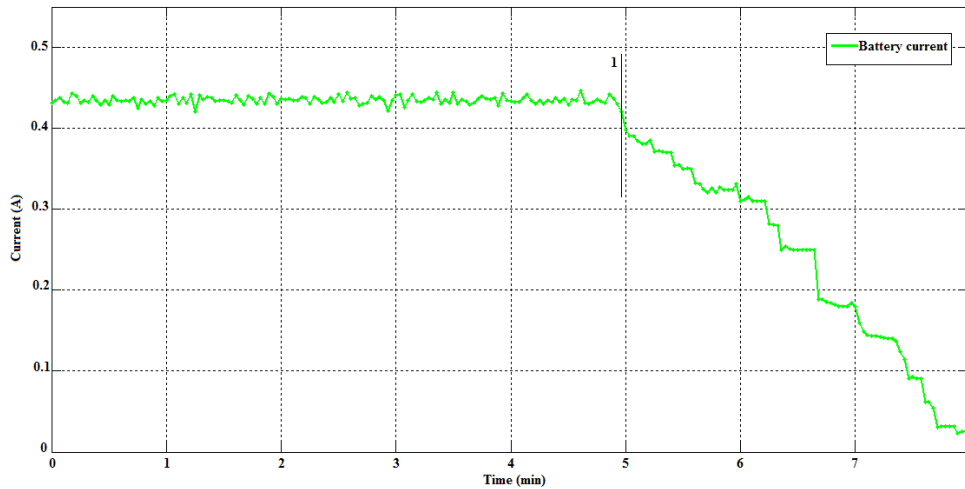


Figure 5.10: Battery charge current during charge period

This is a satisfactory result as the completion of the charge cycle took approximately eight minutes, less than the orbital time spent in the sun which was calculated to be 65.32min. A concern might arise when the battery needs to discharge during the time spent in eclipse in order to provide enough power to operate the transmitter. However, this concern will be evaluated during the orbital simulation test.

5.1.5 Distribution System

The distribution system gating signal and duty cycles were verified and illustrated in Figure 5.11.

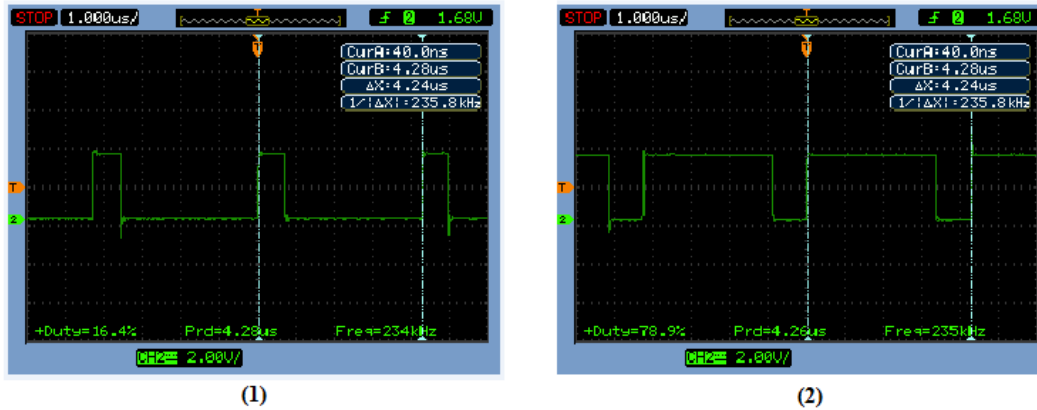


Figure 5.11: dc-dc converter gating signals

Figure 5.11 shows the duty cycle output of the SmartFusion FPGA used to control the output of the 5V and 3.3V dc-dc converters. An output frequency between 234 kHz and 235kHz was measured, correlating well with the chosen frequency of 235kHz. The figures also indicate that the required duty cycle calculated in Appendix J was obtained for both 5V and 3.3V dc-dc converters. A 16.4% duty cycle, as opposed to a calculated 16% required for the 5V boost converter, was measured while a 78.9% duty cycle was measured opposed to a calculated 78.5% required by the 3.3V buck-converter. This small variation in duty cycle can be attributed to the step size of 1.27 which is set by the number of GPIOs used in the design, as previously mentioned. The system was tested using the experimental setup shown in Figure 5.12. The figure shows the use of a bench power supply regulated to produce an output of 4.2V which simulates the regulated output of the maximum power point tracking circuit.

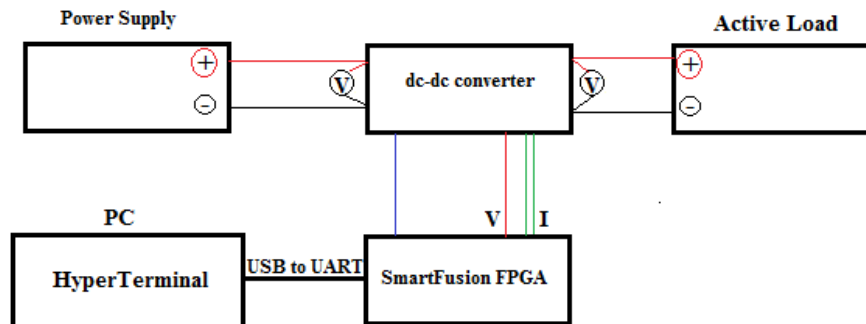


Figure 5.12: Distribution system experimental setup

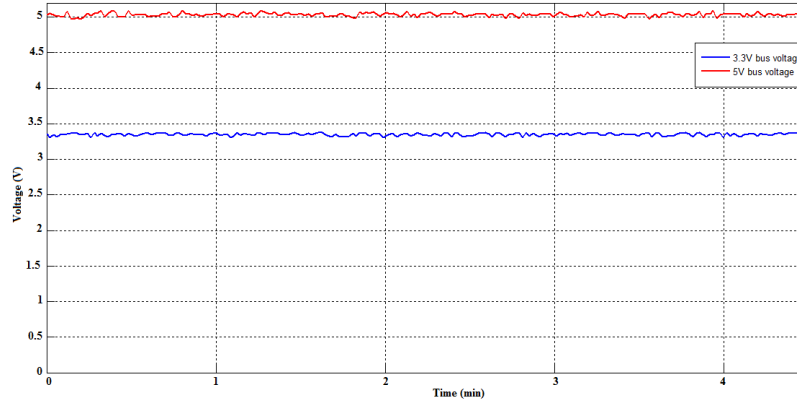


Figure 5.13: dc-dc converter output measurements

Figure 5.13 shows the output of the dc-dc converters. The SmartFusion FPGA is able to regulate the output of the dc-dc converters to stay within 1% of the required bus voltages. Voltages ranged from 4.95V to 5.05V on the 5V bus and 3.25V to 3.35V on the 3.3V bus.

5.2 System Integration

System integration tests were conducted in order to verify the performance of the prototype. Tests were done to confirm that the performance of the various sub-systems which constitute the electronic power system behave as previously tested. Similar experimental setups to Figure 5.12 were conducted to ensure that the system is fully integrated into the FPGA design and is in fact a design solution. Appendix K shows the VHDL implementation of the complete design.

The Libero[®] design canvas indicated in Appendix K shows that the VHDL PWM modules, together with the 3.3V and 5V distribution system, are integrated into the design. The 3.3V and 5V PWM modules will regulate the bus voltage by measuring the output voltage of these voltage buses and implementing a proportional controller to regulate the output voltage. Similar design steps are used to instantiate these VHDL modules into the design. Table 5.3 shows the SmartFusion FPGA resources that were utilised in order to complete the design. The table indicates that only 2.56% of the FPGA fabric, 13.83% of the fabric with clock, 31.25% of the dedicated analogue I/Os and 6.98% of the dedicated microcontroller sub-system I/Os were utilised. These results indicate that the full resources of the SmartFusion FPGA were not needed to complete the design and that more functions could be programmed into the FPGA design; however, more functionality implies the use of more power. As power is a critical

parameter in the CubeSat design process, minimum resources are utilised while ensuring the functionality of the EPS sub-system.

Table 5.3: SmartFusion resource utilisation

<u>FPGA resource</u>	<u>Status</u>	<u>Total amount</u>	<u>Utilised</u>	<u>Percentage</u>
Microcontroller sub-system	used	1	1	100%
Fabric	used	4608	118	2.56%
Fabric I/O (w/clocks)	used	13	94	13.83%
Fabric Differential	Not used	47	0	0%
Dedicated Analogue IO	used	32	0	31.25%
Dedicated MSS IO	used	43	3	6.98%
GLOBAL (Chip + Quadrant)	Not used	15	0	0%
MSS Global	used	3	3	100%
On-chip RC oscillator	used	1	1	100%
Main Crystal oscillator	Not used	1	0	0%
32 kHz Crystal oscillator	Not used	1	0	0%
RAM/FIFO	Not used	8	0	0%
User JTAG	Not used	1	0	0%

Table 5.3 indicates the power that is utilised by the SmartFusion FPGA in order to drive the resources indicated in Table 5.2. The table shows the estimated power consumption for the best, worst and typical cases. It is assumed that the battery heater, included in the power budget, is able to regulate the temperature so as not to fall below 0° C. The best, worst and typical cases show a total power consumption of 90.559mW, 148.93mW and 103.24mW respectively (see Table 5.4). These results are further broken down and illustrated in Figure 5.14.

Table 5.4: Estimated power consumption

<u>Case</u>	<u>Static</u>	<u>Dynamic</u>	<u>Total</u>
Best	23.145 mW	67.414 mW	90.559 mW
Worst	58.959 mW	89.971 mW	148.93 mW
Typical	24.987 mW	78.253 mW	103.24 mW

The power consumption for the worst case is 54.86% less than the allowed 330mW indicated in the power budget, thus allowing more power for charging or a larger payload duty cycle. Orbital simulation tests were conducted in order to determine whether or not the electronic power supply using the SmartFusion FPGA can supply the loads during eclipse and a period of sun exposure.

5.2.1 Orbital Simulation Tests

Orbital simulation tests were conducted in order to verify the operation of the electronic power supply sub-system. The electronic power system consists of the SmartFusion field-programmable-gate array, solar cells, battery charger, lithium-ion battery, maximum power point circuitry, 3.3V and 5V distribution systems, and the active loads. The orbital simulation test was conducted using the experimental setup illustrated in Figure 5.15.

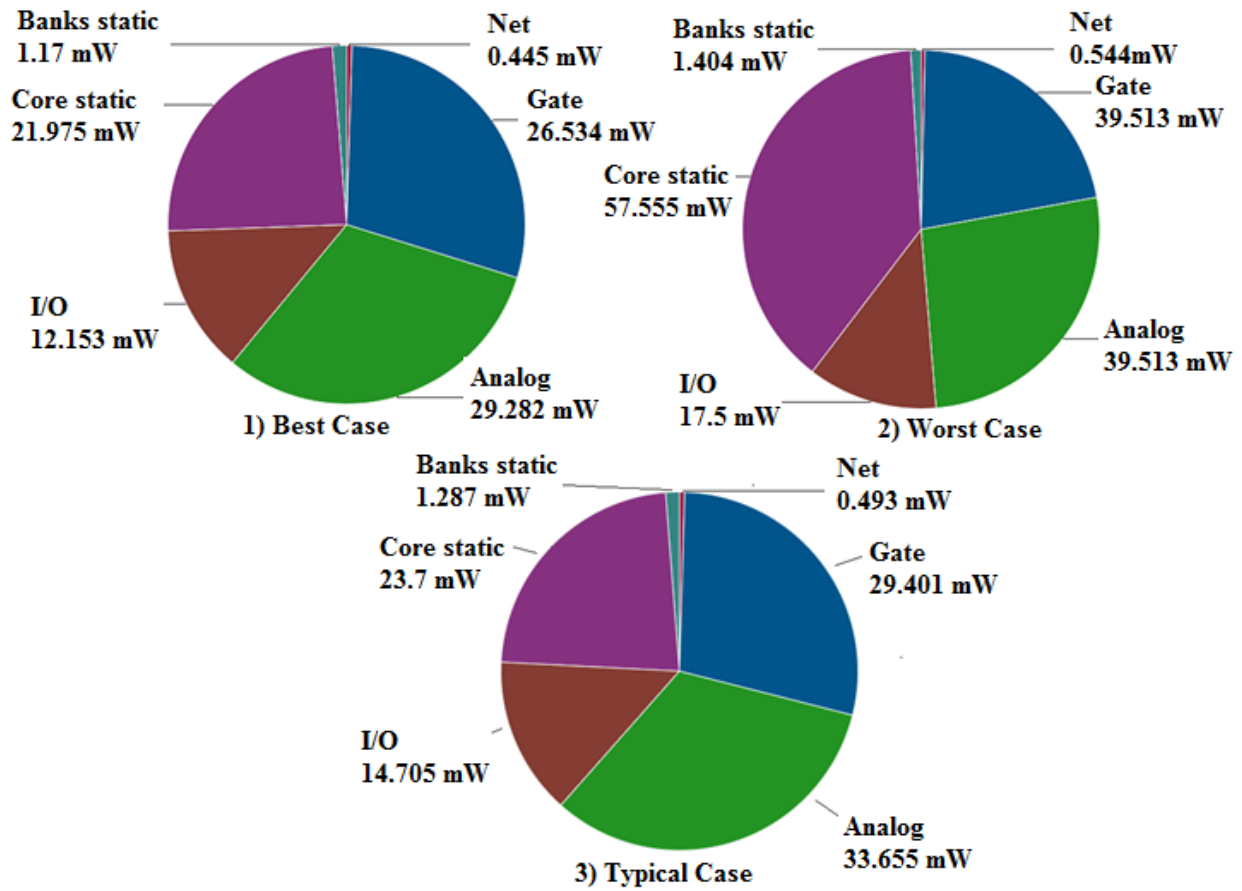


Figure 5.14: SmartFusion FPGA power consumption

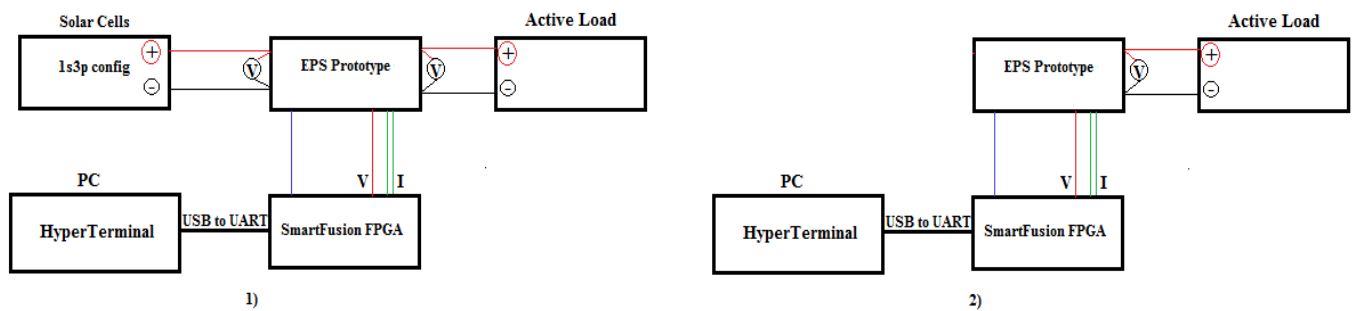


Figure 5.15: Orbital simulation configuration

Figure 5.15 shows two experimental configurations for simulating the CubeSat power configuration during the period of exposure to the sun, indicated by 1. Configuration 2 shows the configuration during the period of eclipse.

During the configuration indicated by 1, the solar cells are connected in a 1s3p configuration while the electronic power supply prototype has the secondary source of power connected with a voltage of approximately 3.36V with an 80% state-of-charge. The lithium-ion battery was discharged to 20% depth-of-discharge in order to simulate the period of the CubeSat orbit where the nano-satellite exits the period of eclipse and enters the period of exposure to the sun. Consequently, it is expected that the lithium-ion battery should enter a constant-current charge mode as soon as the prototype enters maximum power point tracking mode. The voltage and current levels are monitored by the SmartFusion FPGA which implements the perturb-and-observe maximum power point tracking algorithm to maximise the current drawn from the solar cells. Figure 5.16 indicates the changing levels of currents during a full orbit of 101 minutes while Figure 5.17 shows the changing battery levels over the same orbital period.

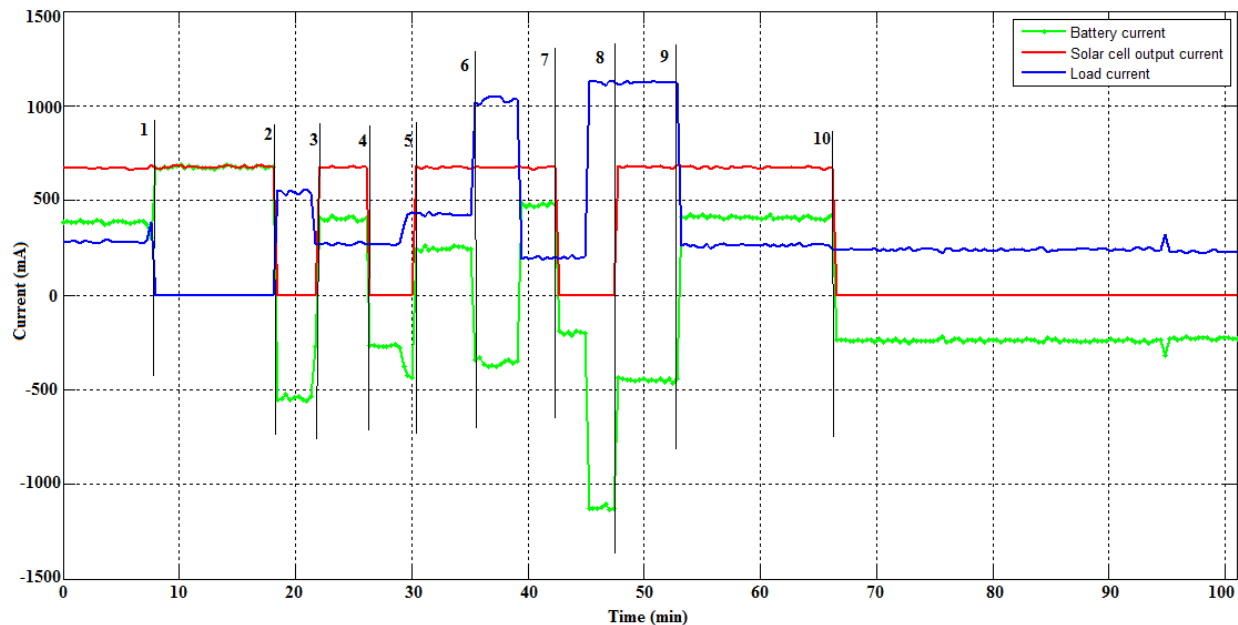


Figure 5.16: EPS prototype currents during orbital simulation tests

Figures 5.16 and 5.17 are explained in detail, analysing the events between the different points on the graphs. The points on the graphs represent the same instance of time within the orbital period, providing a good indication of the EPS prototype response under varying load requirements and varying battery voltage.

From point 0 to point 1:

The EPS prototype is operating with the maximum power point tracker enabled simulating the period of sun exposure. The solar cells are able to obtain a maximum power point and supply the CubeSat with approximately 0.668mA, indicated by the red data points. This current varies due the perturbations that occur around the maximum power point. The blue data points indicate that the current drawn by the load is less than the current produced at maximum power, allowing the lithium-ion battery to charge. The charge period increases the state-of-charge of the lithium-ion battery indicated in Figure 5.17 between point 0 and point 2.

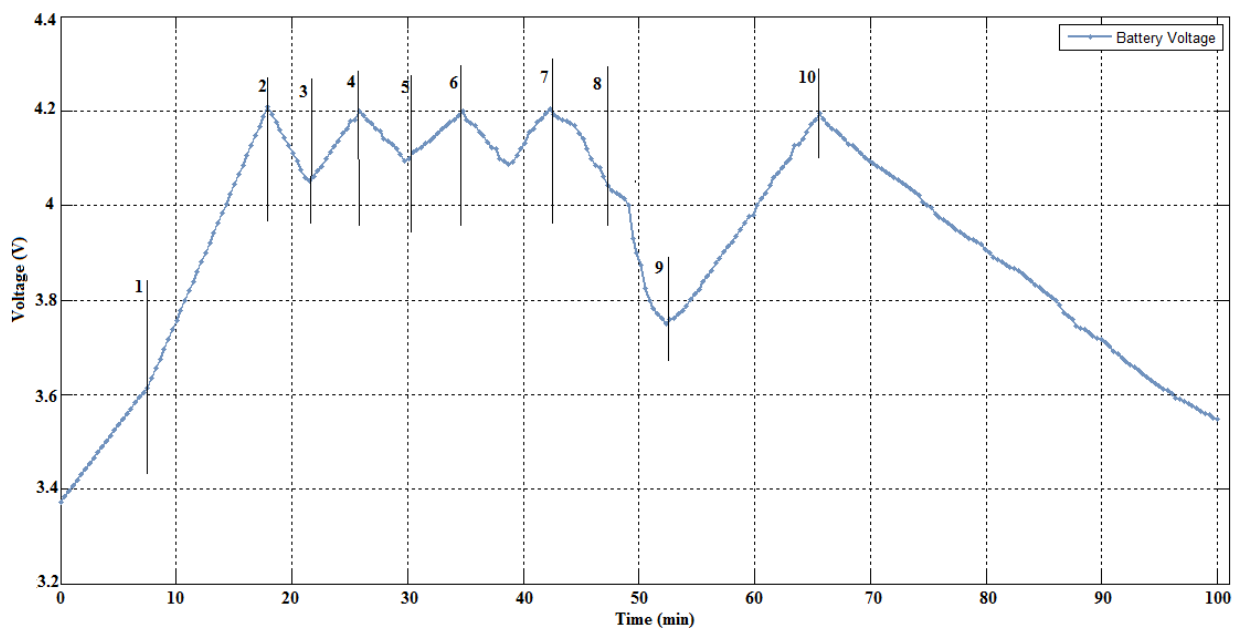


Figure 5.17: Battery voltage variation

From point 1 to point 2:

It is noticed that as soon as the load current is decreased to 0A, the currents produced by the solar cells are used to charge the secondary power source at a faster rate indicated between point 1 and point 2, shown in Figure 5.17. Previous versions of this prototype were unable to source all the current into the battery due to the 2.2k Ω program resistor (R_{PROG}) of the battery charging circuit; however, the problem was solved by replacing this resistor with a 1.2k Ω resistor allowing more current to be sourced by the charging circuit.

From point 2 to point 3:

The MPPT was terminated due the state-of-charge of the lithium-ion battery being 100% at which point the battery immediately enters a state-of-discharge shown by the negative current which matches the requirements of the load. The battery voltage was allowed to drop to 4.05V before activating the MPPT algorithm again (this value can be changed via software).

From point 3 to point 4:

For the period between point 3 and point 4, the secondary source of power was allowed to charge while the solar cells were able to supply a load current of 275mA. 4.2V was reached at point 4, stopping the charge cycle and thus the operation of the maximum power point tracking algorithm.

From point 4 to point 7:

The maximum power point tracking algorithm was restarted at point 5 when the battery voltage dropped below 4.05V and then activated the charging cycle. At point 6 the load current was increased to 1000mA, which is higher than the current the solar cells are able to produce. The lithium-ion battery voltage decreased at point 6 in Figure 5.17 indicating that that the battery had entered a state of discharge and thus supplying the balance of the current required by the load. As soon as the load current was decreased, the battery started charging again until the battery voltage reached 4.2V at point 7.

From point 7 to point 9:

From point 7, a load current of 275mA was supplied by the battery before a large current of 1100mA was drawn. The battery voltage dropped to below 4.05V which activated the maximum power point tracking algorithm; however, the battery continued to discharge as the load current of 1100mA was maintained for another three minutes during which the battery voltage dropped to 3.72V.

From point 9 to 10 minutes:

At point 9 normal operations continued until point 10, allowing the battery to be fully charged before entering the simulated eclipse period indicated by the zero solar cell output current after point 10. The battery continues to discharge until 3.55V, approximately 85% state-of-charge

with a depth-of-discharge of 15%, higher than the calculated 13.8% DoD. However, the 13.8% was calculated at a discharge current of 236.2mAh while the orbital simulation showed current drawn to be approximately 275mAh, giving rise to the slight variation.

The orbital simulation tests produced satisfactory results as they show that the secondary sources of power are able to overcome the eclipse period through the implementation of the SmartFusion FPGA as the main controller.

Chapter 6

Conclusion and Recommendations

6.1 Conclusion

The research aimed to investigate the use of a field-programmable-gate-array as the main controller in an electronic power system of a nano-satellite. Field-programmable-gate-arrays have not yet been implemented on CubeSat electronic power supply sub-systems because the perception is that these devices consume relatively large amounts of power. Because the size, weight and power constraints of CubeSats are limiting factors of the CubeSat standard, engineers and researchers are endeavouring to overcome these constraints by eliminating the need for larger more expensive satellites. Thus, addressing the size, weight and power constraints of individual sub-systems that constitute the CubeSat will not only increase the efficiency of that particular sub-system but increase the efficiency of the entire CubeSat. The research investigated whether or not the implementation of a FPGA-based electronic power supply sub-system addresses these identified size, weight and power constraints.

The electronic power system using the SmartFusion FPGA as the main controller prototype was designed, developed and tested. The various steps taken to complete the project are listed below:

- Power budget was designed considering the environment in space, orbital parameters, critical sub-systems, payloads and the duty cycle of operation of these sub-systems.
- Solar cell technology was investigated and an appropriate maximum power point tracking algorithm was selected from comparative studies.
- A secondary source of power was sized according to the system requirements.
- An electronic power supply prototype was designed and developed with the Smart-Fusion FPGA as the main controller of the nano-satellite.

- Stand-alone tests were conducted to verify the operation of the different sub-circuits of the EPS sub-system.
- Orbital simulation tests were conducted to verify the integration of the various sub-circuits of the sub-system.

The SmartFusion FPGA was programmed with the necessary control algorithms in order to control the state of charge of the lithium-ion battery. The FPGA employs a maximum power point tracking algorithm that is able to track the change in maximum power due to the variations in solar irradiance. The EPS prototype is also able to deal with variations in load current while being able to charge the secondary source of power during the full period of sun exposure. During the eclipse period, the battery voltage decreased to 3.55V, corresponding to an approximate 15% depth-of-discharge, falling into a satisfactory region as a 20% depth-of discharge was anticipated during the eclipse period.

The SmartFusion FPGA offers a high level of integration as it contains ADCs, an ACE, SSE and PPE, decreasing the component count of non-FPGA control based nano-satellite power systems. The aforementioned features optimise the EPS-system even more as the SSE captures the information from the ACE and passes it to the PPE where the data can be transformed and filtered. These actions ensure that during high microcontroller activity, sample sequencing occurs and information required for calculating the MPPT is not lost, thereby improving the reliability of the system.

To limit the power consumption of the FPGA, the full functionality of the FPGA was not utilised. The SmartFusion FPGA analogue compute engine allows for complex algorithms such as the maximum power point tracking and battery charge regulation algorithm to be implemented on the microcontroller sub-system, as these allow for the offloading of many repetitive calculations which then allow the microcontroller sub-system to perform functions with higher accuracy and increased performance. These unique features of the SmartFusion FPGA address the size, weight and power constraints of the CubeSat standard within the electronic power supply sub-system.

6.2 Problems Encountered

- SoftConsole does not enter debug mode when frequencies less than 8Mhz is chosen.

- D13 (red LED) on the SmartFusion lights up and loads the last pdb. file in the NVM. This was due to faulty CP210x USB to UART driver (re-install driver to fix problem).
- Current sense resistor. Value ranges from 0.00001Ω to 0.1Ω . A 0.01Ω resistor was placed in parallel with another 0.01Ω resistor to achieve a 0.005Ω current sense resistor, allowing a measurement range between $250\mu\text{A}$ and 1.023A .
- CorePWM driver did not load. When using the CorePWM module, the APB3 AMBA should be used in conjunction because the CorePWM will be connected as the slave while interfacing with this AMBA.
- Make file not generated. This problem was solved by creating a make file in which the files are generated. The cmd line: "taskkill /IM make.exe /F" was used to terminate hanging make file instances.
- Remember to include all .h files.
- CorePWM implementation did not work.
- The PWM 1 and PWM 0 pins have a first order RC filter connected on their output which could filter certain frequencies causing a 0V output when measured using an oscilloscope.

6.3 Recommendations for Future Work

- Using the mixed signal daughter card only allowed the use of two of the four available current sensors, limiting the amount of information that could be gathered at a single instance of time; however, using the SmartFusion FPGA as a stand-alone device will allow the utilisation of the resources as dedicated evaluation board pin outs become available.
- Using the FPGA in a system with more power available will allow the usage of more of the available SmartFusion capacity as only 31.25% of the FPGA's analogue resources, 6.98% MSS I/O resources and only 2.56% of the FPGA fabric were used to complete the design. Therefore, developing an EPS with an integrated OBC, communication, command and data handling or payload sub-system will utilise more of the SmartFusion functionalities and produce a system with lower component count and smaller footprint. Thus, various levels of redundancy can be programmed into the eNVM and only become active if a component or sub-system should fail, further augmenting the nano-satellite through the use of the SmartFusion FPGA.

- This design could be implemented on a PC-104 circuit board and could make use of surface mount components. Using the surface mount components will further reduce the physical size of the EPS sub-system on PC-104 circuit board while a good PCB design and layout reduce the noise signals that were superimposed on the various output and control signals. This space saved can be used for redundant circuits, further increasing the reliability of the system.

Publications emanating from the dissertation

Cupido, S.W.J., Adonis, M. & Barnard, A. (in-press). MPPT efficacy design via an FPGA implementation for Nano-satellites, International Journal on Energy Conversion (IRECON).

Cupido, S.W.J. & Adonis, M. (in-press). MPPT algorithm via VHDL programming for a CubeSat, ICEE/ICIT-2013, 8 to 12 December 2013 in Cape Town, South Africa

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Appendix A: Nano-Satellite Mission

Table A-1: Previous CubeSat missions

<u>Country</u>	<u>Year</u>	<u>CubeSat name</u>
South Africa	2012	ZA-CUBE 01
Romania	2012	GOLIAT
Poland	2012	BPW-Sat
France	2012	Robusta
Spain	2012	XaTcobeá
Hungary	2012	MaSat-1

Appendix B: MATLAB® Source Code

V-I characteristics

```
Iph = 3.17;
Isat = 0.5*(10^-6);
q = 1.6*(10^-19);           %Electron Charge
k = 1.38*(10^-23);         % Boltzmann's constant
n = 1.5;                   %diode ideality factor
Ns = 36;                   %series connected cell
Rs = 0.004;                %series resistance
Vd = 0.1:21.8;
Ta=20;                     %Reference temperature
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
figure;
plot(V,I,'k')
hold on
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
%figure;
plot(V,I,'r')
Ta=40;
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
%figure;
plot(V,I,'g')
Ta=50;
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
%figure;
plot(V,I,'c')
Ta=60;
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
%figure;
plot(V,I,'m')
Ta=70;
Tcell = 273+Ta;
I = Iph-Isat*(exp((q*Vd)/(n*k*Tcell*Ns))-1)
V = Vd-I*Rs
%figure;
plot(V,I,'b')
xlabel('Voltage in Volts')
ylabel('Current in Amps')
title('I-V curve for varying temperatures')

grid on
```

Appendix C: MATLAB® Source Code

Average Orbit Power

```
clear all
clc
steps=150
theta=0:90/steps:90
phi=0:90/steps:90
[a,b]=size(theta)
totPow=zeros(b,b)
limitAngle=0
limitAngleReverse=90-limitAngle

side1pow=0
side2pow= 2.11
side3pow= 2.11

side1powTemp=0
side2powTemp=0
side3powTemp=0

for i = 1:b
    for j = 1:b
        if ((phi(j)>=limitAngleReverse) || (theta(i)<=limitAngle))
            side1powTemp=0;
        else
            side1powTemp = side1pow*cosd(phi(j))*sind(theta(i));
        end
        if ((theta(i)<=limitAngle) || (phi(j)<=limitAngle))
            side2powTemp=0;
        else
            side2powTemp = side2pow*sind(theta(i))*sind(phi(j));
        end
        if (theta(i)>=limitAngleReverse)
            side3powTemp= side3pow*cosd(theta(i));
        else
            side3powTemp = side3pow*cosd(theta(i));
        end
        totPow(i,j) = side1powTemp+side2powTemp+side3powTemp;
    end
end
end
surface(phi,theta,totPow)
shading interp
ylabel('\theta (degrees)','FontSize',14)
xlabel('\phi (degrees)','FontSize',14)
zlabel('Solar Array Output Power (W)','FontSize',14)
title('Solar Array Output Power for varying angles of
incidence','FontSize',16,'FontWeight','bold')
grid on

max_power=0
for i=1:b
    for j=1:b
```

```
        if max_power < totPow(i,j)
            max_power = totPow(i,j)
            max_phi=j
            max_theta=i
        end
    end
end

max_theta=max_theta*(90/(steps+1))
max_phi=max_phi*(90/(steps+1))

avg_power=mean(mean(totPow))
```

Appendix D: MATLAB® Source Code

Perturb-and-observe algorithm

```
function D = PandO(Param, Enabled, V, I)

% MPPT controller based on the Perturb & Observe algorithm.

% D output = Duty cycle (value between 0 and 1)
%
% Enabled input = 1 to enable the MPPT controller
% V input = PV array terminal voltage (V)
% I input = PV array current (A)
%
% Param input:
Dinit = Param(1); %Initial value for D output
Dmax = Param(2); %Maximum value for D
Dmin = Param(3); %Minimum value for D
deltaD = Param(4); %Increment value used to increase/decrease the duty cycle
D
% ( increasing D = decreasing Vref )

persistent Vold Pold Dold;

dataType = 'double';

if isempty(Vold)
    Vold=0;
    Pold=0;
    Dold=Dinit;
end
P= V*I;
dV= V - Vold;
dP= P - Pold;

if dP ~= 0 & Enabled ~=0
    if dP < 0
        if dV < 0
            D = Dold - deltaD;
        else
            D = Dold + deltaD;
        end
    else
        if dV < 0
            D = Dold + deltaD;
        else
            D = Dold - deltaD;
        end
    end
else D=Dold;
end

if D >= Dmax | D<= Dmin
```

```
    D=Dold;  
end
```

```
Dold=D;  
Vold=V;  
Pold=P;
```

Appendix E: Power Budget

Payload/sub-systems	Voltage (V)	Current (mA)	Power (mW)	Duty Cycle during Sun	Duty Cycle during Eclipse	Power during Sun (mW)	Power During Eclipse (mW)
EPS							
FPGA(Control Circuitry)	3.30	100	330	1	1	330	330
Battery Heater	3.30	66.67	220.01	0.00	0.50	0.00	110.01
OBC							
ARM 7 core	5.00	22.00	110.00	1.00	1.00	110.00	110.00
VHF							
Rx	5.00	50.00	250.00	1.00	1.00	250.00	250.00
UHF							
Tx (10 min max)	5.00	200.00	1000.00	0.15	0.00	151.50	0.00
Imaging							
Camera (6.6 min max)	3.30	75.00	247.50	0.10	0.00	24.75	0.00
Sub-Total			2157.51			866.25	800.01
Design Margin (5 %)			107.88			43.31	40.00
Total Power			2265.39			909.56	840.01
Power System Efficiencies							
Path from Solar arrays to PowerBus (85%)			339.8079825			136.434375	126.0008663
Path from Power Bus to Battery (100 %)			0				
Path from Power Bus to Payload (90 %)			226.538655			90.95625	84.0005775
Total Power Required			2831.73			1136.95	1050.01
User input							
Calculated							

Appendix F: MPPT Circuit Design Calculations

The boost converter is needed to step up the voltage of the solar array in order to match the voltage of the battery pack.

Table F-1: MPPT converter design parameters

<u>Parameter</u>	<u>Symbol</u>	<u>Value</u>
Input Voltage	V_{in}	3.8V
Output Voltage	V_{out}	4.2
Input Power	P_{in}	2.9W
% Ripple Voltage	V_{ripple}	1%
% Ripple Current	I_{ripple}	10%
Switching Frequency	f_{sw}	235kHz

Duty cycle calculation:

$$D = 1 - \frac{V_{in}}{V_{out}}$$

$$D = 1 - \frac{3.88V}{4.2V}$$

$$D = 0.076$$

Input current:

$$I_{in} = \frac{P_{in}}{V_{in}}$$

$$I_{in} = \frac{2.9W}{3.88V}$$

$$I_{in} = 0.747A$$

Output current:

$$I_{out} = \frac{P_{in}}{V_{out}}$$

$$I_{out} = \frac{2.9W}{4.2V}$$

$$I_{out} = 609.47mA$$

Output ripple current:

$$\Delta I_L = 0.747 \left(\frac{1}{100} \right)$$

$$\Delta I_L = 0.00747A$$

Output ripple voltage:

$$\Delta V_{out} = 4.2 \left(\frac{1}{100} \right)$$

$$\Delta V_{out} = 42mV$$

Switching period:

$$T = \frac{1}{f_{sw}}$$

$$T = \frac{1}{235Khz}$$

$$T = 4.255\mu s$$

Switch on-time:

$$T_{on} = 4.255\mu s \times 0.076$$

$$T_{on} = 323.4ns$$

Inductor value:

$$L = \frac{V_{in} \times T_{on}}{\Delta I_L}$$

$$L = \frac{3.88V \times 323.4ns}{0.00747A}$$

$$L = 167.97\mu H \Rightarrow 180\mu H$$

Output capacitor:

$$C = \frac{I_{out} \times D}{\Delta V_{out} \times f_{sw}}$$

$$C = \frac{609.47mA \times 0.076}{42mV \times 235KHz}$$

$$C = 4.692\mu F \Rightarrow 46.92\mu F$$

Appendix G: VHDL PWM

```
library IEEE;
use IEEE.std_logic_1164.all;
use IEEE.std_logic_arith.all;
use IEEE.std_logic_unsigned.all;
entity VHDL_PWM is
    port (
        clk : in std_logic;
        reset: in std_logic;
        pwm_value: in std_logic_vector (6 downto 0) ;
        pwm_out : out std_logic
    );
end VHDL_PWM;
architecture behavioural of VHDL_PWM is
    signal counter : std_logic_vector(6 downto 0) ;
begin
    process ( clk,reset,counter,pwm_value )
    begin
        if (reset = '0') then
            pwm_out <= '0';
        elsif rising_edge(clk) then
            if (pwm_value >= counter) then
                pwm_out <= '1' ;
            else
                pwm_out <= '0' ;
            end if;
        end if;
    end process;
end architecture;
```

```
        end if;
    end process;
process ( clk,reset )
    begin
        if (reset = '0') then
            counter <= "0111111";
            elsif rising_edge(clk) then
                counter <= counter + 1;
            end if;
        end process;

-- architecture body

end behavioural;
```

Appendix H: VHDL PWM Test Bench

```
LIBRARY ieee;

USE ieee.std_logic_1164.ALL;

USE ieee.std_logic_unsigned.all; --

ENTITY test_tb IS

END test_tb;

ARCHITECTURE behavior OF test_tb IS      -- Component Declaration for the Unit Under Test (UUT)

COMPONENT VHDL_PWM --'test' is the name of the module needed to be tested.

--just copy and paste the input and output ports of your module as such.

    PORT(

        clk : in std_logic;

        reset: in std_logic;

        pwm_value: in std_logic_vector (6 downto 0) ;

        pwm_out : out std_logic

    );

END COMPONENT;

                                --declare inputs and initialize them

signal s_clk : std_logic := '0';

signal s_reset : std_logic := '0';

                                --declare outputs and initialize them

signal s_pwm_value : std_logic_vector(6 downto 0) := "0000000";

signal s_pwm_out : std_logic := '0';
```

```

-- Clock period definitions

constant clk_period : time := 125 ns;

BEGIN -- Instantiate the Unit Under Test (UUT)

 uut: VHDL_PWM PORT MAP (

         clk => s_clk,

         pwm_value => s_pwm_value,

         reset => s_reset,

         pwm_out => s_pwm_out

     );

-- Clock process definitions( clock with 50% duty cycle is generated here.

clk_process :process

begin

    s_clk <= '0';

    wait for clk_period/2; --for 0.5 ns signal is '0'.

    s_clk <= '1';

    wait for clk_period/2; --for next 0.5 ns signal is '1'.

end process;

-- Reset process.

reset_process :process

begin

    s_reset <= '0';

    wait for clk_period*10; --for 10 clocks.

```



```

        s_reset <= '1';

        wait;

    end process;

                                -- Stimulus process

stim_proc: process

    begin

        wait for clk_period*20; --for 20 clocks.

        s_pwm_value <= "0000000";

        wait for clk_period*400; --for 20 clocks.

        s_pwm_value <= "0101111";

        wait for clk_period*400; --for 20 clocks.

        s_pwm_value <= "0111111";

        wait for clk_period*400; --for 20 clocks.

        s_pwm_value <= "1011111";

        wait for clk_period*400; --for 20 clocks.

        s_pwm_value <= "1111111";

    wait;

    end process;

END behaviour;

```

Appendix I: MATLAB® Binary Duty Cycle Calculations

%This Program calculates the Binary Value of Duty_Cycles expressed as 7 bit Binary values. It produces 2 tables: %1- rounded decimal value of the Duty cycle as well as calculated value. 2- Binary Value

```
clear all;
```

```
n = 0;
```

```
while (n < 100)
```

```
    n=n +1 ;
```

```
    value(n,1) = (n/100)*127;
```

```
    value(n,2) = round((n / 100)* 127);
```

```
        bin_val{n,1}=dec2bin(round((n / 100)* 127),7);
```

```
end
```

Appendix J: Distribution System Circuit Design Calculations

Table J-1: 5V boost converter parameters

<u>Parameter</u>	<u>Symbol</u>	<u>Value</u>
Input Voltage	V_{in}	4.2V
Output Voltage	V_{out}	5V
Output Power	P_{out}	2.4W
% Ripple Voltage	ΔV_o	10%
Switching Frequency	f_{sw}	235kHz

Duty cycle:

$$D = 1 - \frac{V_{in}}{V_{out}}$$

$$D = 1 - \frac{4.2}{5}$$

$$D = 0.16$$

Inductor value:

$$L_{min} = \frac{D(1-D)^2 R}{2(f_{sw})}$$

$$L_{\min} = \frac{0.16(1-0.16)^2 8.56}{2(235\text{kHz})}$$

$$L_{\min} = 2.056\mu\text{H}$$

Capacitor value:

$$\Delta V_o = \frac{D}{RCf_{sw}}$$

$$10\% = \frac{0.16}{(8.56)C(235\text{kHz})}$$

$$C = 9.29\text{nF}$$

Table J-2: 3.3V Buck converter parameters

<u>Parameter</u>	<u>Symbol</u>	<u>Value</u>
Input Voltage	V_{in}	4.2V
Output Voltage	V_{out}	3.3V
Output Power	P_{out}	0.5W
% Ripple Voltage	ΔV_o	10%

Duty cycle:

$$D = \frac{V_{out}}{V_{in}}$$

$$D = \frac{3.3V}{4.2}$$

$$D = 0.785$$

Inductor value:

$$L_{\min} = \frac{(1-D)R}{2(f_{sw})}$$

$$L_{\min} = \frac{(1-0.785)23.4}{2(235kHz)}$$

$$L_{\min} = 10.66\mu H$$

Capacitor value:

$$\Delta V_o = \frac{1-D}{8LCf_{sw}^2}$$

$$0.01 = \frac{1-0.785}{8(10.66\mu H)C(235kHz)^2}$$

$$C = 4.565\mu H \Rightarrow 45.65\mu H$$

Appendix K: System Integration

